

High-performance 240 MHz Arm Cortex-M33 core, up to 512 KB code flash memory with background operation, 16 KB Data flash memory, and 64 KB SRAM with ECC. Integrated 12-bit A/D Converter with sample-and-hold circuit for simultaneous sampling and single-end/pseudo-differential input supportive amplifier. Integrated General PWM Timer with 200 MHz operation and high resolution. Integrated Secure Cryptographic Engine with cryptography accelerators and key management support in concert with Arm TrustZone for integrated secure element functionality.

## Features

- **Arm® Cortex®-M33 Core**
  - Armv8-M architecture with the main extension
  - Maximum operating frequency: 240 MHz
  - Arm Memory Protection Unit (Arm MPU)
    - Protected Memory System Architecture (PMSAv8)
    - Secure MPU (MPU\_S): 8 regions
    - Non-secure MPU (MPU\_NS): 8 regions
  - SysTick timer
    - Embeds two SysTick timers: Secure and Non-secure instance
    - Driven by LOCO or system clock
  - CoreSight™ ETM-M33
- **Memory**
  - Up to 512-KB code flash memory
  - 16-KB data flash memory (125,000 program/erase (P/E) cycles)
  - 64-KB SRAM
- **Connectivity**
  - Serial Communications Interface (SCI) × 6
    - Asynchronous interfaces
    - 8-bit clock synchronous interface
    - Smart card interface
    - Simple IIC
    - Simple SPI
    - Simple LIN
    - Manchester coding
  - I<sup>2</sup>C bus interface (IIC) × 2
    - Transfer at up to 3.2 Mbps (high speed mode)
  - Serial Peripheral Interface (SPI) × 2
  - CAN with Flexible Data-rate (CANFD)
- **Analog**
  - 12-bit A/D Converter (ADC) × 2
    - Sample-and-hold circuits × 6
    - Programmable Gain Amplifier × 4
  - High-Speed Analog Comparator (ACMPHS) × 4
  - 12-bit D/A Converter (DAC12) × 4
  - Temperature Sensor (TSN)
- **Timers**
  - General PWM Timer 32-bit (GPT32) with High Resolution × 4
    - 156 ps resolution in 200 MHz
  - General PWM Timer 32-bit (GPT32) × 6
  - Low Power Asynchronous General Purpose Timer (AGT) × 2
- **Security and Encryption**
  - Secure Cryptographic Engine (SCE5)
    - Symmetric algorithms: AES
    - Hash-value generation: GHASH
    - 128-bit unique ID
  - Arm® TrustZone®
    - Up to three regions for the code flash
    - Up to two regions for the data flash
    - Up to three regions for the SRAM
    - Individual secure or non-secure security attribution for each peripheral
  - Device lifecycle management
- **System and Power Management**
  - Low power modes
  - Event Link Controller (ELC)
  - Data Transfer Controller (DTC)
  - DMA Controller (DMAC) × 8
  - Power-on reset
  - Low Voltage Detection (LVD) with voltage settings
  - Watchdog Timer (WDT)
  - Independent Watchdog Timer (IWDT)
  - Key Interrupt Function (KINT)
- **Data Processing Accelerator**
  - Trigonometric Function Unit (TFU)
  - IIR Filter Accelerator (IIRFA)
- **Multiple Clock Sources**
  - Main clock oscillator (MOSC) (8 to 24 MHz)
  - High-speed on-chip oscillator (HOCO) (16/18/20 MHz)
  - Middle-speed on-chip oscillator (MOCO) (8 MHz)
  - Low-speed on-chip oscillator (LOCO) (32.768 kHz)
  - IWDT-dedicated on-chip oscillator (15 kHz)
  - Clock trim function for HOCO/MOCO/LOCO
  - PLL/PLL2
  - Clock out support
- **General-Purpose I/O Ports**
  - 5-V tolerance, open drain, input pull-up, switchable driving ability
- **Operating Voltage**
  - VCC: 2.7 to 3.6 V
- **Operating Temperature and Packages**
  - Ta = -40°C to +105°C
    - 100-pin LQFP (14 mm × 14 mm, 0.5 mm pitch)
    - 64-pin LQFP (10 mm × 10 mm, 0.5 mm pitch)
    - 48-pin LQFP (7 mm × 7 mm, 0.5 mm pitch)
    - 64-pin QFN (8 mm × 8 mm, 0.4 mm pitch)
    - 48-pin QFN (7 mm × 7 mm, 0.5 mm pitch)

## 1. Overview

The MCU integrates multiple series of software-compatible Arm<sup>®</sup>-based 32-bit cores that share a common set of Renesas peripherals to facilitate design scalability and efficient platform-based product development.

The MCU in this series incorporates a high-performance Arm Cortex<sup>®</sup>-M33 core running up to 240 MHz with the following features:

- Up to 512 KB code flash memory
- 64 KB SRAM
- General PWM Timer (GPT) - Enhanced High Resolution
- Analog peripherals
- Security and safety features

### 1.1 Function Outline

**Table 1.1 Arm core**

Feature	Functional description
Arm Cortex-M33 core	<ul style="list-style-type: none"> <li>• Maximum operating frequency: up to 240 MHz</li> <li>• Arm Cortex-M33 core:               <ul style="list-style-type: none"> <li>– Armv8-M architecture with security extension</li> <li>– Revision: r0p4-00rel0</li> </ul> </li> <li>• Arm Memory Protection Unit (Arm MPU)               <ul style="list-style-type: none"> <li>– Protected Memory System Architecture (PMSAv8)</li> <li>– Secure MPU (MPU_S): 8 regions</li> <li>– Non-secure MPU (MPU_NS): 8 regions</li> </ul> </li> <li>• SysTick timer               <ul style="list-style-type: none"> <li>– Embeds two SysTick timers: Secure and Non-secure instance</li> <li>– Driven by SysTick timer clock (SYSTICCLK) or system clock (ICLK)</li> </ul> </li> <li>• CoreSight™ ETM-M33</li> </ul>

**Table 1.2 Memory**

Feature	Functional description
Code flash memory	Maximum 512 KB of code flash memory.
Data flash memory	16 KB of data flash memory.
Option-setting memory	The option-setting memory determines the state of the MCU after a reset.
SRAM	On-chip high-speed SRAM with Error Correction Code (ECC).

**Table 1.3 System (1 of 2)**

Feature	Functional description
Operating modes	Two operating modes: <ul style="list-style-type: none"> <li>• Single-chip mode</li> <li>• SCI boot mode</li> </ul>
Resets	The MCU provides 14 resets.
Low Voltage Detection (LVD)	The Low Voltage Detection (LVD) module monitors the voltage level input to the VCC pin. The detection level can be selected by register settings. The LVD module consists of three separate voltage level detectors (LVD0, LVD1, LVD2). LVD0, LVD1, and LVD2 measure the voltage level input to the VCC pin. LVD registers allow your application to configure detection of VCC changes at various voltage thresholds.
Clocks	<ul style="list-style-type: none"> <li>• Main clock oscillator (MOSC)</li> <li>• High-speed on-chip oscillator (HOCO)</li> <li>• Middle-speed on-chip oscillator (MOCO)</li> <li>• Low-speed on-chip oscillator (LOCO)</li> <li>• IWDT-dedicated on-chip oscillator</li> <li>• PLL/PLL2</li> <li>• Clock out support</li> </ul>

**Table 1.3 System (2 of 2)**

Feature	Functional description
Clock Frequency Accuracy Measurement Circuit (CAC)	The Clock Frequency Accuracy Measurement Circuit (CAC) counts pulses of the clock to be measured (measurement target clock) within the time generated by the clock selected as the measurement reference (measurement reference clock), and determines the accuracy depending on whether the number of pulses is within the allowable range. When measurement is complete or the number of pulses within the time generated by the measurement reference clock is not within the allowable range, an interrupt request is generated.
Interrupt Controller Unit (ICU)	The Interrupt Controller Unit (ICU) controls which event signals are linked to the Nested Vector Interrupt Controller (NVIC), the DMA Controller (DMAC), and the Data Transfer Controller (DTC) modules. The ICU also controls non-maskable interrupts.
Key Interrupt Function (KINT)	The key interrupt function (KINT) generates the key interrupt by detecting rising or falling edge on the key interrupt input pins.
Low power modes	Power consumption can be reduced in multiple ways, including setting clock dividers, stopping modules, selecting power control mode in normal operation, and transitioning to low power modes.
Register write protection	The register write protection function protects important registers from being overwritten due to software errors. The registers to be protected are set with the Protect Register (PRCR).
Memory Protection Unit (MPU)	The MCU has one Memory Protection Unit (MPU).

**Table 1.4 Event link**

Feature	Functional description
Event Link Controller (ELC)	The Event Link Controller (ELC) uses the event requests generated by various peripheral modules as source signals to connect them to different modules, allowing direct link between the modules without CPU intervention.

**Table 1.5 Direct memory access**

Feature	Functional description
Data Transfer Controller (DTC)	A Data Transfer Controller (DTC) module is provided for transferring data when activated by an interrupt request.
DMA Controller (DMAC)	The MCU includes an 8-channel direct memory access controller (DMAC) that can transfer data without intervention from the CPU. When a DMA transfer request is generated, the DMAC transfers data stored at the transfer source address to the transfer destination address.

**Table 1.6 Timers (1 of 2)**

Feature	Functional description
General PWM Timer (GPT)	The General PWM Timer (GPT) is a 32-bit timer with GPT32 × 10 channels. PWM waveforms can be generated by controlling the up-counter, down-counter, or the up- and down-counter. In addition, PWM waveforms can be generated for controlling brushless DC motors. The GPT can also be used as a general-purpose timer.
PWM Delay Generation Circuit (PDG)	The PWM Delay Generation circuit (PDG) has 4 channels delay circuits that can connect to the GPT. The PDG can control the rise and fall edge timing with which the PWM output for the GPT320 through the GPT323.
Port Output Enable for GPT (POEG)	The POEG issues requests to stop output from output pins of the general PWM timer (GPT). Select the method of detection for stopping the output from the list below.
Low power Asynchronous General Purpose Timer (AGT)	The low power Asynchronous General Purpose Timer (AGT) is a 32-bit timer that can be used for pulse output, external pulse width or period measurement, and counting external events. This timer consists of a reload register and a down counter. The reload register and the down counter are allocated to the same address, and can be accessed with the AGT register.
Watchdog Timer (WDT)	The Watchdog Timer (WDT) is a 14-bit down counter that can be used to reset the MCU when the counter underflows because the system has run out of control and is unable to refresh the WDT. In addition, the WDT can be used to generate a non-maskable interrupt or an underflow interrupt.

**Table 1.6 Timers (2 of 2)**

Feature	Functional description
Independent Watchdog Timer (IWDT)	The Independent Watchdog Timer (IWDT) consists of a 14-bit down counter that must be serviced periodically to prevent counter underflow. The IWDT provides functionality to reset the MCU or to generate a non-maskable interrupt or an underflow interrupt. Because the timer operates with an independent, dedicated clock source, it is particularly useful in returning the MCU to a known state as a fail-safe mechanism when the system runs out of control. The IWDT can be triggered automatically by a reset, underflow, refresh error, or a refresh of the count value in the registers.

**Table 1.7 Communication interfaces**

Feature	Functional description
Serial Communications Interface (SCI)	The Serial Communications Interface (SCI) × 6 channels have asynchronous and synchronous serial interfaces: <ul style="list-style-type: none"> <li>Asynchronous interfaces (UART and Asynchronous Communications Interface Adapter (ACIA))</li> <li>8-bit clock synchronous interface</li> <li>Simple IIC (master-only)</li> <li>Simple SPI</li> <li>Simple LIN</li> <li>Smart card interface</li> <li>Manchester interface</li> </ul> The smart card interface complies with the ISO/IEC 7816-3 standard for electronic signals and transmission protocol. SCIn (n = 0 to 4, 9) has FIFO buffers to enable continuous and full-duplex communication, and the data transfer speed can be configured independently using an on-chip baud rate generator.
I <sup>2</sup> C bus interface (IIC)	The I <sup>2</sup> C bus interface (IIC) has 2 channels. The IIC module conform with and provide a subset of the NXP I <sup>2</sup> C (Inter-Integrated Circuit) bus interface functions.
Serial Peripheral Interface (SPI)	The Serial Peripheral Interface (SPI) has 2 channels. The SPI provides high-speed full-duplex synchronous serial communications with multiple processors and peripheral devices.
CAN with Flexible Data-rate (CANFD)	The CAN with Flexible Data-rate (CANFD) module can handle classical CAN frames and CAN-FD frames complied with ISO 11898-1 standard. The module supports 4 transmit buffers and 32 receive buffer.

**Table 1.8 Analog**

Feature	Functional description
12-bit A/D Converter (ADC)	The 12-bit A/D Converter (ADC) has two units of 12-bit successive approximation A/D Converters with sample-and-hold circuits and programmable gain amplifiers (PGA) provided. The A/D converter unit 0 (ADC0) can select up to 21 channels of analog inputs. The A/D converter unit 1 (ADC1) can select up to 17 channels of analog inputs. The temperature sensor, internal reference voltage, and D/A converters can be A/D-converted by ADC0 or ADC1.
12-bit D/A Converter (DAC12)	A 12-bit D/A converter (DAC12) is provided.
High-Speed Analog Comparator (ACMPHS)	The High-Speed Analog Comparator (ACMPHS) compares a test voltage with a reference voltage and provides a digital output based on the conversion result. Both the test and reference voltages can be provided to the comparator from internal sources such as the DAC12 output and internal reference voltage, and an external source with or without an internal PGA. Such flexibility is useful in applications that require go/no-go comparisons to be performed between analog signals without necessarily requiring A/D conversion.
Temperature Sensor (TSN)	The on-chip Temperature Sensor (TSN) determines and monitors the die temperature for reliable operation of the device. The sensor outputs a voltage directly proportional to the die temperature, and the relationship between the die temperature and the output voltage is fairly linear. The output voltage is provided to the ADC for conversion and can be further used by the end application.

**Table 1.9 Data processing**

Feature	Functional description
Cyclic Redundancy Check (CRC)	The Cyclic Redundancy Check (CRC) generates CRC codes to detect errors in the data. The bit order of CRC calculation results can be switched for LSB-first or MSB-first communication. Additionally, various CRC-generation polynomials are available. The snoop function allows to monitor the access to specific addresses. This function is useful in applications that require CRC code to be generated automatically in certain events, such as monitoring writes to the serial transmit buffer and reads from the serial receive buffer.
Data Operation Circuit (DOC)	The data operation circuit (DOC) is used to compare, add, and subtract 16 or 32-bit data. An interrupt can be generated when the following conditions apply. <ul style="list-style-type: none"> <li>• When the 16 or 32-bit compared values match the detection condition</li> <li>• When the result of 16 or 32-bit data addition overflows</li> <li>• When the result of 16 or 32-bit data subtraction underflows</li> </ul>

**Table 1.10 Data processing accelerator**

Feature	Functional description
Trigonometric function unit (TFU)	Calculation of sine, cosine, arctangent, and $\sqrt{x^2 + y^2}$ <ul style="list-style-type: none"> <li>• A sine and cosine can be simultaneously calculated.</li> <li>• An arctangent and <math>\sqrt{x^2 + y^2}</math> can be simultaneously calculated.</li> </ul>
IIR Filter Accelerator (IIRFA)	<ul style="list-style-type: none"> <li>• 16 channels of biquad IIR filter</li> <li>• cascaded biquad filter (max.32 stages)</li> <li>• Operations using single-precision floating-point numbers</li> </ul>

## 1.2 Block Diagram

Figure 1.1 shows a block diagram of the MCU superset. Some individual devices within the group have a subset of the features.

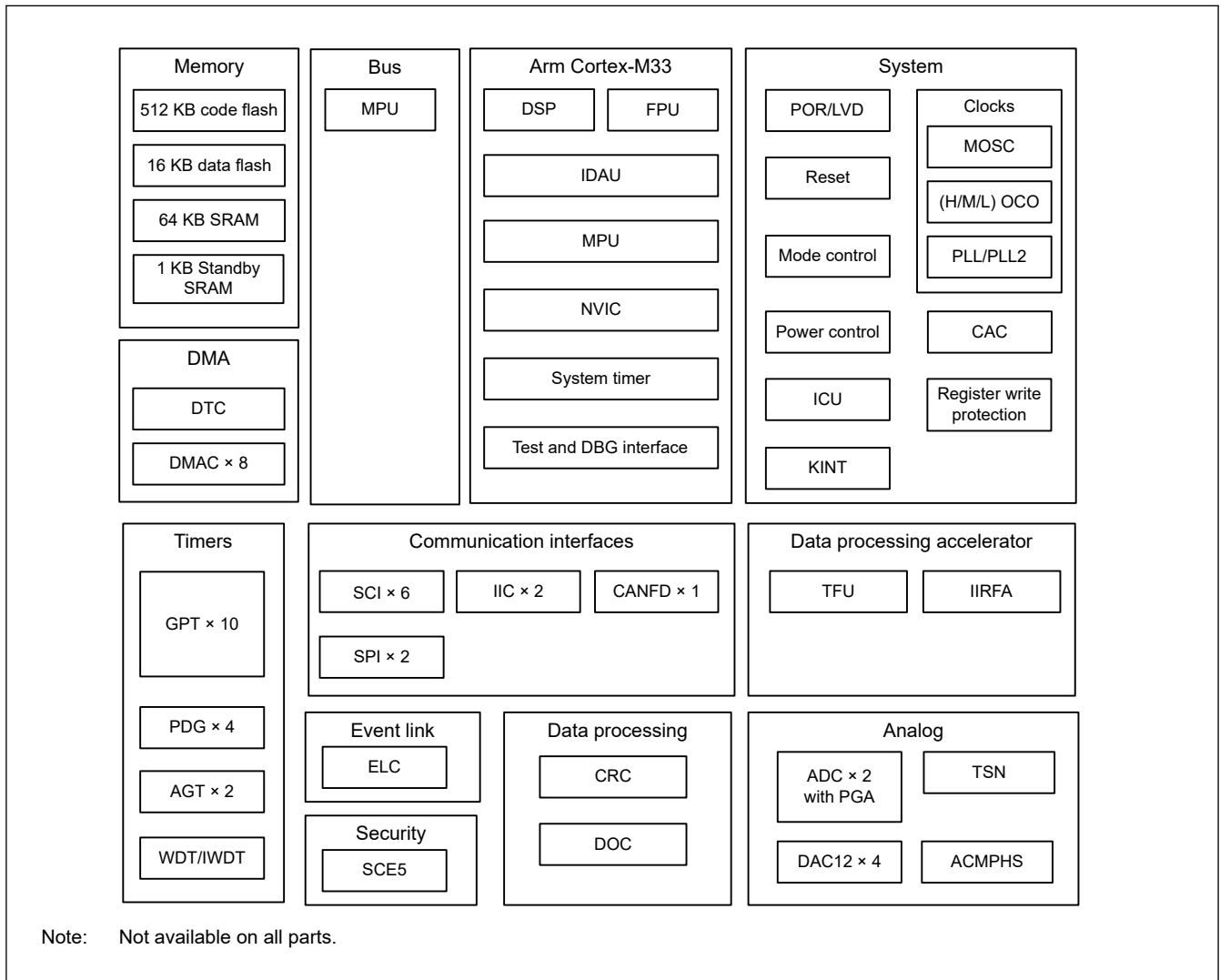


Figure 1.1 Block diagram

## 1.3 Part Numbering

Figure 1.2 shows the product part number information, including memory capacity and package type. Table 1.11 shows a list of products.

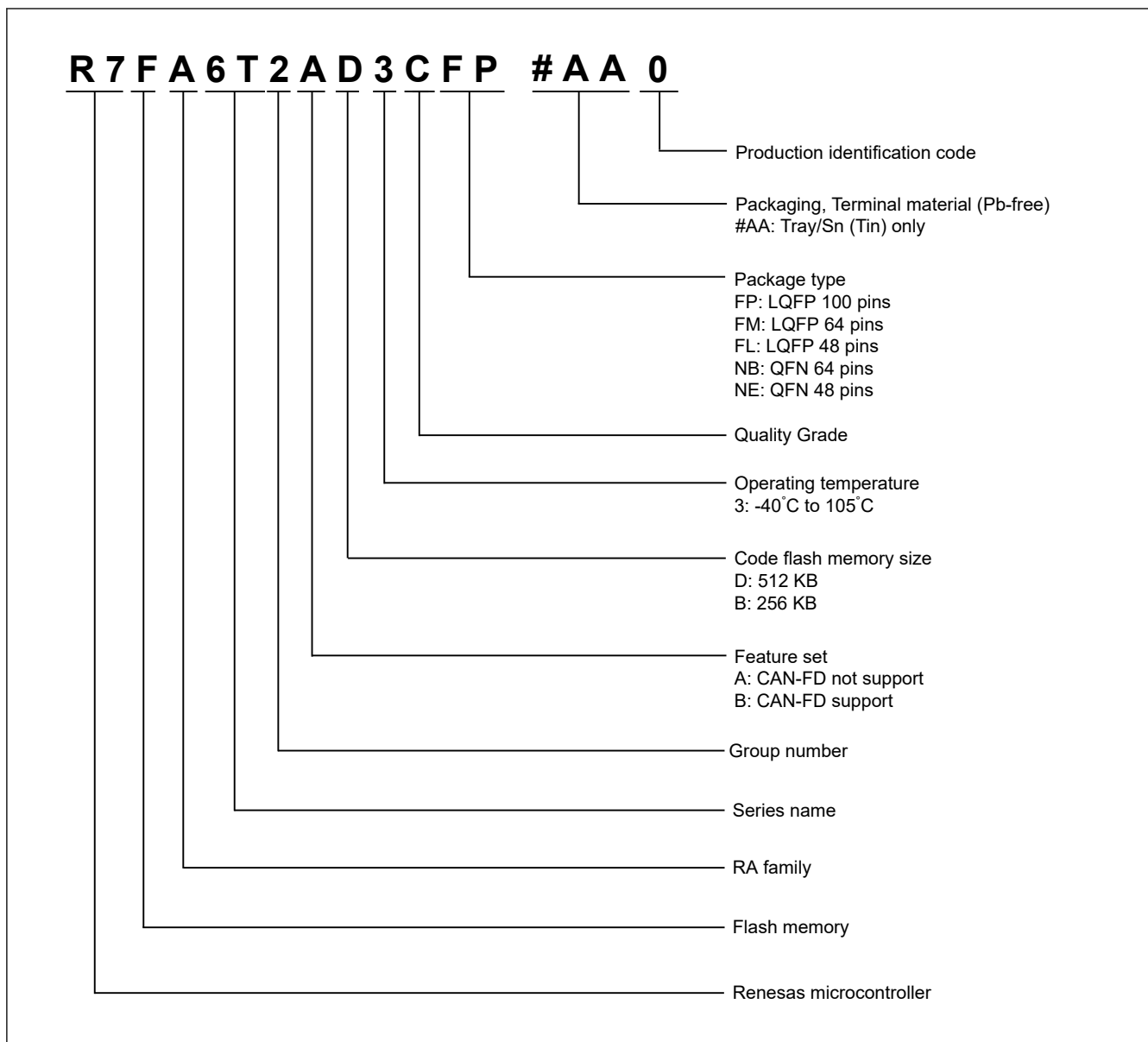


Figure 1.2 Part numbering scheme

Table 1.11 Product list (1 of 2)

Product part number	Package code	Code flash	Data flash	SRAM	CAN-FD	Operating temperature
R7FA6T2AD3CFP	PLQP0100KB-B	512 KB	16 KB	64 KB	Not support	-40 to +105°C
R7FA6T2AD3CFM	PLQP0064KB-C					
R7FA6T2AD3CFL	PLQP0048KB-B					
R7FA6T2AD3CNB	PWQN0064LA-A					
R7FA6T2AD3CNE	PWQN0048KB-A					
R7FA6T2AB3CFP	PLQP0100KB-B	256 KB				
R7FA6T2AB3CFM	PLQP0064KB-C					
R7FA6T2AB3CFL	PLQP0048KB-B					
R7FA6T2AB3CNB	PWQN0064LA-A					
R7FA6T2AB3CNE	PWQN0048KB-A					

**Table 1.11 Product list (2 of 2)**

Product part number	Package code	Code flash	Data flash	SRAM	CAN-FD	Operating temperature
R7FA6T2BD3CFP	PLQP0100KB-B	512 KB	16 KB	64 KB	Support	-40 to +105°C
R7FA6T2BD3CFM	PLQP0064KB-C					
R7FA6T2BD3CFL	PLQP0048KB-B					
R7FA6T2BD3CNB	PWQN0064LA-A					
R7FA6T2BD3CNE	PWQN0048KB-A					
R7FA6T2BB3CFP	PLQP0100KB-B	256 KB				
R7FA6T2BB3CFM	PLQP0064KB-C					
R7FA6T2BB3CFL	PLQP0048KB-B					
R7FA6T2BB3CNB	PWQN0064LA-A					
R7FA6T2BB3CNE	PWQN0048KB-A					



## 1.4 Function Comparison

**Table 1.12 Function Comparison**

Parts number		R7FA6T2XX3CFP	R7FA6T2XX3CFM	R7FA6T2XX3CFL	R7FA6T2XX3CNB	R7FA6T2XX3CNE
Pin count		100	64	48	64	48
Package		LQFP			QFN	
Code flash memory		512 KB, 256KB				
Data flash memory		16 KB				
SRAM	ECC	64 KB				
Standby SRAM	Parity	1 KB				
DMA	DTC	Yes				
	DMAC	8				
System	CPU clock	240 MHz (max.)				
	CPU clock sources	MOSC, HOCO, MOCO, LOCO, PLL				
	CAC	Yes				
	WDT/IWDT	Yes				
	KINT	Yes				
Communication	SCI	6				
	IIC	2*2				
	SPI	2				
	CANFD	1				
Timers	GPT*1	10				
	AGT*1	2				
Analog	ADC	Unit 0: 12 + 9 <sup>3</sup> , Unit 1: 8 + 9 <sup>3</sup>	Unit 0: 10, Unit 1: 8	Unit 0: 6, Unit 1: 4	Unit 0: 10, Unit 1: 8	Unit 0: 6, Unit 1: 4
	DAC12	4		2	4	2
	ACMPHS	4		2	4	2
	PGA	4		3	4	3
	TSN	Yes				
Data processing	CRC	Yes				
	DOC	Yes				
Event control	ELC	Yes				
Accelerator	TFU	Yes				
	IIRFA	Yes				
Security		SCE5, TrustZone and Lifecycle management				

Note: The product name differs depend on the memory size and CAN-FD support. see [section 1.3. Part Numbering](#).

Note 1. Available pins depend on the Pin count, about details see [section 1.7. Pin Lists](#).

Note 2. Fm+ and Hs-mode is only available for IIC channel IIC0.

Note 3. Shared terminal for UNIT0 and UNIT1.

## 1.5 Pin Functions

**Table 1.13 Pin functions (1 of 3)**

Function	Signal	I/O	Description
Power supply	VCC	Input	Power supply pin. Connect it to the system power supply. Connect this pin to VSS by a 0.1- $\mu$ F capacitor. The capacitor should be placed close to the pin.
	VCL	I/O	Connect this pin to the VSS pin by the smoothing capacitor used to stabilize the internal power supply. Place the capacitor close to the pin.
	VSS	Input	Ground pin. Connect it to the system power supply (0 V).
Clock	EXTAL	Input	Pins for a crystal resonator. An external clock signal can be input through the EXTAL pin.
	XTAL	Output	
	CLKOUT	Output	Clock output pin
Operating mode control	MD	Input	Pin for setting the operating mode. The signal level on this pin must not be changed during operation mode transition on release from the reset state.
System control	RES	Input	Reset signal input pin. The MCU enters the reset state when this signal goes low.
CAC	CACREF	Input	Measurement reference clock input pin
On-chip emulator	TMS	Input	On-chip emulator or boundary scan pins
	TDI	Input	
	TCK	Input	
	TDO	Output	
	TCLK	Output	Output clock for synchronization with the trace data
	TDATA0 to TDATA3	Output	Trace data output
	SWO	Output	Serial wire trace output pin
	SWDIO	I/O	Serial wire debug data input/output pin
	SWCLK	Input	Serial wire clock pin
Interrupt	NMI	Input	Non-maskable interrupt request pin
	IRQn	Input	Maskable interrupt request pins
	IRQn-DS	Input	Maskable interrupt request pins that can also be used in Deep Software Standby mode
KINT	KR00 to KR07	Input	A key interrupt can be generated by inputting a falling edge to the key interrupt input pins

Table 1.13 Pin functions (2 of 3)

Function	Signal	I/O	Description
GPT	GTETRGA, GTETRGB, GTETRGC, GTETRGD	Input	External trigger input pins
	GTIOCnA, GTIOCnB	I/O	Input capture, output compare, or PWM output pins
	GTADSM0, GTADSM1	Output	A/D conversion start request monitoring output pins
	GTCPP00 to GTCPP04, GTCPP07	Output	Toggle output synchronized with PWM period
	GTIU	Input	Hall sensor input pin U
	GTIV	Input	Hall sensor input pin V
	GTIW	Input	Hall sensor input pin W
	GTOUUP	Output	3-phase PWM output for BLDC motor control (positive U phase)
	GTOULO	Output	3-phase PWM output for BLDC motor control (negative U phase)
	GTOVUP	Output	3-phase PWM output for BLDC motor control (positive V phase)
	GTOVLO	Output	3-phase PWM output for BLDC motor control (negative V phase)
	GTOWUP	Output	3-phase PWM output for BLDC motor control (positive W phase)
	GTOWLO	Output	3-phase PWM output for BLDC motor control (negative W phase)
AGT	AGTEEn	Input	External event input enable signals
	AGTIO n	I/O	External event input and pulse output pins
	AGTO n	Output	Pulse output pins
	AGTOAn	Output	Output compare match A output pins
	AGTOBn	Output	Output compare match B output pins
SCI	SCKn	I/O	Input/output pins for the clock (clock synchronous mode)
	RXDn	Input	Input pins for received data (asynchronous mode/clock synchronous mode)
	TXDn	Output	Output pins for transmitted data (asynchronous mode/clock synchronous mode)
	CTS n_RTSn	I/O	Input/output pins for controlling the start of transmission and reception (asynchronous mode/clock synchronous mode), active-low.
	CTS n	Input	Input for the start of transmission.
	DEn	Output	Output pins for Driver Enable signal
	SCLn	I/O	Input/output pins for the IIC clock (simple IIC mode)
	SDAn	I/O	Input/output pins for the IIC data (simple IIC mode)
	SCKn	I/O	Input/output pins for the clock (simple SPI mode)
	MISO n	I/O	Input/output pins for slave transmission of data (simple SPI mode)
	MOSIn	I/O	Input/output pins for master transmission of data (simple SPI mode)
	SSn	Input	Chip-select input pins (simple SPI mode), active-low
IIC	SCLn	I/O	Input/output pins for the clock
	SDAn	I/O	Input/output pins for data
SPI	RSPCKA, RSPCKB	I/O	Clock input/output pin
	MOSIA, MOSIB	I/O	Input or output pins for data output from the master
	MISOA, MISOB	I/O	Input or output pins for data output from the slave
	SSLA0, SSLB0	I/O	Input or output pin for slave selection
	SSLA1 to SSLA3, SSLB1 to SSLB3	Output	Output pins for slave selection

Table 1.13 Pin functions (3 of 3)

Function	Signal	I/O	Description
CANFD	CRX0	Input	Receive data
	CTX0	Output	Transmit data
Analog power supply	AVCC0	Input	Analog voltage supply pin. This is used as the analog power supply for the respective modules. Supply this pin with the same voltage as the VCC pin.
	AVSS0	Input	Analog ground pin. This is used as the analog ground for the respective modules. Supply this pin with the same voltage as the VSS pin.
	VREFH0	Input	Analog reference voltage supply pin for the ADC. Connect this pin to AVCC0 when not using the ADC.
	VREFL0	Input	Analog reference ground pin for the ADC. Connect this pin to AVSS0 when not using the ADC.
ADC	AN000 to AN028	Input	Input pins for the analog signals to be processed by the A/D converter.
	PGAIN0 to PGAIN3	Input	Pseudo-differential input pins of programmable gain amplifier (Signal source side)
	PGAVSS0 to PGAVSS3	Input	Pseudo-differential input pins of programmable gain amplifier (reference ground side)
	PGAOUT0 to PGAOUT3	Output	Monitor output pins of programmable gain amplifier
	ADTRGm	Input	Input pins for the external trigger signals that start the A/D conversion, active-low.
DAC12	DAn	Output	Output pins for the analog signals processed by the D/A converter.
ACMPHS	VCOUT	Output	Comparator output pin (OR output of all units)
	CMPOUTm	Output	Comparator output pin (m:unit number)
	CMPOUT012	Output	Comparator output pin (OR output of units 0, 1 and 2)
	IVREF0, IVREF1	Input	Reference voltage input pins for comparator
	IVCMPm0, IVCMPm2, IVCMPm3	Input	Analog voltage input pins for comparator (m:unit number)
I/O ports	P201, P212, P213, PA08 to PA15, PB03 to PB10, PB12 to PB15, PC06 to PC12, PC14, PC15, PD00 to PD15, PE00 to PE06, PE08 to PE15	I/O	General-purpose input/output pins
	P000, P001, P002, PA00 to PA07, PB00 to PB02, PC00 to PC05, PC13	Input	General-purpose input pins

### 1.6 Pin Assignments

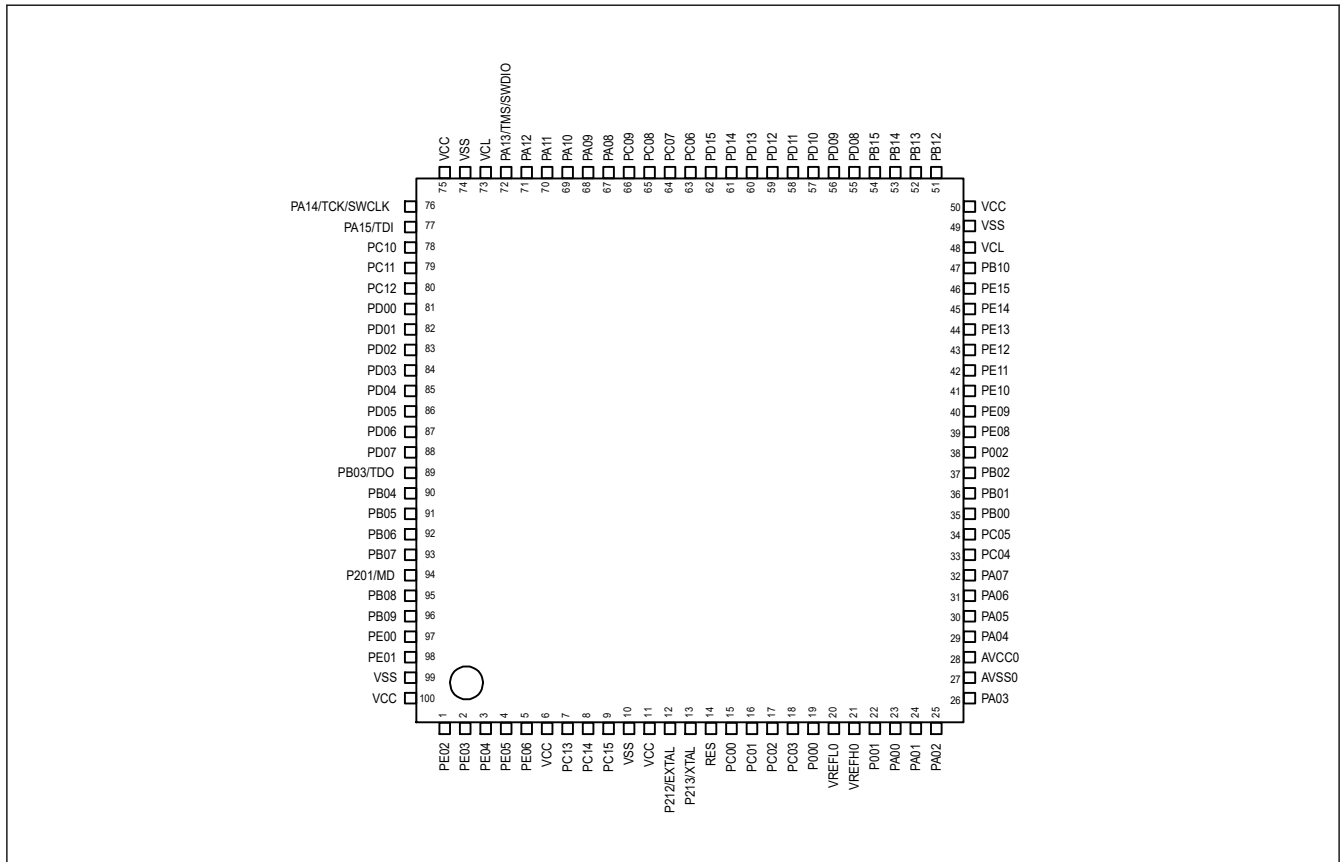


Figure 1.3 Pin assignment for LQFP 100-pin

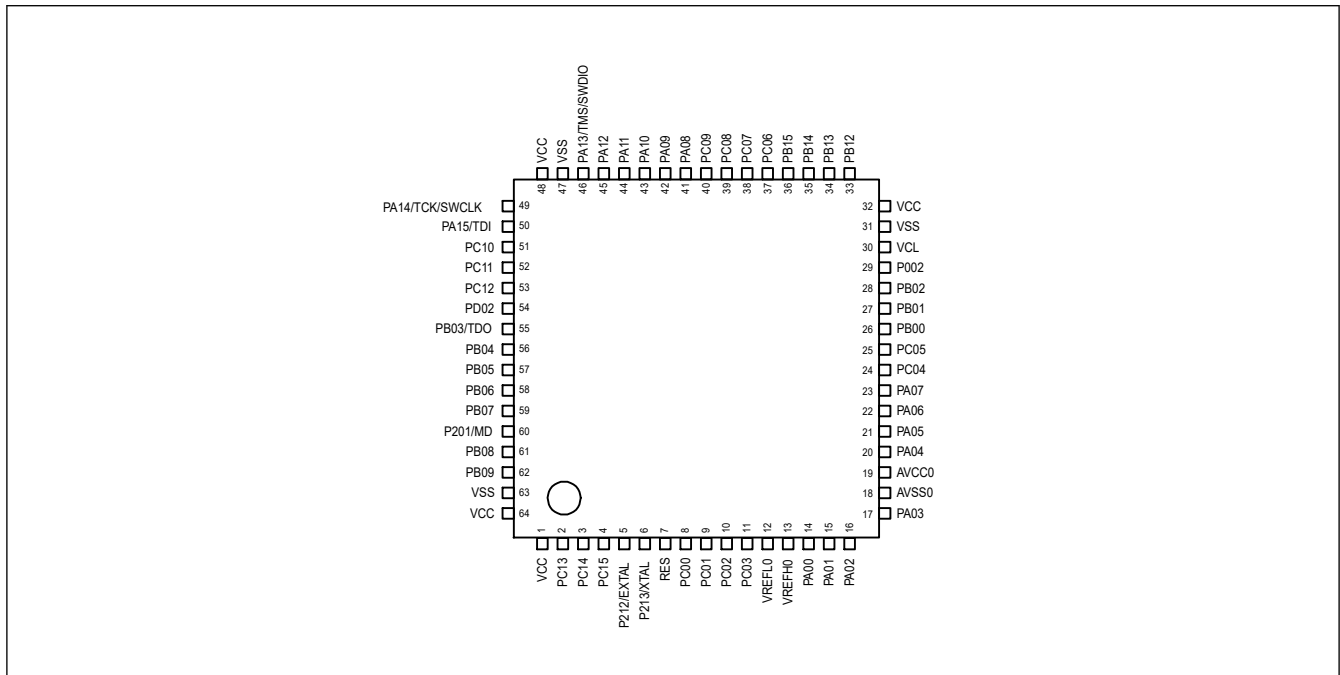


Figure 1.4 Pin assignment for LQFP 64-pin

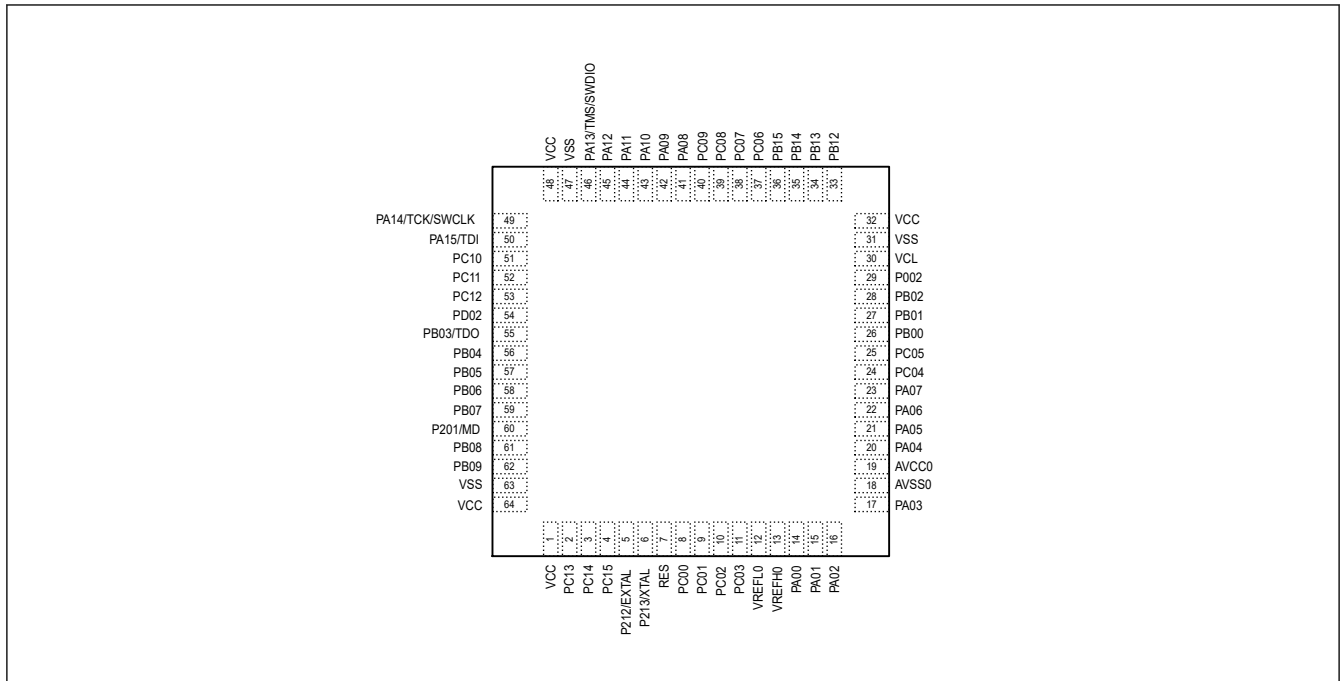


Figure 1.5 Pin assignment for QFN 64-pin

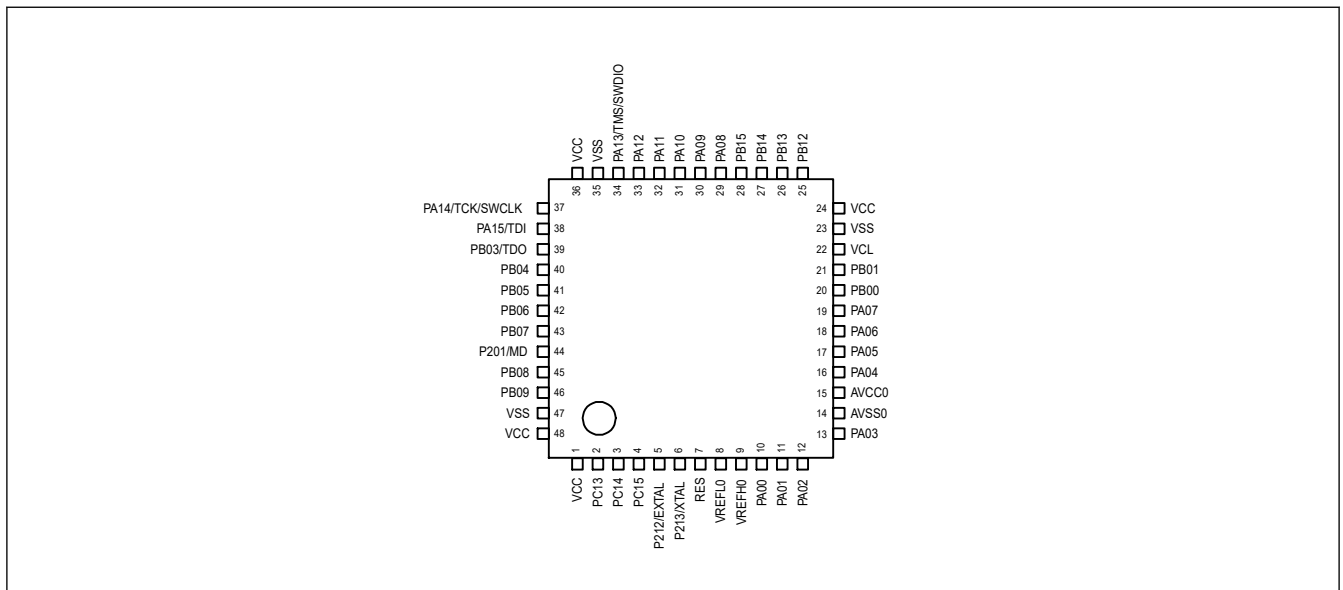


Figure 1.6 Pin assignment for LQFP 48-pin

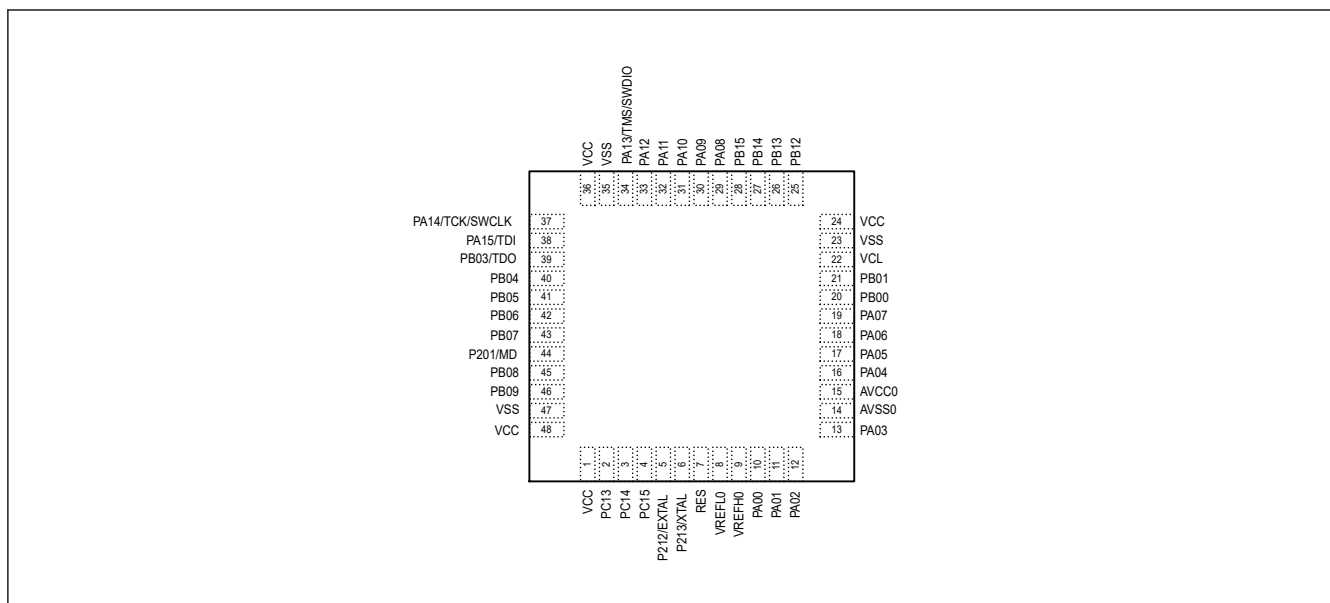


Figure 1.7 Pin assignment for QFN 48-pin

1.7 Pin Lists

Table 1.14 Pin list (1 of 3)

LQFP100	LQFP64, QFN64	LQFP48, QFN48	Power, System, Clock, Debug, CAC	I/O ports	Ex. Interrupt/KINT	SCI/IIC/SPI/CANFD	GPT/AGT	ADC/DAC12/ACMPHS
1	—	—	CLKOUT/TCLK	PE02	—	SCK0_B/DE0/SCK3_A/DE3/RSPCKB_C	GTOVLO/GTIOC7B/GTIOC8A	CMPOUT0
2	—	—	TDATA0	PE03	—	RXD0_B/MISO0_B/SCL0/CTS3_A/SSLB0_C	GTOWLO/GTIOC8A/GTIOC9A	CMPOUT1
3	—	—	TDATA1	PE04	—	TXD0_B/MOSI0_B/SDA0/CTS3_RTS3/SS3_A/DE3/SSLB1_C	GTOUUP/GTIOC8B/GTIOC7B	CMPOUT2
4	—	—	TDATA2	PE05	—	CTS0_RTS0/SS0_B/DE0/RXD3_A/MISO3_A/SCL3/MISOB_C	GTOVUP/GTIOC9A/GTIOC8B/GTCPPO2	CMPOUT3
5	—	—	TDATA3	PE06	—	CTS0_B/TXD3_A/MOSI3_A/SDA3/MOSIB_C	GTOWUP/GTIOC9B/GTCPPO3	—
6	1	1	VCC	—	—	—	—	—
7	2	2	—	PC13	NMI	—	GTETRGD	—
8	3	3	—	PC14	IRQ14	—	GTETRGA/GTIOC3A/GTCPPO0/GTADSM0/GTCPPO4/AGTIO0	ADTRG0/CMPOUT012
9	4	4	—	PC15	IRQ15	—	GTETRGB/GTIOC3B/GTCPPO1/GTADSM1/GTCPPO7/AGTIO1	ADTRG1/CMPOUT3
10	—	—	VSS	—	—	—	—	—
11	—	—	VCC	—	—	—	—	—
12	5	5	EXTAL	P212	—	—	—	—
13	6	6	XTAL	P213	IRQ0	—	—	—
14	7	7	RES	—	—	—	—	—
15	8	—	—	PC00	IRQ11-DS	—	—	AN012/PGAOUT0/IVCMP00
16	9	—	—	PC01	IRQ12-DS	—	—	AN013/PGAOUT1/IVCMP10
17	10	—	—	PC02	IRQ13-DS	—	—	AN014/PGAOUT2/IVCMP20
18	11	—	—	PC03	IRQ14-DS	—	—	AN015/PGAOUT3/IVCMP30
19	—	—	—	P000	IRQ0	—	—	AN016/IVREF0
20	12	8	VREFL0	—	—	—	—	—
21	13	9	VREFH0	—	—	—	—	—
22	—	—	—	P001	IRQ2	—	—	AN017/IVREF1
23	14	10	—	PA00	IRQ0-DS	—	—	AN000/PGAIN0/IVCMP02/IVCMP03
24	15	11	—	PA01	IRQ1	—	—	AN001/PGAVSS0
25	16	12	—	PA02	IRQ2	—	—	AN002/PGAIN1/IVCMP12/IVCMP13
26	17	13	—	PA03	IRQ3	—	—	AN003/PGAVSS1
27	18	14	AVSS0	—	—	—	—	—
28	19	15	AVCC0	—	—	—	—	—
29	20	16	—	PA04	IRQ4	—	—	AN004/PGAIN2/IVCMP22/IVCMP23
30	21	17	—	PA05	IRQ5	—	—	AN005/PGAVSS2
31	22	18	—	PA06	IRQ6	—	—	AN006/DA0
32	23	19	—	PA07	IRQ7	—	—	AN007/DA1
33	24	—	—	PC04	IRQ10	—	—	AN010/DA2
34	25	—	—	PC05	IRQ11	—	—	AN011/DA3
35	26	20	—	PB00	IRQ0	—	—	AN008/PGAOUT0/PGAOUT2
36	27	21	—	PB01	IRQ1	—	—	AN009/PGAOUT1/PGAOUT3
37	28	—	—	PB02	IRQ15-DS	—	—	AN018/PGAIN3/IVCMP32/IVCMP33
38	29	—	—	P002	—	—	—	AN019/PGAVSS3
39	—	—	—	PE08	KR00	SSLA3_C	GTIV/GTIOC3A/GTETRGC/GTADSM0	AN020/ADTRG0/CMPOUT012
40	—	—	CACREF	PE09	KR01	SSLA2_C	GTIW/GTIOC3B/GTETRGD/GTADSM1	AN021/ADTRG1/CMPOUT3
41	—	—	—	PE10	KR02	SSLA1_C	GTOULO/GTIOC2A/GTIOC4A/GTIOC7A	AN022



Table 1.14 Pin list (2 of 3)

LQFP100	LQFP64, QFN64	LQFP48, QFN48	Power, System, Clock, Debug, CAC	I/O ports	Ex. Interrupt/KINT	SCI/IIC/SPI/CANFD	GPT/AGT	ADC/DAC12/ACMPHS
42	—	—	—	PE11	KR03	SSLA0_C	GTOUUP/GTIOC2B/GTIOC5A/ GTIOC8A	AN023
43	—	—	—	PE12	KR04	RSPCKA_C	GTOVLO/GTIOC1A/GTIOC6A/ GTIOC9A	AN024
44	—	—	—	PE13	KR05	MISOA_C	GTOVUP/GTIOC1B/GTIOC4B/ GTIOC7B	AN025
45	—	—	—	PE14	KR06	MOSIA_C	GTOVLO/GTIOC0A/GTIOC5B/ GTIOC8B	AN026
46	—	—	—	PE15	KR07	RXD4_A/MISO4_A/SCL4	GTOVUP/GTIOC0B/GTIOC6B/ GTIOC9B	AN027
47	—	—	CACREF/VCOUT	PB10	IRQ10-DS	TXD4_A/MOSI4_A/SDA4/CTS3_B	GTIU/GTETRA/GTETRGB/ GTCPP04/GTCPP07	AN028
48	30	22	VCL	—	—	—	—	—
49	31	23	VSS	—	—	—	—	—
50	32	24	VCC	—	—	—	—	—
51	33	25	—	PB12	IRQ2	SCK4_A/DE4/RXD3_B/MISO3_B/SCL3/SSLB0_A/ CRX0	GTETRA/GTIOC0A/GTIOC4A	ADTRG0
52	34	26	—	PB13	IRQ3	CTS4_A/TXD3_B/MOSI3_B/SDA3/RSPCKB_A/CTX0	GTOULO/GTIOC0B/GTIOC7A/ GTIOC5A	—
53	35	27	—	PB14	IRQ4	CTS4_RTS4/SS4_A/DE4/SCK3_B/DE3/SDA0_C/ MISOB_A	GTOVLO/GTIOC1A/GTIOC8A/ GTIOC6A	—
54	36	28	—	PB15	IRQ5	RXD4_A/MISO4_A/SCL4/CTS3_RTS3/SS3_B/DE3/ SCL0_C/MOSIB_A	GTOVLO/GTIOC1B/GTIOC9A/ GTIOC4B	—
55	—	—	—	PD08	KR00	CTS2_B/TXD1_A/MOSI1_A/SDA1/SSLB1_A	GTIOC2A	—
56	—	—	—	PD09	KR01	CTS2_RTS2/SS2_B/DE2/RXD1_A/MISO1_A/SCL1/ SSLB2_A	GTIOC2B	—
57	—	—	—	PD10	KR02	SCK2_C/DE2/SCK1_A/DE1/SSLB3_A	GTETRC/GTIOC3A	—
58	—	—	—	PD11	KR03	RXD2_C/MISO2_C/SCL2/CTS1_A	GTIOC3B	—
59	—	—	—	PD12	IRQ12/KR04	TXD2_C/MOSI2_C/SDA2/CTS1_RTS1/SS1_A/DE1/ SCL1_D	GTIOC4A	—
60	—	—	—	PD13	IRQ13/KR05	SCK4_C/DE4/SCK9_C/DE9/SDA1_D	GTIOC4B	—
61	—	—	—	PD14	IRQ14/KR06	RXD4_C/MISO4_C/SCL4/RXD9_C/MISO9_C/SCL9/ SCL0_F	GTIOC5A	—
62	—	—	—	PD15	IRQ15/KR07	TXD4_C/MOSI4_C/SDA4/TXD9_C/MOSI9_C/ SDA9/DE9/SDA0_F	GTIOC5B	—
63	37	—	—	PC06	IRQ6	TXD2_B/MOSI2_B/SDA2/CTS9_RTS9/SS9_C/DE9/ SCL1_E	GTETRGD/GTIOC6A/GTIOC5B/ AGT00	—
64	38	—	—	PC07	IRQ7	RXD2_B/MISO2_B/SCL2/CTS9_C/SDA1_E	GTETRA/GTIOC6B/AGTEE0	—
65	39	—	CACREF	PC08	IRQ8	SCK2_B/DE2/CTS3_RTS3/SS3_C/DE3/SCL0_E/ SSLA3_B	GTIV/GTIOC7A/AGTOA0	—
66	40	—	CLKOUT	PC09	IRQ9	CTS2_RTS2/SS2_B/DE2/CTS3_C/SDA0_D/SDA0_E/ SSLA2_B	GTIW/GTIOC7B/GTIOC8A/AGTOB0	—
67	41	29	CLKOUT	PA08	IRQ8/KR00	SCK0_A/DE0/SCK1_C/DE1/SCL0_D/SSLA1_B	GTOUUP/GTIOC8A/GTIOC7B/ GTIOC2A/GTIOC9A/AGTIO0	CMPOUT2
68	42	30	—	PA09	IRQ9/KR01	TXD0_A/MOSI0_A/SDA0/SCL1_C/SSLA0_B	GTOVUP/GTIOC8B/GTIOC8B/ GTIOC2B/GTIOC7B	CMPOUT3
69	43	31	—	PA10	IRQ10/KR02	RXD0_A/MISO0_A/SCL0/SDA1_C/RSPCKA_B	GTOVUP/GTIOC9A/GTIOC9B/ GTIOC3A/GTIOC8B	CMPOUT0
70	44	32	—	PA11	IRQ11/KR03	CTS0_A/RXD1_C/MISO1_C/SCL1/MOSIA_B/CTX0	GTETRGD/GTIOC9B/GTETRC/ GTIOC3B	CMPOUT1
71	45	33	CACREF	PA12	IRQ12/KR04	CTS0_RTS0/SS0_A/DE0/TXD1_C/MOSI1_C/SDA1/ MISOA_B/CRX0	GTETRGB/GTCPP00/GTCPP02/ GTADSM0/GTCPP07	ADTRG1
72	46	34	TMS/SWDIO	PA13	—	SCK0_C/DE0/CTS1_RTS1/SS1_C/DE1	AGT00	—
73	—	—	VCL	—	—	—	—	—
74	47	35	VSS	—	—	—	—	—
75	48	36	VCC	—	—	—	—	—
76	49	37	TCK/SWCLK	PA14	—	TXD0_C/MOSI0_C/SDA0/SCK9_B/DE9	AGT01	—
77	50	38	TDI	PA15	IRQ11/KR02	RXD0_C/MISO0_C/SCL0/RXD9_B/MISO9_B/SCL9/ SSLA0_A	GTETRGB/GTADSM1/GTCPP04	ADTRG0/CMPOUT012
78	51	—	—	PC10	IRQ6-DS/KR05	TXD1_B/MOSI1_B/SDA1/SCL0_B/RSPCKB_B	AGTIO1	CMPOUT0

**Table 1.14 Pin list (3 of 3)**

LQFP100	LQFP64, QFN64	LQFP48, QFN48	Power, System, Clock, Debug, CAC	I/O ports	Ex. Interrupt/KINT	SCI/IIC/SPI/CANFD	GPT/AGT	ADC/DAC12/ACMPHS
79	52	—	—	PC11	IRQ7-DS/KR06	RXD1_B/MISO1_B/SCL1/SDA0_B/MISOB_B	AGTOA1	CMPOUT1
80	53	—	—	PC12	IRQ8-DS/KR07	TXD4_B/MOSI4_B/SDA4/SCK1_B/DE1/MOSIB_B	AGTOB1	CMPOUT2
81	—	—	—	PD00	KR00	CTS2_A/RXD3_C/MISO3_C/SCL3/SSLB0_B/CRX0	GTADSM0/GTCPPO4	—
82	—	—	—	PD01	KR01	CTS2_RTS2/SS2_A/DE2/TXD3_C/MOSI3_C/SDA3/SSLB1_B/CTX0	GTADSM1/GTCPPO7	—
83	54	—	CLKOUT	PD02	IRQ9-DS/KR02	RXD4_B/MISO4_B/SCL4/SCK3_C/DE3	GTCPP00/GTCPPO2/AGTEE1	CMPOUT3
84	—	—	—	PD03	KR03	SCK4_B/DE4/CTS9_A/SSLB2_B	GTCPP00	CMPOUT0
85	—	—	—	PD04	KR04	CTS4_RTS4/SS4_B/DE4/CTS9_RTS9/SS9_A/DE9/SSLB3_B	GTCPP01	CMPOUT1
86	—	—	—	PD05	KR05	TXD9_A/MOSI9_A/SDA9/SDA1_B/SSLA3_A	GTADSM0/GTCPPO3	—
87	—	—	—	PD06	KR06	RXD9_A/MISO9_A/SCL9/SCL1_B/SSLA2_A	GTCPP04	—
88	—	—	—	PD07	KR07	SCK9_A/DE9/SSLA1_A	GTADSM1/GTCPPO7	—
89	55	39	TDO/SWO	PB03	IRQ0/KR03	TXD2_A/MOSI2_A/SDA2/TXD9_B/MOSI9_B/SDA9/RSPCKA_A/CRX0	GTIOC4A/GTCPPO1/GTCPPO3/AGTO1	ADTRG1/CMPOUT3
90	56	40	CACREF/VCOU	PB04	IRQ13/KR04	RXD2_A/MISO2_A/SCL2/RXD3_D/MISO3_D/SCL3/MISOA_A/CTX0	GTIOC4A/GTIOC5A/GTIOC0A/AGTOA0	—
91	57	41	—	PB05	IRQ3-DS/KR05	SCK2_A/DE2/TXD3_D/MOSI3_D/SDA3/MOSIA_A/CRX0	GTIU/GTIOC4B/GTIOC6A/GTIOC0B/AGTOB0	—
92	58	42	—	PB06	IRQ4-DS/KR06	TXD0_D/MOSI0_D/SDA0/CTS3_RTS3/SS3_D/DE3/SCL0_A/CTX0	GTIV/GTIOC5A/GTIOC4B/GTIOC1A/AGTOA1	—
93	59	43	—	PB07	IRQ5-DS/KR07	RXD0_D/MISO0_D/SCL0/CTS1_RTS1/SS1_D/DE1/SDA0_A	GTIW/GTIOC5B/GTETRGC/GTIOC1B/AGTOB1	—
94	60	44	MD	P201	—	—	—	—
95	61	45	—	PB08	IRQ1-DS/KR00	RXD4/MISO4_C/SCL4/RXD1_D/MISO1_D/SCL1/SCL1_A/CRX0	GTIOC6A/GTIOC5B/GTIOC2A/AGTIO0	—
96	62	46	—	PB09	IRQ2-DS/KR01	TXD4/MOSI4_C/SDA4/TXD1_D/MOSI1_D/SDA1/SDA1_A/CTX0	GTIOC6B/GTIOC2B/AGTIO1	—
97	—	—	CACREF	PE00	—	TXD0_E/MOSI0_E/SDA0/TXD9_D/MOSI9_D/SDA9/SSLB3_C	GTETRGA/GTIOC4A/GTADSM0/AGTEE0	ADTRG0
98	—	—	—	PE01	—	RXD0_E/MISO0_E/SCL0/RXD9_D/MOSI9_D/SCL9/SSLB2_C	GTOULO/GTIOC7A/GTIOC4B/GTADSM1/AGTEE1	ADTRG1
99	63	47	VSS	—	—	—	—	—
100	64	48	VCC	—	—	—	—	—

Note: Several pin names have the added suffix of \_A, \_B, \_C, \_D, \_E and \_F. The suffix can be ignored when assigning functionality.

## 2. Electrical Characteristics

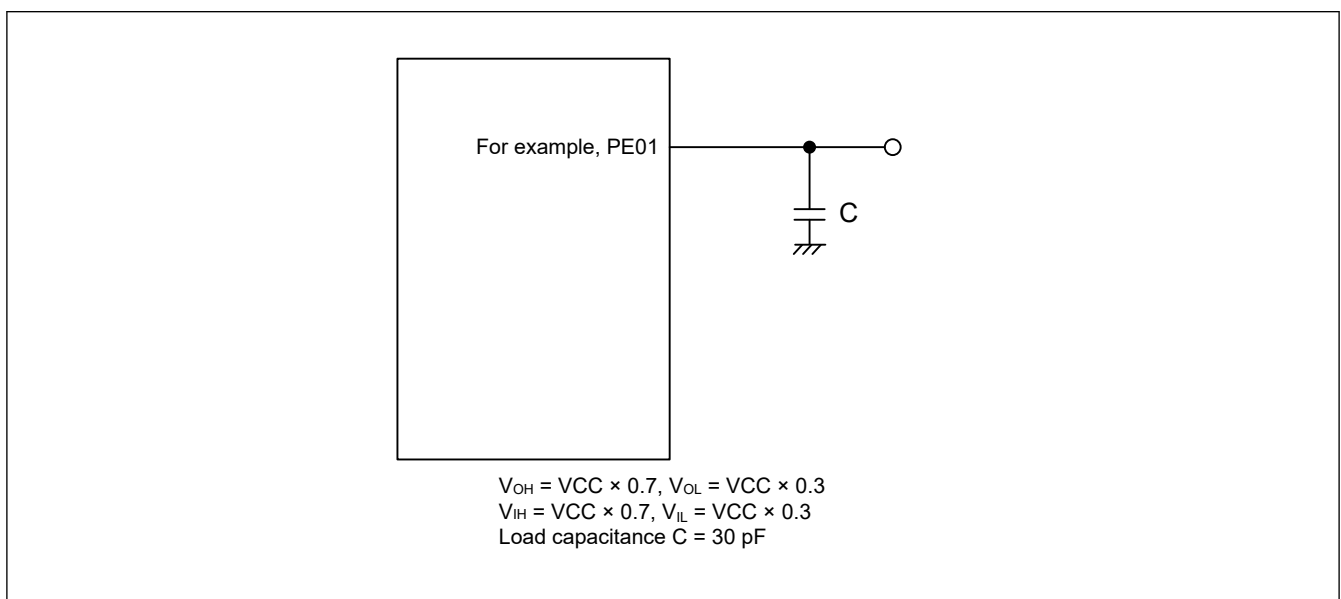
Unless otherwise specified, minimum and maximum values are guaranteed by either design simulation, characterization results or test in production.

Supported peripheral functions and pins differ from one product name to another.

Unless otherwise specified, the electrical characteristics of the MCU are defined under the following conditions:

- $VCC = AVCC0 = 2.7$  to  $3.6$  V
- $2.7 \leq VREFH0 \leq AVCC0$
- $VSS = AVSS0 = VREFL0 = 0$  V
- $T_a = T_{opr}$

Figure 2.1 shows the timing conditions.



**Figure 2.1** Input or output timing measurement conditions

The recommended measurement conditions for the timing specification of each peripheral provided are for the best peripheral operation. Make sure to adjust the driving abilities of each pin to meet your conditions.

### 2.1 Absolute Maximum Ratings

**Table 2.1** Absolute maximum ratings (1 of 2)

Parameter	Symbol	Value	Unit
Power supply voltage	VCC	-0.3 to +4.0	V
Input voltage (except for 5 V-tolerant ports*1)	$V_{in}$	-0.3 to VCC + 0.3	V
Input voltage (5 V-tolerant ports*1)	$V_{in}$	-0.3 to + VCC + 4.0 (max. 5.8)	V
Reference power supply voltage	VREFH0	-0.3 to VCC + 0.3	V
Analog power supply voltage	AVCC0*2	-0.3 to +4.0	V
Analog input voltage (except for PA00 to PA05, PB02, P002)	$V_{AN}$	-0.3 to AVCC0 + 0.3	V
Analog input voltage (PA00 to PA05, PB02, P002) when PGA differential input is disabled	$V_{AN}$	-0.3 to AVCC0 + 0.3	V
Analog input voltage (PA00, PA02, PA04, PB02) when PGA differential input is enabled	$V_{AN}$	-1.3 to AVCC0 + 0.3	V
Analog input voltage (PA01, PA03, PA05, P002) when PGA differential input is enabled	$V_{AN}$	-0.8 to AVCC0 + 0.3	V

**Table 2.1 Absolute maximum ratings (2 of 2)**

Parameter	Symbol	Value	Unit
Operating temperature <sup>*3 *4</sup>	T <sub>opr</sub>	−40 to +105	°C
Storage temperature	T <sub>stg</sub>	−55 to +125	°C

Note 1. Ports PA12 to PA15, PB03 to PB09, PC10 to PC12, PC14, PC15, PD00 to PD07, PE00, and PE01 are 5 V tolerant.

Note 2. Connect AVCC0 to VCC.

Note 3. See [section 2.2.1. Tj/Ta Definition](#).

Note 4. Contact a Renesas Electronics sales office for information on derating operation when Ta = +85°C to +105°C. Derating is the systematic reduction of load for improved reliability.

**Caution: Permanent damage to the MCU might result if absolute maximum ratings are exceeded.**

**Table 2.2 Recommended operating conditions**

Parameter	Symbol	Min	Typ	Max	Unit
Power supply voltages	VCC	2.7	—	3.6	V
	VSS	—	0	—	V
Analog power supply voltages	AVCC0 <sup>*1</sup>	—	VCC	—	V
	AVSS0	—	0	—	V

Note 1. Connect AVCC0 to VCC. When the A/D converter and the D/A converter are not in use, do not leave the AVCC0, VREFH0, AVSS0, and VREFL0 pins open. Connect the AVCC0 and VREFH0 pins to VCC, and the AVSS0 and VREFL0 pins to VSS, respectively.

## 2.2 DC Characteristics

### 2.2.1 Tj/Ta Definition

**Table 2.3 DC characteristics**

Parameter	Symbol	Typ	Max	Unit	Test conditions
Permissible junction temperature	T <sub>j</sub>	—	125	°C	High-speed mode Low-speed mode

Note: Make sure that  $T_j = T_a + \theta_{ja} \times \text{total power consumption (W)}$ , where total power consumption =  $(V_{CC} - V_{OH}) \times \Sigma I_{OH} + V_{OL} \times \Sigma I_{OL} + I_{CCmax} \times V_{CC}$ .

2.2.2 I/O  $V_{IH}$ ,  $V_{IL}$ Table 2.4 I/O  $V_{IH}$ ,  $V_{IL}$ 

Parameter			Sym bol	Min	Typ	Max	Unit
Input voltage (except for Schmitt trigger input pins)	Peripheral function pin	EXTAL (external clock input), SPI (except RSPCK)	$V_{IH}$	$VCC \times 0.8$	—	—	V
			$V_{IL}$	—	—	$VCC \times 0.2$	
		IIC (SMBus)* <sup>1</sup>	$V_{IH}$	2.1	—	—	
			$V_{IL}$	—	—	0.8	
		IIC (SMBus)* <sup>2</sup>	$V_{IH}$	2.1	—	$VCC + 3.6$ (max 5.8)	
			$V_{IL}$	—	—	0.8	
Schmitt trigger input voltage	Peripheral function pin	IIC (Except for SMBus)* <sup>1</sup>	$V_{IH}$	$VCC \times 0.7$	—	—	
			$V_{IL}$	—	—	$VCC \times 0.3$	
			$\Delta V_T$	$VCC \times 0.05$	—	—	
		IIC (Except for SMBus)* <sup>2</sup>	$V_{IH}$	$VCC \times 0.7$	—	$VCC + 3.6$ (max 5.8)	
			$V_{IL}$	—	—	$VCC \times 0.3$	
			$\Delta V_T$	$VCC \times 0.05$	—	—	
		5 V-tolerant ports* <sup>3</sup> * <sup>7</sup>	$V_{IH}$	$VCC \times 0.8$	—	$VCC + 3.6$ (max 5.8)	
			$V_{IL}$	—	—	$VCC \times 0.2$	
			$\Delta V_T$	$VCC \times 0.05$	—	—	
		Other input pins* <sup>4</sup>	$V_{IH}$	$VCC \times 0.8$	—	—	
			$V_{IL}$	—	—	$VCC \times 0.2$	
			$\Delta V_T$	$VCC \times 0.05$	—	—	
	Ports	5 V-tolerant ports* <sup>5</sup> * <sup>7</sup>	$V_{IH}$	$VCC \times 0.8$	—	$VCC + 3.6$ (max 5.8)	
			$V_{IL}$	—	—	$VCC \times 0.2$	
			$\Delta V_T$	$VCC \times 0.05$	—	—	
Other input pins* <sup>6</sup>		$V_{IH}$	$VCC \times 0.8$	—	—		
		$V_{IL}$	—	—	$VCC \times 0.2$		
		$\Delta V_T$	$VCC \times 0.05$	—	—		

Note 1. SCL0\_C, SDA0\_C, SCL0\_D, SDA0\_D, SCL0\_E, SDA0\_E, SCL0\_F, SDA0\_F, SCL1\_C, SDA1\_C, SCL1\_D, SDA1\_D, SCL1\_E, SDA1\_E (total 14 pins). This is the value when IIC function is selected.

Note 2. SCL0\_A, SDA0\_A, SCL0\_B, SDA0\_B, SCL1\_A, SDA1\_A, SCL1\_B, SDA1\_B (total 8 pins). This is the value when IIC function is selected.

Note 3. RES and peripheral function pins associated with PA12 to PA15, PB03, PB05 to PB09, PC10 to PC12, PC14, PC15, PD00 to PD07, PE00, and PE01 (total 26 pins).

Note 4. All input pins except for the peripheral function pins already described in the table.

Note 5. PA12 to PA15, PB03, PB05 to PB09, PC10 to PC12, PC14, PC15, PD00 to PD07, PE00, and PE01 (total 25 pins).

Note 6. All input pins except for the ports already described in the table.

Note 7. When VCC is less than 2.7 V, the input voltage of 5 V-tolerant ports should be less than 3.6 V, otherwise breakdown may occur because 5 V-tolerant ports are electrically controlled so as not to violate the break down voltage.

2.2.3 I/O  $I_{OH}$ ,  $I_{OL}$ Table 2.5 I/O  $I_{OH}$ ,  $I_{OL}$ 

Parameter		Symbol	Min	Typ	Max	Unit	
Permissible output current (average value per pin)	IIC pins	Standard mode* <sup>1</sup>	$I_{OL}$	—	—	3.0	mA
		Fast mode* <sup>1</sup>	$I_{OL}$	—	—	6.0	mA
		Fast mode plus* <sup>2</sup>	$I_{OL}$	—	—	20	mA
		High speed mode* <sup>2</sup>	$I_{OL}$	—	—	3.0	mA
	Other output pins* <sup>3</sup>	Low drive* <sup>4</sup>	$I_{OH}$	—	—	-2.0	mA
			$I_{OL}$	—	—	2.0	mA
		Middle drive* <sup>5</sup>	$I_{OH}$	—	—	-4.0	mA
			$I_{OL}$	—	—	4.0	mA
		High drive* <sup>6</sup>	$I_{OH}$	—	—	-10	mA
			$I_{OL}$	—	—	10	mA
		High speed high drive* <sup>7</sup>	$I_{OH}$	—	—	-10	mA
			$I_{OL}$	—	—	10	mA
	High current drive* <sup>8</sup>	$I_{OH}$	—	—	-10	mA	
		$I_{OL}$	—	—	20	mA	
Permissible output current (max value per pin)	IIC pins	Standard mode* <sup>1</sup>	$I_{OL}$	—	—	3.0	mA
		Fast mode* <sup>1</sup>	$I_{OL}$	—	—	6.0	mA
		Fast mode plus* <sup>2</sup>	$I_{OL}$	—	—	20	mA
		High speed mode* <sup>2</sup>	$I_{OL}$	—	—	3.0	mA
	Other output pins* <sup>3</sup>	Low drive* <sup>4</sup>	$I_{OH}$	—	—	-2.0	mA
			$I_{OL}$	—	—	2.0	mA
		Middle drive* <sup>5</sup>	$I_{OH}$	—	—	-4.0	mA
			$I_{OL}$	—	—	4.0	mA
		High drive* <sup>6</sup>	$I_{OH}$	—	—	-16	mA
			$I_{OL}$	—	—	16	mA
		High speed high drive* <sup>7</sup>	$I_{OH}$	—	—	-16	mA
			$I_{OL}$	—	—	16	mA
	High current drive* <sup>8</sup>	$I_{OH}$	—	—	-16	mA	
		$I_{OL}$	—	—	20	mA	
Permissible output current (max value of total of all pins)	Maximum of all output pins	$\Sigma I_{OH}$ (max)	—	—	-80	mA	
		$\Sigma I_{OL}$ (max)	—	—	80	mA	

Note 1. SCL0\_A, SDA0\_A, SCL1\_A, SDA1\_A (total 4 pins). This is the value when IIC function is selected.

Note 2. SCL0\_A, SDA0\_A (total 2 pins). This is the value when IIC function is selected.

Note 3. Except for P000 to P002, PA00 to PA07, PB00 to PB02, PC00 to PC05, PC13, which are input ports.

Note 4. This is the value when low driving ability is selected in the Port Drive Capability bit in the PmnPFS register. The selected driving ability is retained in Deep Software Standby mode.

Note 5. This is the value when middle driving ability is selected in the Port Drive Capability bit in the PmnPFS register. The selected driving ability is retained in Deep Software Standby mode.

Note 6. This is the value when high driving ability is selected in the Port Drive Capability bit in the PmnPFS register. The selected driving ability is retained in Deep Software Standby mode.

Note 7. This is the value when high speed high driving ability is selected in the Port Drive Capability bit in the PmnPFS register. The selected driving ability is retained in Deep Software Standby mode.

Note 8. This is the value when high current driving ability is selected in the Port Drive Capability bit in the PmnPFS register. The selected driving ability is retained in Deep Software Standby mode.

**Caution:** To protect the reliability of the MCU, the output current values should not exceed the values in this table. The average output current indicates the average value of current measured during 100  $\mu$ s.

## 2.2.4 I/O $V_{OH}$ , $V_{OL}$ , and Other Characteristics

**Table 2.6** I/O  $V_{OH}$ ,  $V_{OL}$ , and other characteristics

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
Output voltage	IIC*1	$V_{OL}$	—	—	0.4	V	$I_{OL} = 3.0$ mA
		$V_{OL}$	—	—	0.6		$I_{OL} = 6.0$ mA
	IIC*2	$V_{OL}$	—	—	0.4		$I_{OL} = 15.0$ mA (BFCTL.FMPE = 1)
		$V_{OL}$	—	0.4	—		$I_{OL} = 20.0$ mA (BFCTL.FMPE = 1)
		$V_{OL}$	—	—	0.4		$I_{OL} = 3.0$ mA (BFCTL.HSME = 1)
	Ports PA08 to PA11, PB12 to PB15, PC06 to PC09, PD08 to PD15, PE10 to PE15*3	$V_{OH}$	$V_{CC} - 0.5$	—	—		$I_{OH} = -1.0$ mA
		$V_{OL}$	—	—	0.6		$I_{OL} = 20$ mA
	Other output pins	$V_{OH}$	$V_{CC} - 0.5$	—	—		$I_{OH} = -1.0$ mA
$V_{OL}$		—	—	0.5	$I_{OL} = 1.0$ mA		
Input leakage current	RES	$ I_{in} $	—	—	5.0	$\mu$ A	$V_{in} = 0$ V $V_{in} = 5.5$ V
	Port P000, P001, PA06, PA07, PB00, PB01, PC00 to PC05, PC13		—	—	1.0		$V_{in} = 0$ V $V_{in} = V_{CC}$
	Port PA00, PA02, PA04, PB02 (PGA input pins)		—	—	1.0		$V_{in} = 0$ V $V_{in} = V_{CC}$
	Port PA01, PA03, PA05, P002 (PGAVSS pins)*4		—	—	1.0		$V_{in} = 0$ V $V_{in} = V_{CC}$
Three-state leakage current (off state)	5 V-tolerant ports	$ I_{TSI} $	—	—	5.0	$\mu$ A	$V_{in} = 0$ V $V_{in} = 5.5$ V
	Other ports (except for input ports)		—	—	1.0		$V_{in} = 0$ V $V_{in} = V_{CC}$
Input pull-up MOS current	Ports P0, P2, PA to PE (except for ports P002, PA00 to PA05, PB02)	$I_p$	-300	—	-10	$\mu$ A	$V_{CC} = 2.7$ to $3.6$ V $V_{in} = 0$ V
Pull-up current serving as the SCL current source	IIC*5	$I_{CS}$	3	—	12	mA	$V_{CC} = 3.0$ to $3.6$ V $V_{in} = 0.3 \times V_{CC}$ to $0.7 \times V_{CC}$
Input capacitance	All input pins	$C_{in}$	—	—	8	pF	$V_{bias} = 0$ V $V_{amp} = 20$ mV $f = 1$ MHz $T_a = 25^\circ$ C

Note 1. SCL0\_A, SDA0\_A, SCL1\_A, SDA1\_A (total 4 pins). This is the value when IIC function is selected.

Note 2. SCL0\_A, SDA0\_A (total 2 pins). This is the value when IIC function is selected.

Note 3. This is the value when high current driving ability is selected in the Port Drive Capability bit in the PmnPFS register. The selected driving ability is retained in Deep Software Standby mode.

Note 4. This is the value when the pseudo-differential input on the PGAn pin is disabled (single-ended input).

Note 5. SCL0\_A (1 pin). This is the value when IIC high speed mode is selected.

## 2.2.5 Operating and Standby Current

Table 2.7 Operating and standby current

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions	
Supply current <sup>*1</sup>	High-speed mode	Maximum <sup>*2</sup>	I <sub>CC</sub> <sup>*3</sup>	—	—	150	mA ICLK = 240 MHz PCLKA = 120 MHz PCLKB = 60 MHz PCLKC = 60 MHz PCLKD = 120 MHz FCLK = 60 MHz	
		CoreMark <sup>®5 *6</sup>		—	34	—		
		Normal mode		All peripheral clocks enabled, while (1) code executing from flash <sup>*4</sup>	—	44		—
				All peripheral clocks disabled, while (1) code executing from flash <sup>*5 *6</sup>	—	28		—
		Sleep mode <sup>*5 *6</sup>		—	13	78		
		Increase during BGO operation		Data flash P/E	—	6		—
	Code flash P/E		—	8	—			
	Low-speed mode <sup>*5 *10</sup>	—	5	—	ICLK = 1 MHz			
	Software Standby mode	SNZCR.RXDREQEN = 1	—	—	63	ICLK = 32.768 kHz		
		SNZCR.RXDREQEN = 0	—	5.1	—	—		
	Deep Software Standby mode	Power supplied to Standby SRAM	—	22.7	60	μA	—	
		Power not supplied to SRAM	Power-on reset circuit low power function disabled	—	11.3	30	—	
			Power-on reset circuit low power function enabled	—	4.4	20	—	
Inrush current on returning from deep software standby mode	Inrush current <sup>*7</sup>	I <sub>RUSH</sub>	—	160	—	mA		
	Energy of inrush current <sup>*7</sup>	E <sub>RUSH</sub>	—	1.0	—	μC		
Analog power supply current	During ADC conversion (1unit)	Without SH	A <sub>ICC</sub>	—	4.8	6.0	mA	
		With SH		—	7.3	11.5	mA	
	PGA (1channel)	—		1	3	mA		
	ACMPHS (1unit)	—		0.1	0.2	mA		
	Temperature sensor	—		0.1	0.2	mA		
	During D/A conversion (1channel) <sup>*8</sup>	Without AMP output		—	0.2	0.3	mA	
		With AMP output		—	0.8	1.3	mA	
	Waiting for ADC, DAC12 conversion (all units)	—		3.8	4.5	mA		
	ADC, DAC12 in standby modes (all units) <sup>*9</sup>	—		0.7	10	μA		
Reference power supply current (VREFH0)	During ADC conversion (1unit)	A <sub>IREFH0</sub>	—	21	50	μA		
	Waiting for ADC, DAC12 conversion (all units)		—	18	50	μA		
	ADC, DAC12 in standby modes (all units) <sup>*9</sup>		—	0.03	1	μA		

Note 1. Supply current values are with all output pins unloaded and all input pull-up MOSs in the off state.

Note 2. Measured with clocks supplied to the peripheral functions. This does not include the BGO operation.

Note 3. I<sub>CC</sub> depends on f (ICLK) as follows.

$$I_{CC} \text{ Max.} = 0.34 \times f + 67 \text{ (max. operation in high-speed mode)}$$

$$I_{CC} \text{ Typ.} = 0.095 \times f + 4.7 \text{ (normal operation in high-speed mode, all peripheral clocks disabled)}$$

$$I_{CC} \text{ Typ.} = 0.9 \times f + 4.1 \text{ (low-speed mode)}$$

$$I_{CC} \text{ Max.} = 0.045 \times f + 67 \text{ (sleep mode)}$$

Note 4. This does not include the BGO operation.

Note 5. Supply of the clock signal to peripherals is stopped in this state. This does not include the BGO operation.

Note 6. FCLK, PCLKA, PCLKB, PCLKC, and PCLKD are set to divided by 64 (3.75 MHz).

Note 7. Reference value

Note 8. The DAC12 includes the Reference current in the analog power supply current.



Note 9. When the MCU is in Software Standby mode or the MSTPCRD.MSTPD16 (12-Bit A/D Converter Module Stop bit) is in the module-stop state.

Note 10. FCLK, PCLKA, PCLKB, PCLKC, and PCLKD are set to divided by 64 (15.6 kHz).

**Table 2.8 Coremark and normal mode current**

Parameter		Symbol	Typ	Unit	Test conditions	
Supply Current*1	Coremark	I <sub>CC</sub>	139	μA/MHz	ICLK = 240 MHz PCLKA = PCLKB = PCLKC = PCLKD = FCLK = 3.75 MHz	
	Normal mode		All peripheral clocks disabled, cache on, while (1) code executing from flash*2			139
			All peripheral clocks disabled, cache off, while (1) code executing from flash*2			115

Note 1. Supply current values are with all output pins unloaded and all input pull-up MOSs in the off state.

Note 2. Supply of the clock signal to peripherals is stopped in this state. This does not include the BGO operation.

## 2.2.6 VCC Rise and Fall Gradient and Ripple Frequency

**Table 2.9 Rise and fall gradient characteristics**

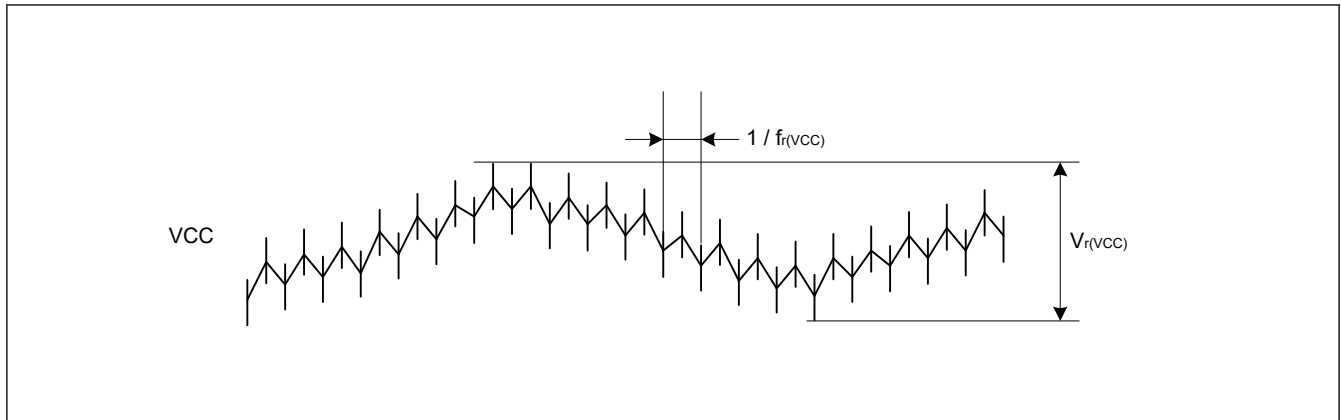
Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
VCC rising gradient	Voltage monitor 0 reset disabled at startup	SrVCC	0.0084	—	20	ms/V	—
	Voltage monitor 0 reset enabled at startup		0.0084	—	—		—
	SCI boot mode*1		0.0084	—	20		—
VCC falling gradient		SfVCC	0.0084	—	—	ms/V	—

Note 1. At boot mode, the reset from voltage monitor 0 is disabled regardless of the value of the OFS1.LVDAS bit.

**Table 2.10 Rising and falling gradient and ripple frequency characteristics**

The ripple voltage must meet the allowable ripple frequency  $f_{r(VCC)}$  within the range between the VCC upper limit (3.6 V) and lower limit (2.7 V). When the VCC change exceeds  $VCC \pm 10\%$ , the allowable voltage change rising and falling gradient  $dt/dVCC$  must be met.

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Allowable ripple frequency	$f_{r(VCC)}$	—	—	10	kHz	Figure 2.2 $V_{r(VCC)} \leq VCC \times 0.2$
		—	—	1	MHz	Figure 2.2 $V_{r(VCC)} \leq VCC \times 0.08$
		—	—	10	MHz	Figure 2.2 $V_{r(VCC)} \leq VCC \times 0.06$
Allowable voltage change rising and falling gradient	dt/dVCC	1.0	—	—	ms/V	When VCC change exceeds $VCC \pm 10\%$



**Figure 2.2** Ripple waveform

### 2.2.7 Thermal Characteristics

Maximum value of junction temperature ( $T_j$ ) must not exceed the value of [section 2.2.1.  \$T\_j/T\_a\$  Definition](#).

$T_j$  is calculated by either of the following equations.

- $T_j = T_a + \theta_{ja} \times \text{Total power consumption}$
- $T_j = T_t + \Psi_{jt} \times \text{Total power consumption}$ 
  - $T_j$  : Junction Temperature ( $^{\circ}\text{C}$ )
  - $T_a$  : Ambient Temperature ( $^{\circ}\text{C}$ )
  - $T_t$  : Top Center Case Temperature ( $^{\circ}\text{C}$ )
  - $\theta_{ja}$  : Thermal Resistance of “Junction”-to-“Ambient” ( $^{\circ}\text{C}/\text{W}$ )
  - $\Psi_{jt}$  : Thermal Resistance of “Junction”-to-“Top Center Case” ( $^{\circ}\text{C}/\text{W}$ )
- Total power consumption = Voltage  $\times$  (Leakage current + Dynamic current)
- Leakage current of IO =  $\Sigma (I_{OL} \times V_{OL}) / \text{Voltage} + \Sigma (|I_{OH}| \times |V_{CC} - V_{OH}|) / \text{Voltage}$
- Dynamic current of IO =  $\Sigma IO (C_{in} + C_{load}) \times IO \text{ switching frequency} \times \text{Voltage}$ 
  - $C_{in}$ : Input capacitance
  - $C_{load}$ : Output capacitance

Regarding  $\theta_{ja}$  and  $\Psi_{jt}$ , refer to [Table 2.11](#).

**Table 2.11** Thermal Resistance

Parameter	Package	Symbol	Value*1	Unit	Test conditions
Thermal Resistance	100-pin LQFP (PLQP0100KB-B)	$\theta_{ja}$	36	$^{\circ}\text{C}/\text{W}$	JESD 51-2 and 51-7 compliant
	64-pin LQFP (PLQP0064KB-C)		39		
	64-pin QFN (PWQN0064LA-A)		26		
	48-pin LQFP (PLQP0048KB-B)		60		
	48-pin QFN (PWQN0048KB-A)		28		
	100-pin LQFP (PLQP0100KB-B)	$\Psi_{jt}$	0.65	$^{\circ}\text{C}/\text{W}$	
	64-pin LQFP (PLQP0064KB-C)		0.69		
	64-pin QFN (PWQN0064LA-A)		0.15		
	48-pin LQFP (PLQP0048KB-B)		2.01		
	48-pin QFN (PWQN0048KB-A)		0.17		

Note 1. The values are reference values when the 4-layer board is used. Thermal resistance depends on the number of layers or size of the board. For details, refer to the JEDEC standards.

## 2.2.7.1 Calculation guide of ICCmax

Table 2.12 shows the power consumption of each unit.

**Table 2.12 Power consumption of each unit**

Dynamic current/Leakage current	MCU Domain	Category	Item	Frequency [MHz]	Current [ $\mu$ A/MHz]	Current*1 [mA]
Leakage current	Analog	LDO and Leak*2	Ta = 75 °C*3	—	—	37.8
			Ta = 85 °C*3	—	—	46.4
			Ta = 95 °C*3	—	—	56.1
			Ta = 105 °C*3	—	—	68.0
Dynamic current	CPU	Operation with Flash and SRAM	Coremark	240	105.324	25.28
	Peripheral Unit	Timer	GPT32 (10ch)*4	120	29.697	3.56
			POEG (4 Groups)*4	60	1.483	0.09
			AGT (2ch)*4	60	3.09	0.19
			WDT	60	0.641	0.04
			IWDT	60	0.225	0.01
		Communication interfaces	SCI (6ch)*4	120	27.683	3.32
			IIC (2ch)*4	120	5.304	0.64
			CANFD	60	5.763	0.35
			SPI (2ch)*4	120	5.738	0.69
		Data processing accelerator	TFU	240	1.188	0.03
			IIRFA	240	34.252	8.22
		Data processing	DOC	120	0.221	0.03
			CRC	120	0.508	0.06
		Analog	ADC (2 Units)*4	60	172.958	10.38
			DAC12 (4ch)*4	120	1.097	0.13
			ACMPHS (4ch)*4	60	0.641	0.04
			TSN	60	0.111	0.01
		Event link	ELC	60	1.852	0.11
		Security	SCE5	120	68.404	8.21
		System	CAC	60	0.63	0.04
			KINT	60	0.072	0.004
		DMA	DMAC	240	5.073	1.22
DTC			240	4.18	1	

Note 1. The values are guaranteed by design.

Note 2. LDO and Leak are internal voltage regulator's current and MCU's leakage current. It is selected according to the temperature of Ta.

Note 3.  $\Delta(T_j - T_a) = 20$  °C is considered to measure the current.

Note 4. To determine the current consumption per channel or unit, divide Current [mA] by the number of channels, groups or units.

**Table 2.13 Outline of operation for each unit (1 of 2)**

Peripheral	Outline of operation
GPT	Operating modes is set to saw-wave PWM mode. GPT is operating with PCLKD.

**Table 2.13 Outline of operation for each unit (2 of 2)**

Peripheral	Outline of operation
POEG	Only clear module stop bit.
AGT	AGT is operating with PCLKB.
WDT	WDT is operating with PCLKB.
IWDT	IWDT is operating with IWDTCLK.
SCI	SCI is transmitting data in clock synchronous mode.
IIC	Communication format is set to I2C-bus format. IIC is transmitting data in master mode.
CANFD	CANFD is transmitting and receiving data in self-test mode 1.
SPI	SPI mode is set to SPI operation (4-wire method). SPI master/slave mode is set to master mode. SPI is transmitting 8-bit width data.
TFU	Performs sincos operations.
IIRFA	Channel 0 performs 32 stages of channel processing.
DOC	DOC is operating in data addition mode.
CRC	CRC is generating CRC code using 32-bit CRC32-C polynomial.
ADC	Resolution is set to 12-bit accuracy. Conversion Data Operation Control B Register is set to 16 times average mode. ADC is converting the analog input in continuous scan mode. ADC is operating with PCLKC.
DAC12	DAC12 is outputting the conversion result while updating the value of data register.
ACMPHS	Compare between IVCMP2 and IVREF0 and enable compare output.
TSN	TSN is operating.
ELC	Only clear module stop bit.
SCE5	SCE5 is executing built-in self test.
DMAC	Bit length of transfer data is set to 32 bits. Transfer mode is set to block transfer mode. DMAC is transferring data from SRAM0 to SRAM0.
DTC	Bit length of transfer data is set to 32 bits. Transfer mode is set to block transfer mode. DTC is transferring data from SRAM0 to SRAM0.
CAC	Measurement target clocks is set to PCLKB. Measurement reference clocks is set to PCLKB. CAC is measuring the clock frequency accuracy.
KINT	Only clear module stop bit.

### 2.2.7.2 Example of Tj calculation

Assumption:

- Package 100-pin LQFP:  $\theta_{ja} = 36.0 \text{ }^{\circ}\text{C/W}$
- $T_a = 100 \text{ }^{\circ}\text{C}$
- $I_{CCmax} = 80 \text{ mA}$
- $V_{CC} = 3.5 \text{ V}$  ( $V_{CC} = AVCC0$ )
- $I_{OH} = 1 \text{ mA}$ ,  $V_{OH} = V_{CC} - 0.5 \text{ V}$ , 12 Outputs
- $I_{OL} = 20 \text{ mA}$ ,  $V_{OL} = 1.0 \text{ V}$ , 8 Outputs
- $I_{OL} = 1 \text{ mA}$ ,  $V_{OL} = 0.5 \text{ V}$ , 12 Outputs
- $C_{in} = 8 \text{ pF}$ , 16 pins, Input frequency = 10 MHz

- $C_{load} = 30 \text{ pF}$ , 16 pins, Output frequency = 10 MHz

$$\begin{aligned} \text{Leakage current of IO} &= \Sigma (V_{OL} \times I_{OL}) / \text{Voltage} + \Sigma ((VCC - V_{OH}) \times I_{OH}) / \text{Voltage} \\ &= (20 \text{ mA} \times 1 \text{ V}) \times 8 / 3.5 \text{ V} + (1 \text{ mA} \times 0.5 \text{ V}) \times 12 / 3.5 \text{ V} + ((VCC - (VCC - 0.5 \text{ V})) \times 1 \text{ mA}) \times 12 / 3.5 \text{ V} \\ &= 45.7 \text{ mA} + 1.71 \text{ mA} + 1.71 \text{ mA} \\ &= 49.1 \text{ mA} \end{aligned}$$

$$\begin{aligned} \text{Dynamic current of IO} &= \Sigma IO (C_{in} + C_{load}) \times \text{IO switching frequency} \times \text{Voltage} \\ &= ((8 \text{ pF} \times 16) \times 10 \text{ MHz} + (30 \text{ pF} \times 16) \times 10 \text{ MHz}) \times 3.5 \text{ V} \\ &= 21.3 \text{ mA} \end{aligned}$$

$$\begin{aligned} \text{Total power consumption} &= \text{Voltage} \times (\text{Leakage current} + \text{Dynamic current}) \\ &= (80 \text{ mA} \times 3.5 \text{ V}) + (49.1 \text{ mA} + 21.3 \text{ mA}) \times 3.5 \text{ V} \\ &= 526 \text{ mW (0.526 W)} \end{aligned}$$

$$\begin{aligned} T_j &= T_a + \theta_{ja} \times \text{Total power consumption} \\ &= 100 \text{ }^\circ\text{C} + 36.0 \text{ }^\circ\text{C/W} \times 0.526 \text{ W} \\ &= 118.9 \text{ }^\circ\text{C} \end{aligned}$$

## 2.3 AC Characteristics

### 2.3.1 Frequency

**Table 2.14 Operation frequency value in high-speed mode**

Parameter	Symbol	Min	Typ	Max	Unit	
Operation frequency	System clock (ICLK)	f	—	—	240	MHz
	Peripheral module clock (PCLKA)	—	—	120		
	Peripheral module clock (PCLKB)	—	—	60		
	Peripheral module clock (PCLKC)	—*2	—	60		
	Peripheral module clock (PCLKD)	—	—	120		
	Flash interface clock (FCLK)	—*1	—	60		

Note 1. FCLK must run at a frequency of at least 4 MHz when programming or erasing the flash memory.

Note 2. When the ADC is used, the PCLKC frequency must be at least 1 MHz.

**Table 2.15 Operation frequency value in low-speed mode**

Parameter	Symbol	Min	Typ	Max	Unit	
Operation frequency	System clock (ICLK)	f	—	—	1	MHz
	Peripheral module clock (PCLKA)	—	—	1		
	Peripheral module clock (PCLKB)	—	—	1		
	Peripheral module clock (PCLKC) *2	—*2	—	1		
	Peripheral module clock (PCLKD)	—	—	1		
	Flash interface clock (FCLK)*1	—	—	1		

Note 1. Programming or erasing the flash memory is disabled in low-speed mode.

Note 2. When the ADC is used, the PCLKC frequency must be set to at least 1 MHz.

## 2.3.2 Clock Timing

Table 2.16 Clock timing

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
EXTAL external clock input cycle time	$t_{EXcyc}$	41.66	—	—	ns	Figure 2.3
EXTAL external clock input high pulse width	$t_{EXH}$	15.83	—	—	ns	
EXTAL external clock input low pulse width	$t_{EXL}$	15.83	—	—	ns	
EXTAL external clock rise time	$t_{EXr}$	—	—	5.0	ns	
EXTAL external clock fall time	$t_{EXf}$	—	—	5.0	ns	
Main clock oscillator frequency	$f_{MAIN}$	8	—	24	MHz	—
Main clock oscillation stabilization wait time (crystal)*1	$t_{MAINOSCWT}$	—	—	—*1	ms	Figure 2.4
LOCO clock oscillation frequency	$f_{LOCO}$	29.4912	32.768	36.0448	kHz	—
LOCO clock oscillation stabilization wait time	$t_{LOCOWT}$	—	—	60.4	$\mu$ s	Figure 2.5
ILOCO clock oscillation frequency	$f_{ILOCO}$	13.5	15	16.5	kHz	—
MOCO clock oscillation frequency	$F_{MOCO}$	6.8	8	9.2	MHz	—
MOCO clock oscillation stabilization wait time	$t_{MOCOWT}$	—	—	15.0	$\mu$ s	—
HOCO clock oscillator oscillation frequency	$f_{HOCO16}$	15.78	16	16.22	MHz	$-20 \leq Ta \leq 105^{\circ}C$
	$f_{HOCO18}$	17.75	18	18.25		
	$f_{HOCO20}$	19.72	20	20.28		
	$f_{HOCO16}$	15.71	16	16.29	MHz	$-40 \leq Ta \leq -20^{\circ}C$
	$f_{HOCO18}$	17.68	18	18.32		
	$f_{HOCO20}$	19.64	20	20.36		
HOCO clock oscillation stabilization wait time*2	$t_{HOCOWT}$	—	—	64.7	$\mu$ s	—
HOCO period jitter	—	—	$\pm 85$	—	ps	—
PLL clock frequency	$f_{PLL}$	120	—	240	MHz	—
PLL2 clock frequency	$f_{PLL2}$	120	—	240	MHz	—
PLL/PLL2 clock oscillation stabilization wait time	$t_{PLLWT}$	—	—	174.9	$\mu$ s	Figure 2.6
PLL/PLL2 period jitter	—	—	$\pm 100$	—	ps	—
PLL/PLL2 long term jitter	—	—	$\pm 300$	—	ps	Term: 1 $\mu$ s, 10 $\mu$ s

- Note 1. When setting up the main clock oscillator, ask the oscillator manufacturer for an oscillation evaluation, and use the results as the recommended oscillation stabilization time. Set the MOSCWTCR register to a value equal to or greater than the recommended value. After changing the setting in the MOSCCR.MOSTP bit to start main clock operation, read the OSCSF.MOSCSF flag to confirm that it is 1, and then start using the main clock oscillator.
- Note 2. This is the time from release from reset state until the HOCO oscillation frequency ( $f_{HOCO}$ ) reaches the range for guaranteed operation.

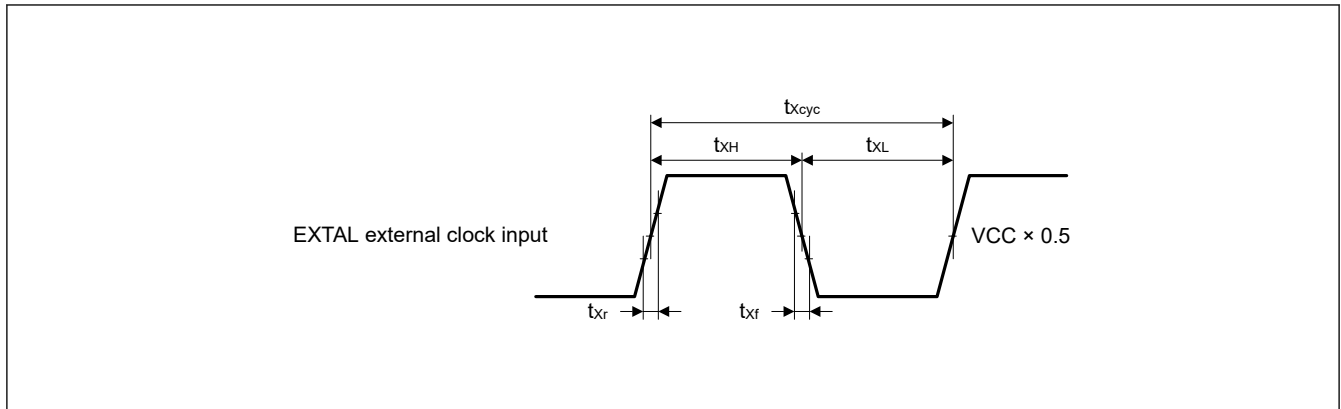


Figure 2.3 EXTAL external clock input timing

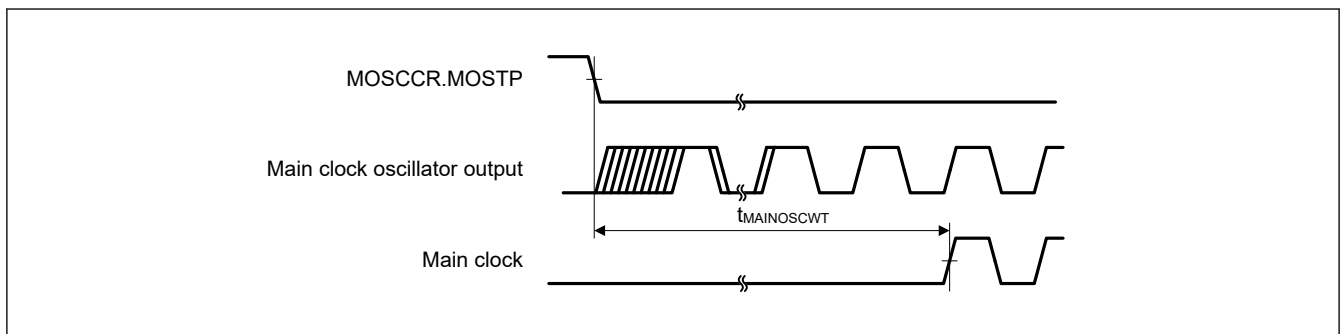


Figure 2.4 Main clock oscillation start timing

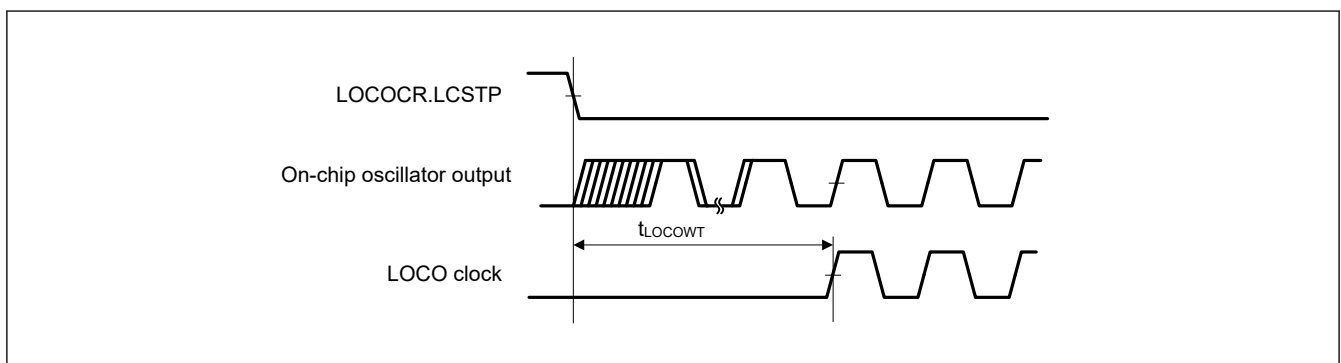


Figure 2.5 LOCO clock oscillation start timing

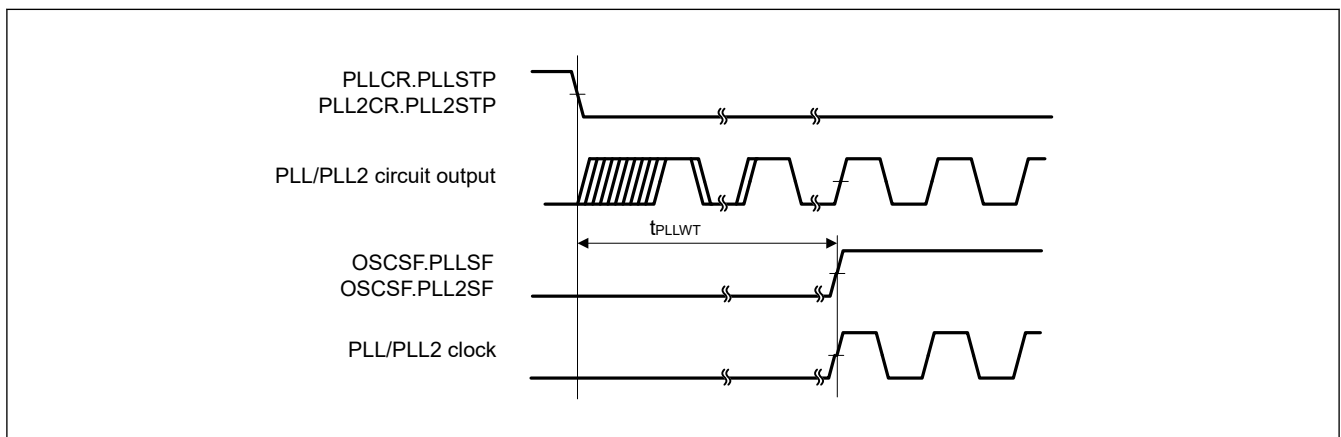


Figure 2.6 PLL/PLL2 clock oscillation start timing

2.3.3 Reset Timing

Table 2.17 Reset timing

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions	
RES pulse width	Power-on	$t_{RESWP}$	0.7	—	—	ms	Figure 2.7
	Deep Software Standby mode	$t_{RESWD}$	0.6	—	—	ms	Figure 2.8
	Software Standby mode	$t_{RESWS}$	0.3	—	—	ms	
	All other	$t_{RESW}$	200	—	—	$\mu$ s	
Wait time after RES cancellation	$t_{RESWT}$	—	37.3	41.2	$\mu$ s	Figure 2.7	
Wait time after internal reset cancellation (IWDT reset, WDT reset, software reset, SRAM parity error reset, bus master MPU error reset, TrustZone error reset, Cache parity error reset)	$t_{RESW2}$	—	324	397.7	$\mu$ s	—	

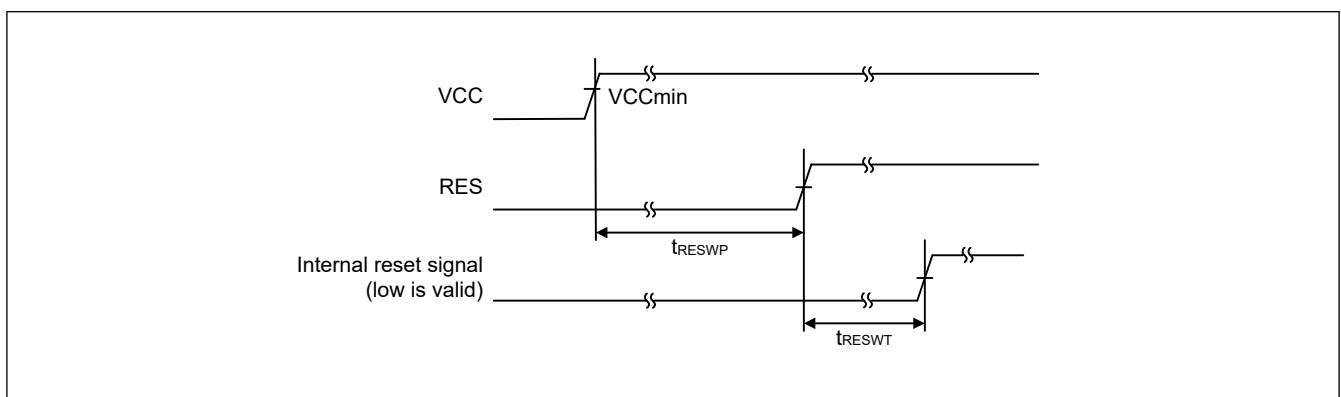


Figure 2.7 RES pin input timing under the condition that VCC exceeds  $V_{POR}$  voltage threshold

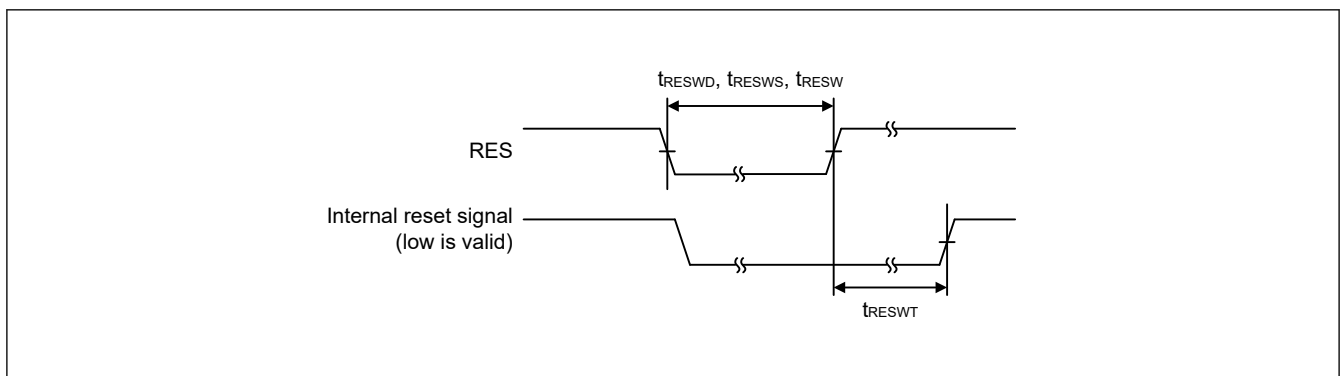


Figure 2.8 Reset input timing



## 2.3.4 Wakeup Timing

Table 2.18 Timing of recovery from low power modes

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions		
Recovery time from Software Standby mode <sup>*1</sup>	Crystal resonator connected to main clock oscillator	System clock source is main clock oscillator <sup>*2</sup>	t <sub>SBYMC</sub> <sup>*11</sup>	—	2.1	2.4	ms	Figure 2.9 The division ratio of all oscillators is 1.
		System clock source is PLL with main clock oscillator <sup>*3</sup>	t <sub>SBYPC</sub> <sup>*11</sup>	—	2.2	2.6	ms	
	External clock input to main clock oscillator	System clock source is main clock oscillator <sup>*4</sup>	t <sub>SBYEX</sub> <sup>*11</sup>	—	45	125	μs	
		System clock source is PLL with main clock oscillator <sup>*5</sup>	t <sub>SBYPE</sub> <sup>*11</sup>	—	170	255	μs	
	System clock source is LOCO <sup>*6</sup>		t <sub>SBYLO</sub> <sup>*11</sup>	—	0.7	0.9	ms	
	System clock source is HOCO clock oscillator <sup>*7</sup>		t <sub>SBYHO</sub> <sup>*11</sup>	—	55	130	μs	
	System clock source is PLL with HOCO <sup>*8</sup>		t <sub>SBYPH</sub> <sup>*11</sup>	—	175	265	μs	
	System clock source is MOCO clock oscillator <sup>*9</sup>		t <sub>SBYMO</sub> <sup>*11</sup>	—	35	65	μs	
Recovery time from Deep Software Standby mode	DPSBYCR.DEEP_CUT[1] = 0 and DPSWCR.WTSTS[5:0] = 0x0E		t <sub>DSBY</sub>	—	0.38	0.54	ms	Figure 2.10
	DPSBYCR.DEEP_CUT[1] = 1 and DPSWCR.WTSTS[5:0] = 0x19		t <sub>DSBY</sub>	—	0.55	0.73	ms	
Wait time after cancellation of Deep Software Standby mode			t <sub>DSBYWT</sub>	56	—	57	t <sub>cyc</sub>	
Recovery time from Software Standby mode to Snooze mode	High-speed mode when system clock source is HOCO (20 MHz)		t <sub>SNZ</sub>	—	35 <sup>*10</sup>	70 <sup>*10</sup>	μs	Figure 2.11
	High-speed mode when system clock source is MOCO (8 MHz)		t <sub>SNZ</sub>	—	11 <sup>*10</sup>	14 <sup>*10</sup>	μs	

- Note 1. The recovery time is determined by the system clock source. When multiple oscillators are active, the recovery time can be determined with the following equation:  
Total recovery time = recovery time for an oscillator as the system clock source + the longest t<sub>SBYOSCWT</sub> in the active oscillators - t<sub>SBYOSCWT</sub> for the system clock + 2 LOCO cycles (when LOCO is operating)
- Note 2. When the frequency of the crystal is 24 MHz (Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x05) and the greatest value of the internal clock division setting is 1.
- Note 3. When the frequency of PLL is 240 MHz (Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x05) and the greatest value of the internal clock division setting is 4.
- Note 4. When the frequency of the external clock is 24 MHz (Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x00) and the greatest value of the internal clock division setting is 1.
- Note 5. When the frequency of PLL is 240 MHz (Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x00) and the greatest value of the internal clock division setting is 4.
- Note 6. The LOCO frequency is 32.768 kHz and the greatest value of the internal clock division setting is 1.
- Note 7. The HOCO frequency is 20 MHz and the greatest value of the internal clock division setting is 1.
- Note 8. The PLL frequency is 240 MHz and the greatest value of the internal clock division setting is 4.
- Note 9. The MOCO frequency is 8 MHz and the greatest value of the internal clock division setting is 1.
- Note 10. When the SNZCR.RXDREQEN bit is set to 0, the following time is added as the power supply recovery time: 16 μs (typical), 48 μs (maximum).
- Note 11. The recovery time can be calculated with the equation of t<sub>SBYOSCWT</sub> + t<sub>SBYSEQ</sub>. And they can be determined with the following value and equation. For n, the greatest value is selected from among the internal clock division settings.

Wakeup time	TYP		MAX		Unit
	t <sub>SBYOSCWT</sub>	t <sub>SBYSEQ</sub>	t <sub>SBYOSCWT</sub>	t <sub>SBYSEQ</sub>	
t <sub>SBYMC</sub>	(MSTS[7:0]*32 + 3) / 0.262	35 + 18 / f <sub>ICLK</sub> + 4n / f <sub>MAIN</sub>	(MSTS[7:0]*32 + 14) / 0.236	62 + 18 / f <sub>ICLK</sub> + 4n / f <sub>MAIN</sub>	μs
t <sub>SBYPC</sub>	(MSTS[7:0]*32 + 34) / 0.262	35 + 18 / f <sub>ICLK</sub> + 4n / f <sub>PLL</sub>	(MSTS[7:0]*32 + 45) / 0.236	62 + 18 / f <sub>ICLK</sub> + 4n / f <sub>PLL</sub>	μs

Wakeup time	TYP		MAX		Unit
	tSBYOSCWT	tSBYSEQ	tSBYOSCWT	tSBYSEQ	
tSBYEX	10	$35 + 18 / f_{ICLK} + 4n / f_{EXMAIN}$	62	$62 + 18 / f_{ICLK} + 4n / f_{EXMAIN}$	μs
tSBYPE	135	$35 + 18 / f_{ICLK} + 4n / f_{PLL}$	192	$62 + 18 / f_{ICLK} + 4n / f_{PLL}$	μs
tSBYLO	0	$35 + 18 / f_{ICLK} + 4n / f_{LOCO}$	0	$62 + 18 / f_{ICLK} + 4n / f_{LOCO}$	μs
tSBYHO	20	$35 + 18 / f_{ICLK} + 4n / f_{HOCO}$	67	$62 + 18 / f_{ICLK} + 4n / f_{HOCO}$	μs
tSBYPH	140	$35 + 18 / f_{ICLK} + 4n / f_{PLL}$	202	$62 + 18 / f_{ICLK} + 4n / f_{PLL}$	μs
tSBYMO	0	$35 + 18 / f_{ICLK} + 4n / f_{MOCO}$	0	$62 + 18 / f_{ICLK} + 4n / f_{MOCO}$	μs

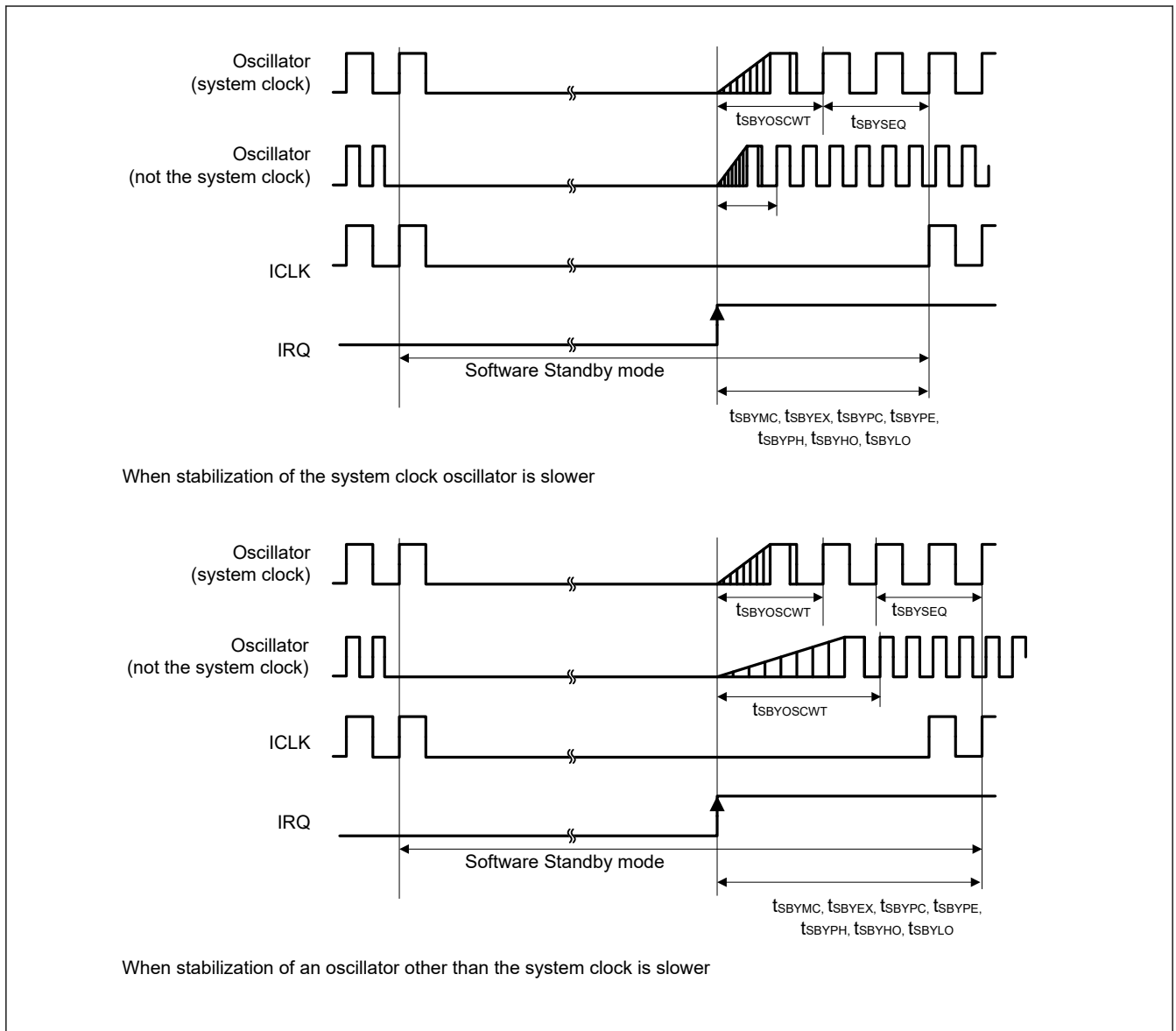


Figure 2.9 Software Standby mode cancellation timing

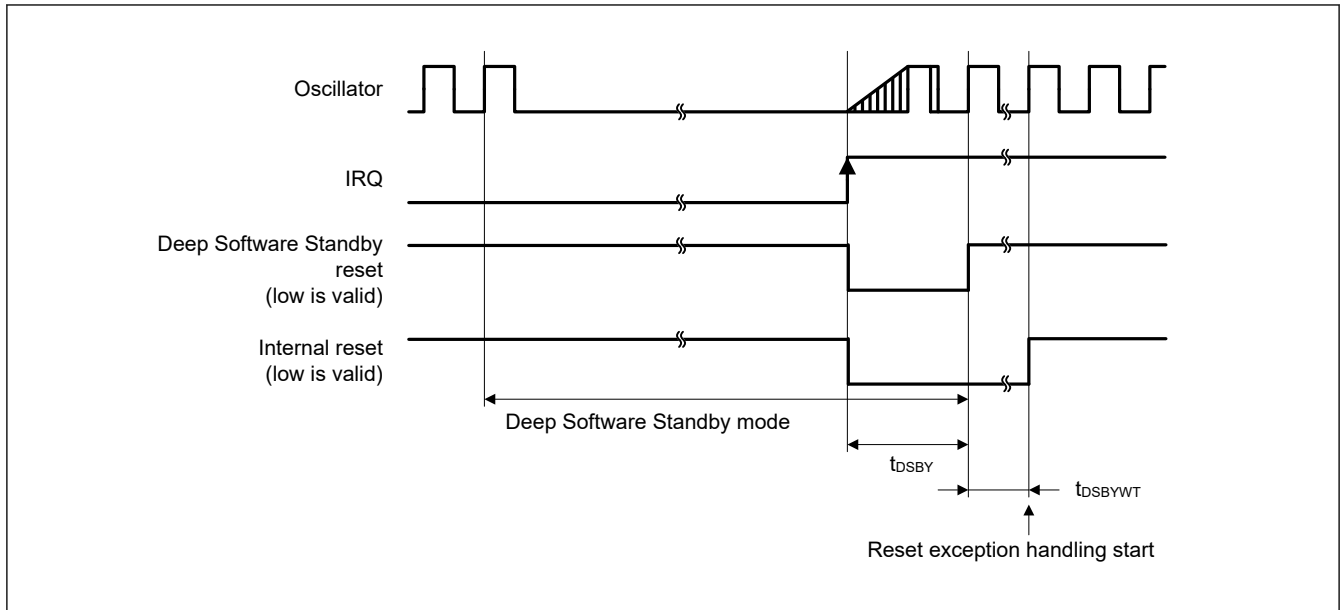
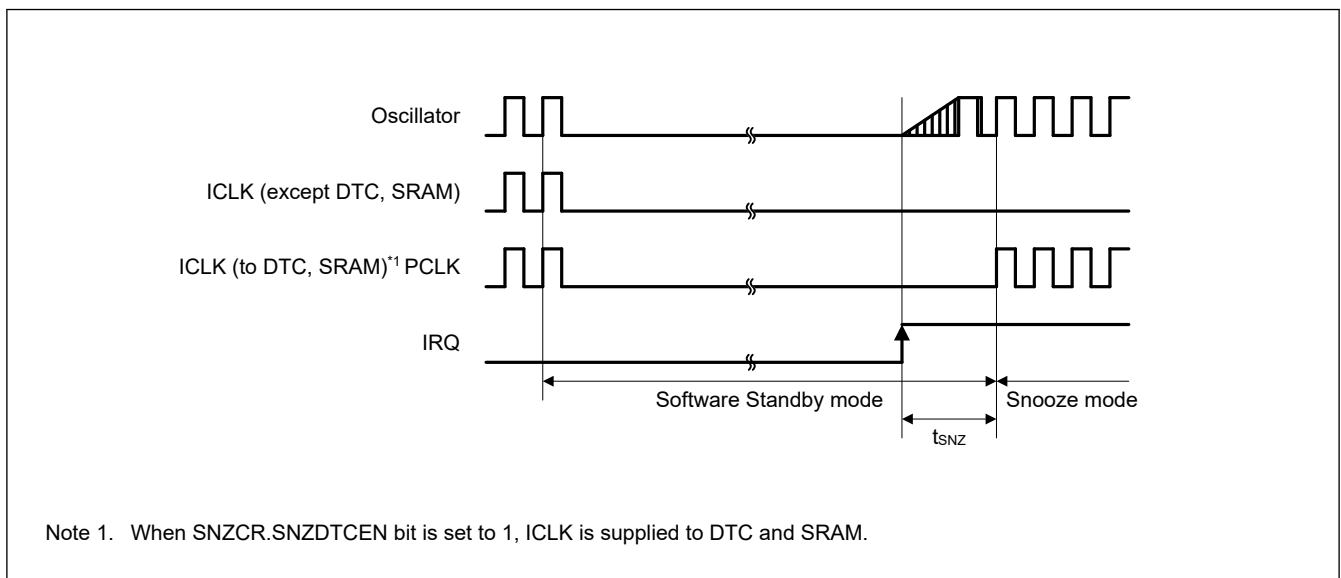


Figure 2.10 Deep Software Standby mode cancellation timing



Note 1. When SNZCR.SNZDTCEN bit is set to 1, ICLK is supplied to DTC and SRAM.

Figure 2.11 Recovery timing from Software Standby mode to Snooze mode

### 2.3.5 NMI and IRQ Noise Filter

Table 2.19 NMI and IRQ noise filter

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions	
NMI pulse width	$t_{NMIW}$	200	—	—	ns	NMI digital filter disabled	$t_{Pcyc} \times 2 \leq 200$ ns
		$t_{Pcyc} \times 2^{*1}$	—	—			$t_{Pcyc} \times 2 > 200$ ns
		200	—	—		NMI digital filter enabled	$t_{NMICK} \times 3 \leq 200$ ns
		$t_{NMICK} \times 3.5^{*2}$	—	—			$t_{NMICK} \times 3 > 200$ ns
IRQ pulse width	$t_{IRQW}$	200	—	—	ns	IRQ digital filter disabled	$t_{Pcyc} \times 2 \leq 200$ ns
		$t_{Pcyc} \times 2^{*1}$	—	—			$t_{Pcyc} \times 2 > 200$ ns
		200	—	—		IRQ digital filter enabled	$t_{IRQCK} \times 3 \leq 200$ ns
		$t_{IRQCK} \times 3.5^{*3}$	—	—			$t_{IRQCK} \times 3 > 200$ ns

- Note: 200 ns minimum in Software Standby mode.
- Note: If the clock source is switched, add 4 clock cycles of the switched source.
- Note 1.  $t_{P_{cyc}}$  indicates the PCLKB cycle.
- Note 2.  $t_{NMICK}$  indicates the cycle of the NMI digital filter sampling clock.
- Note 3.  $t_{IRQCK}$  indicates the cycle of the IRQi digital filter sampling clock.

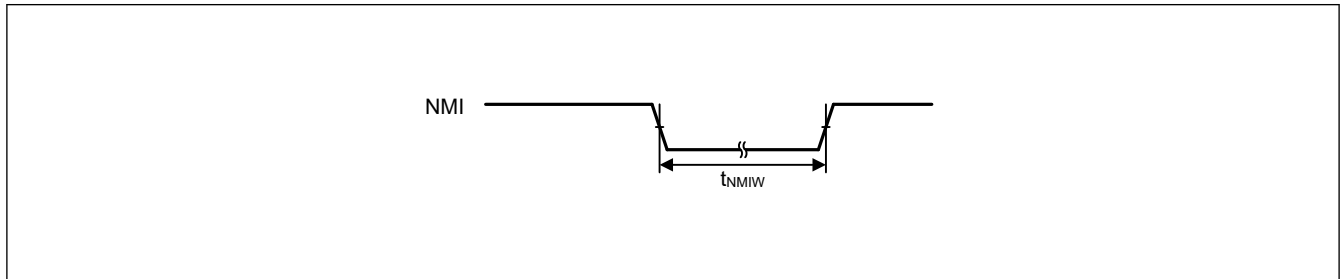


Figure 2.12 NMI interrupt input timing

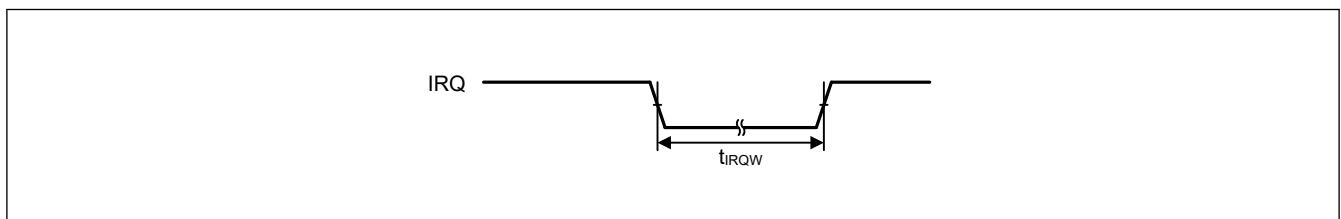


Figure 2.13 IRQ interrupt input timing

### 2.3.6 I/O Ports, POEG, GPT, AGT, KINT and ADC Trigger Timing

Table 2.20 I/O ports, POEG, GPT, AGT, KINT and ADC trigger timing (1 of 4)

GPT Conditions:  
 High drive output is selected in the Port Drive Capability bit in the PmnPFS register.  
 AGT Conditions:  
 Middle drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions
I/O ports	Input data pulse width	$t_{PRW}$	1.5	—	—	$t_{cyc}$	Figure 2.14

**Table 2.20 I/O ports, POEG, GPT, AGT, KINT and ADC trigger timing (2 of 4)**

GPT Conditions:

High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

AGT Conditions:

Middle drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter		Symbol	Min	Typ	Max	Unit	Test conditions	
POEG	GTETRGN input pulse width	$t_{POEW}$	1.5	—	—	$t_{Pcyc}$	<a href="#">Figure 2.15</a>	
	Output disable time	Input level detection of the GTETRGN pin (via flag)	$t_{POEGDI}$	—	—	3 PCLKB + 0.34	$\mu\text{s}$	<a href="#">Figure 2.16</a> When the digital noise filter is not in use (POEGn.NFE N = 0 (n = A to D))
		Detection of the output stopping signal from GPT (deadtime error, simultaneous high output, or simultaneous low output)	$t_{POEGDE}$	—	—	0.5	$\mu\text{s}$	<a href="#">Figure 2.17</a>
		Edge detection signal from a comparator	$t_{POEGDC}$	—	—	4 PCLKB + 0.5	$\mu\text{s}$	<a href="#">Figure 2.18</a> The time is that when the noise filter for ACMPHS is not in use (CMPCTL.CDFS[1:0] = 00) and excludes the time for detection by ACMPHS.
		Register setting	$t_{POEGDS}$	—	—	1 PCLKB + 0.3	$\mu\text{s}$	<a href="#">Figure 2.19</a> Time for access to the register is not included.
		Oscillation stop detection*3	$t_{POEGDOS}$	—	$\leq 1$	—	$\mu\text{s}$	<a href="#">Figure 2.20</a>
		Input level detection of the GTETRGN pin (direct path)	$t_{POEGDDI}$	—	—	2 PCLKB + 1 PCLKD + 0.34	$\mu\text{s}$	<a href="#">Figure 2.21</a>
		Level detection signal from a comparator	$t_{POEGDDC}$	—	—	3 PCLKD + 0.3	$\mu\text{s}$	<a href="#">Figure 2.22</a> The time is that when the noise filter for ACMPHS is not in use (CMPCTL.CDFS[1:0] = 00) and excludes the time for detection by ACMPHS.

**Table 2.20 I/O ports, POEG, GPT, AGT, KINT and ADC trigger timing (3 of 4)**

GPT Conditions:

High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

AGT Conditions:

Middle drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter			Symbol	Min	Typ	Max	Unit	Test conditions	
GPT	Input capture pulse width	Single edge	$t_{GTICW}$	1.5	—	—	$t_{PDcyc}$	Figure 2.23	
		Dual edge		2.5	—	—			
	GTIOCxY output skew (x = 0 to 3, Y = A or B)	Middle drive buffer	$t_{GTISK}^{*1}$	—	—	4	ns	Figure 2.24	
		High drive buffer		—	—	4			
		High current output buffer		—	—	4			
	GTIOCxY output skew (x = 4 to 6, Y = A or B)	Middle drive buffer		—	—	4			
		High drive buffer		—	—	4			
		High current output buffer		—	—	4			
	GTIOCxY output skew (x = 7 to 9, Y = A or B)	Middle drive buffer		—	—	4			
		High drive buffer		—	—	4			
		High current output buffer		—	—	4			
	GTIOCxY output skew (x = 0 to 9, Y = A or B)	Middle drive buffer	—	—	6				
		High drive buffer	—	—	6				
		High current output buffer	—	—	6				
	OPS output skew GTOUUP, GTOULO, GTOVUP, GTOVLO, GTOWUP, GTOWLO			$t_{GTOSK}$	—	—	5	ns	Figure 2.25
	External trigger input pulse width	Synchronous clock	Single-edge setting	$t_{GTEW}$	1.5	—	—	$t_{Pcyc}$	Figure 2.26
			Both-edge setting		2.5	—	—		
		Asynchronous clock	Single-edge setting		2.5	—	—		
			Both-edge setting		3.5	—	—		
	Timer clock pulse width	Synchronous clock	Single-edge setting	$t_{GTCKWH}$ , $t_{GTCKWL}$	1.5	—	—	$t_{Pcyc}$	Figure 2.27
Both-edge setting			2.5		—	—			
Asynchronous clock		Single-edge setting	2.5		—	—			
		Both-edge setting	3.5		—	—			
GPT (PWM Delay Generation Circuit)	GTIOCxY_Z skew (x = 0 to 3, Y = A or B, Z = A to D)		$t_{HRSK}^{*2}$	—	—	4.0	ns	Figure 2.28	
AGT	AGTIO, AGTEE input cycle		$t_{ACYC}^{*2}$	50	—	—	ns	Figure 2.29	
	AGTIO, AGTEE input high width, low width		$t_{ACKWH}$ , $t_{ACKWL}$	20	—	—	ns		
	AGTIO, AGTO, AGTOA, AGTOB output cycle		$t_{ACYC2}$	33.3	—	—	ns		
KINT	KRn (n = 00 to 07) pulse width		$t_{KR}$	250	—	—	ns	Figure 2.30	

**Table 2.20 I/O ports, POEG, GPT, AGT, KINT and ADC trigger timing (4 of 4)**

GPT Conditions:

High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

AGT Conditions:

Middle drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
ADC	ADC trigger input pulse width	t <sub>TRGW</sub>	1.5	—	—	t <sub>ADcyc</sub> <a href="#">Figure 2.31</a>

Note: t<sub>l<sub>cyc</sub></sub>: ICLK cycle, t<sub>P<sub>cyc</sub></sub>: PCLKB cycle, t<sub>P<sub>Dcyc</sub></sub>: GTCLK cycle, t<sub>AD<sub>cyc</sub></sub>: ADCLK cycle.

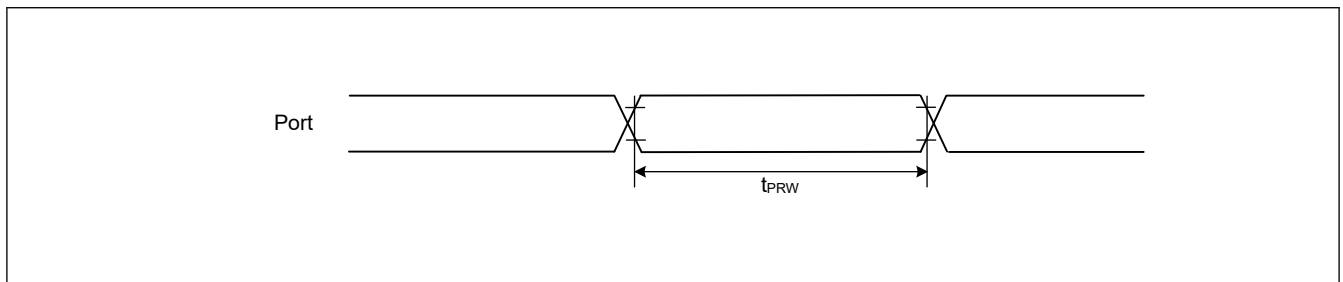
Note 1. This skew applies when the same driver I/O is used. If the I/O of the middle and high drivers is mixed, operation is not guaranteed.

Note 2. Constraints on input cycle:

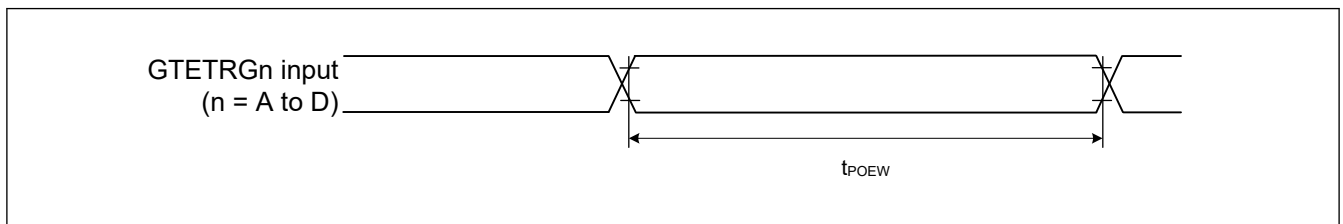
When not switching the source clock: t<sub>P<sub>cyc</sub></sub> × 2 < t<sub>AC<sub>YC</sub></sub> should be satisfied.

When switching the source clock: t<sub>P<sub>cyc</sub></sub> × 6 < t<sub>AC<sub>YC</sub></sub> should be satisfied.

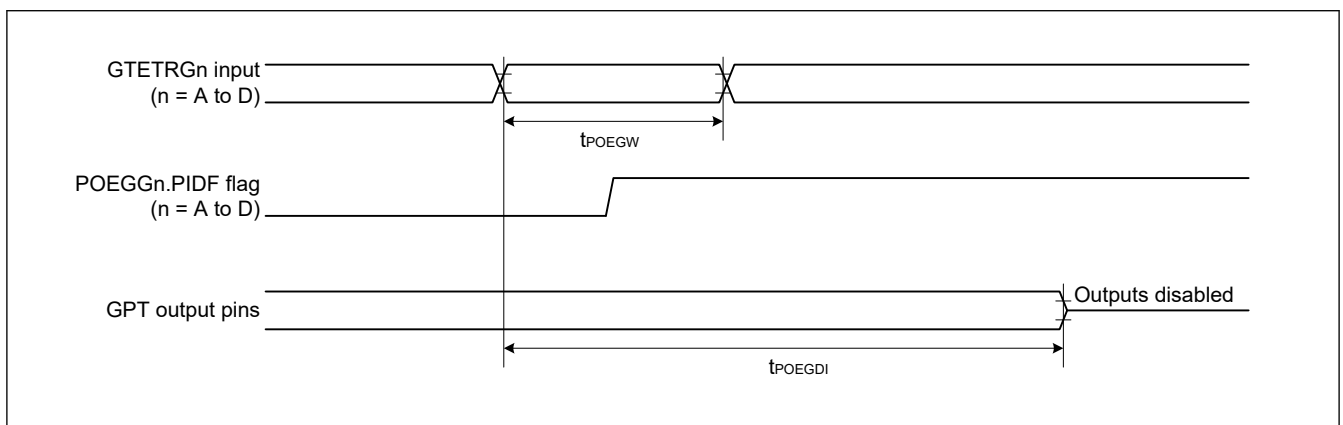
Note 3. Reference value.



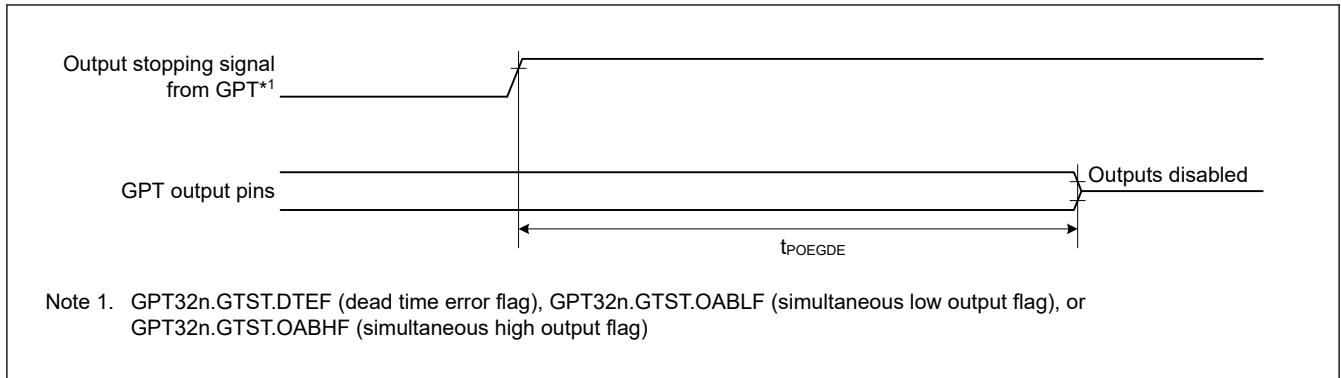
**Figure 2.14 I/O ports input timing**



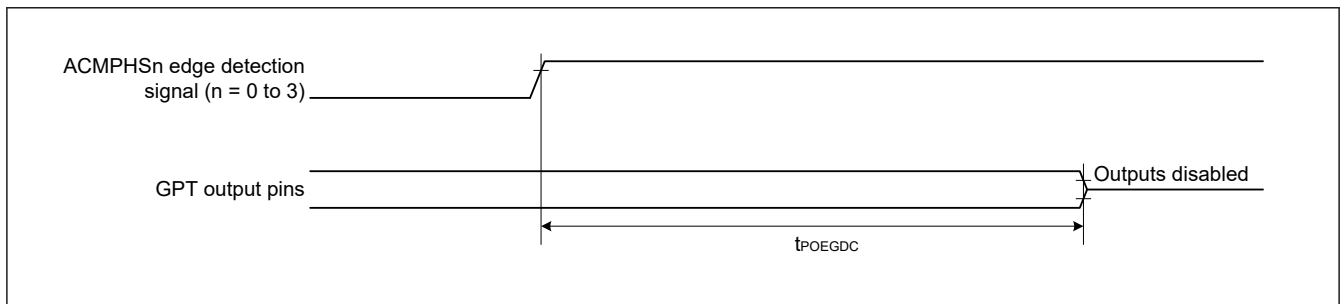
**Figure 2.15 POEG input trigger timing**



**Figure 2.16 Output Disable Time for POEG via Detection Flag in Response to the Input Level Detection of the GTETRn pin**



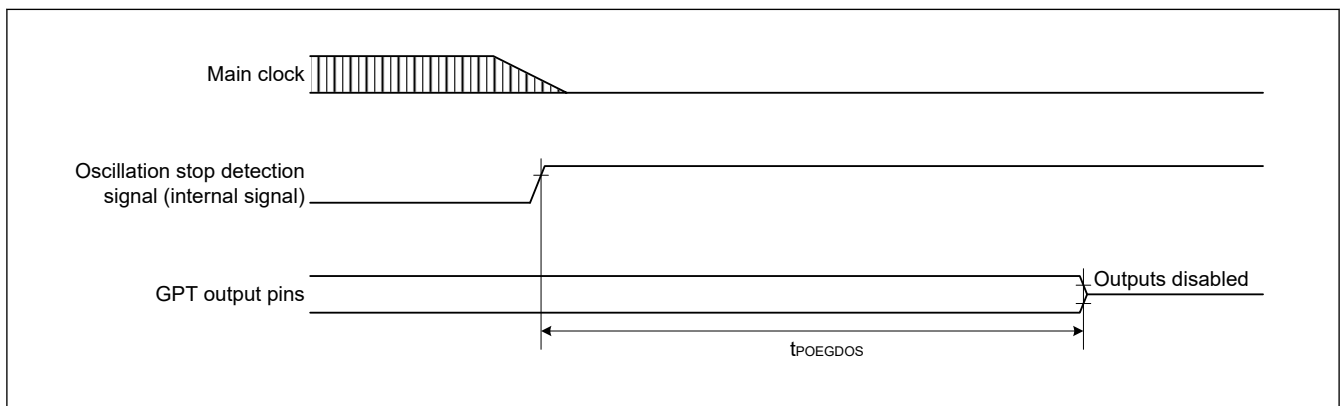
**Figure 2.17 Output Disable Time for POEG in Response to Detection of the Output Stopping Signal from GPT**



**Figure 2.18 Output Disable Time for POEG in Response to Edge Detection Signal from ACPHPS**

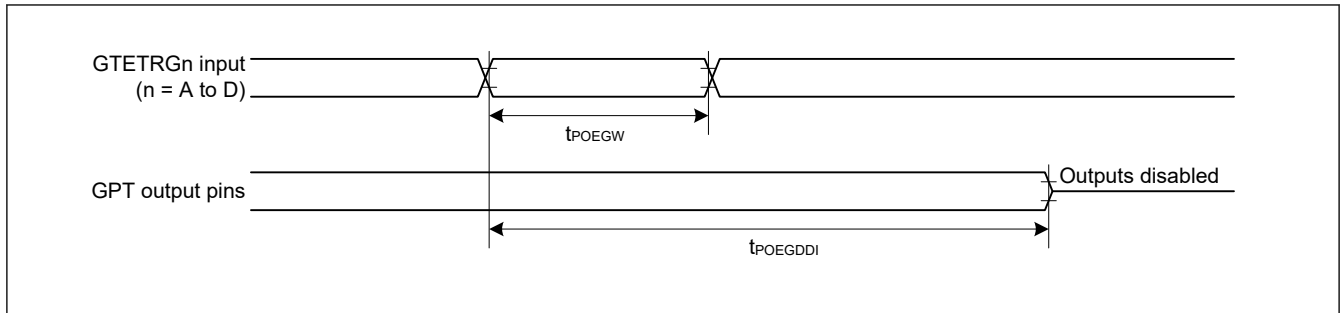


**Figure 2.19 Output Disable Time for POEG in Response to the Register Setting**

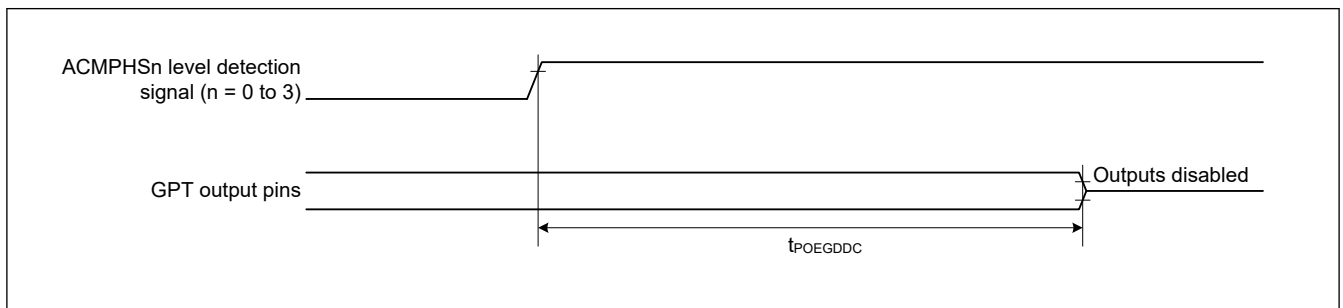


**Figure 2.20 Output Disable Time of POEG in Response to the Oscillation Stop Detection**

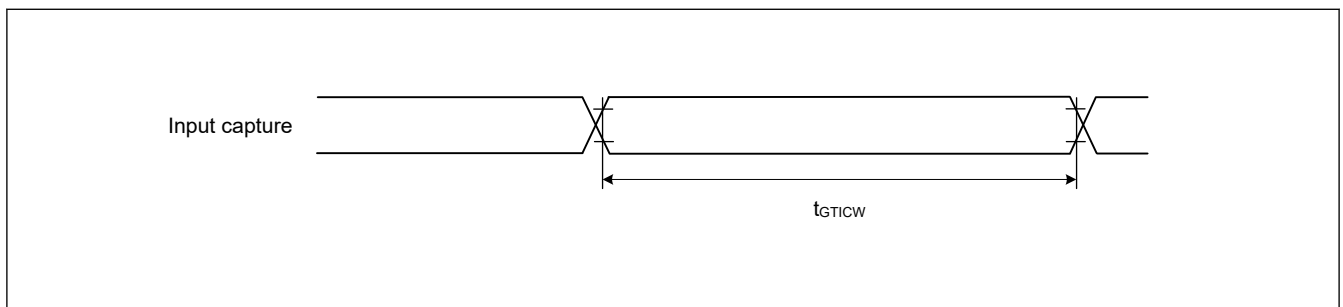




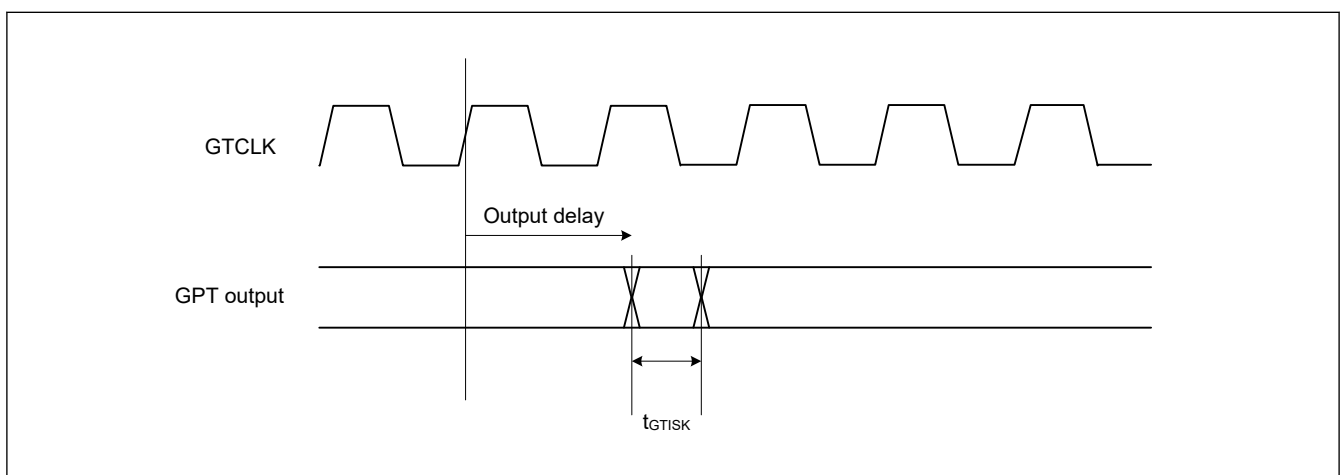
**Figure 2.21 Output Disable Time for POEG in Direct Response to the Input Level Detection of the GTETRn pin**



**Figure 2.22 Output Disable Time for POEG in Response to Level Detection Signal from ACMPHS**



**Figure 2.23 GPT input capture timing**



**Figure 2.24 GPT output delay skew**

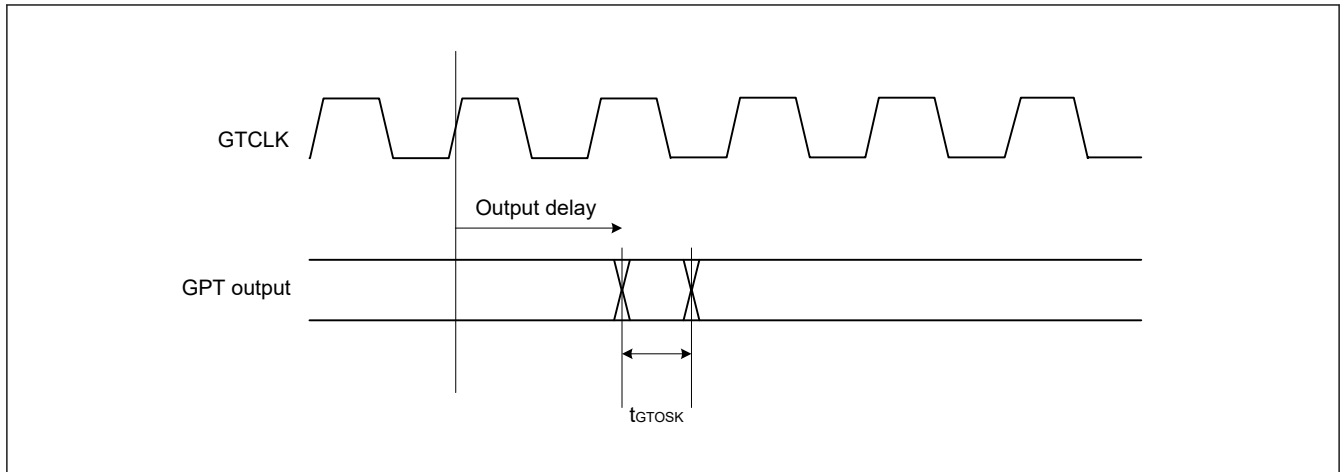


Figure 2.25 GPT output delay skew for OPS

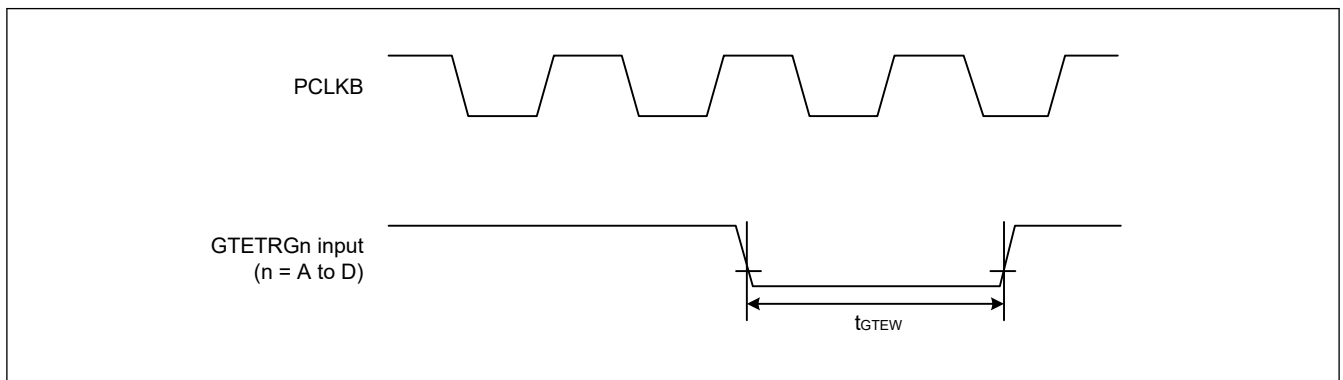


Figure 2.26 GPT External Trigger Input Timing

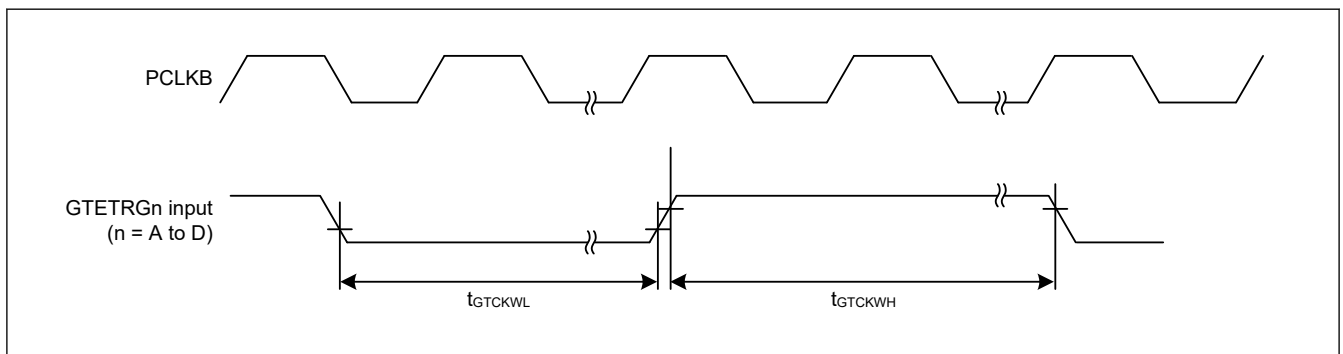


Figure 2.27 GPT Clock Input Timing

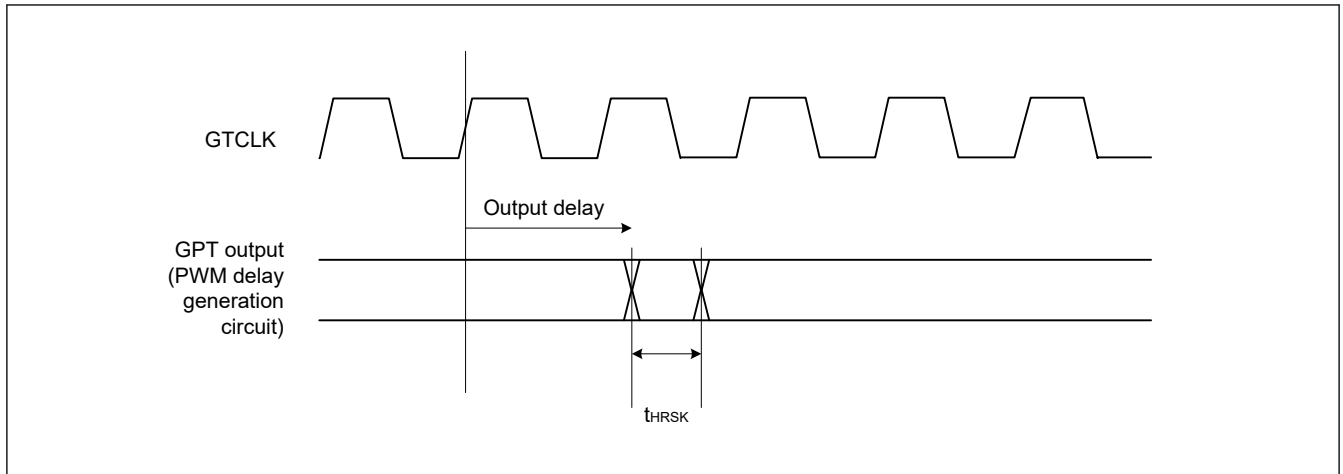


Figure 2.28 GPT (PDG) output delay skew

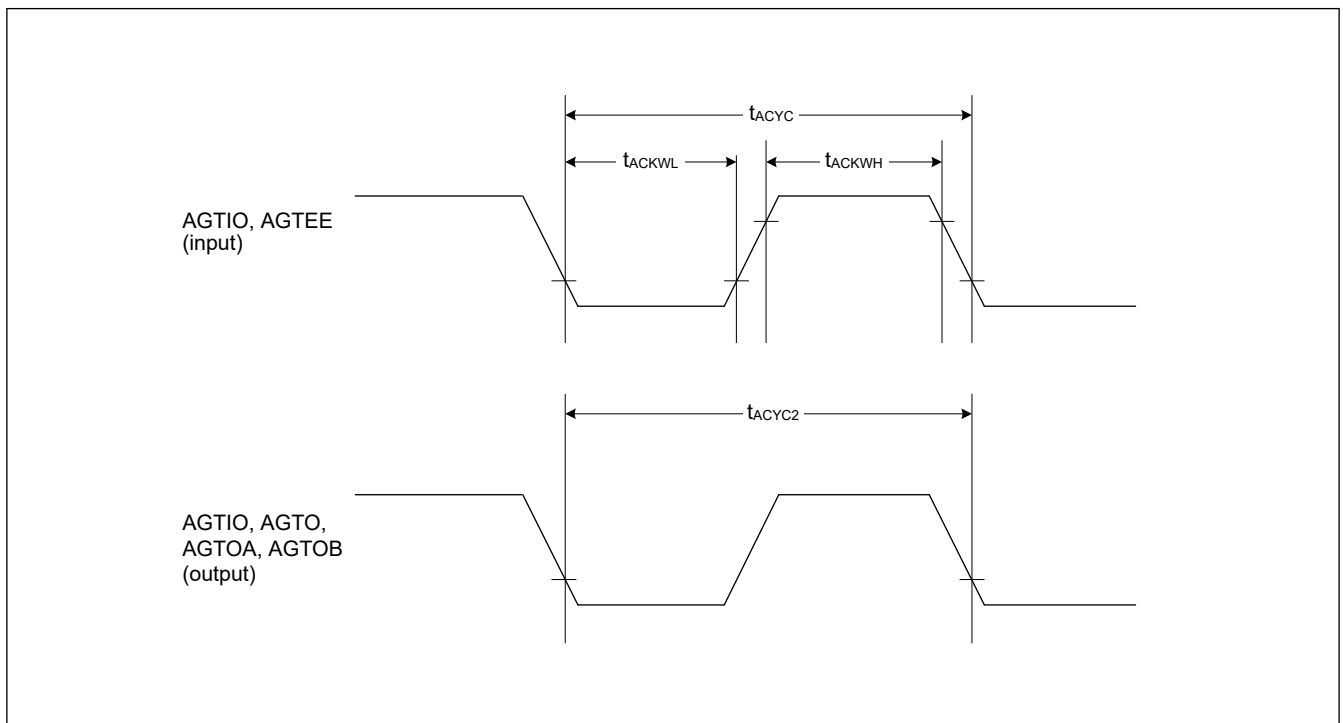


Figure 2.29 AGT input/output timing

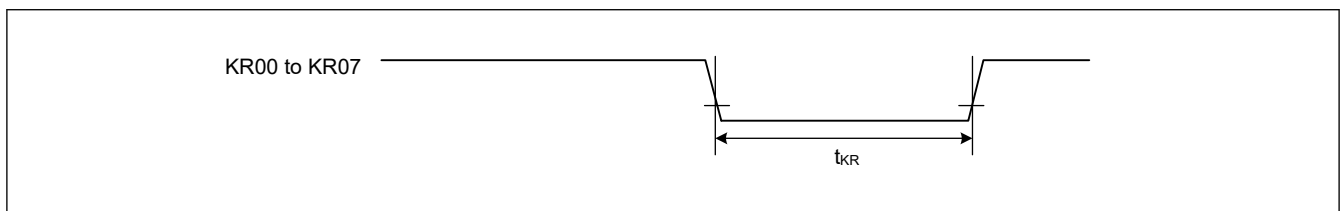


Figure 2.30 Key interrupt input timing

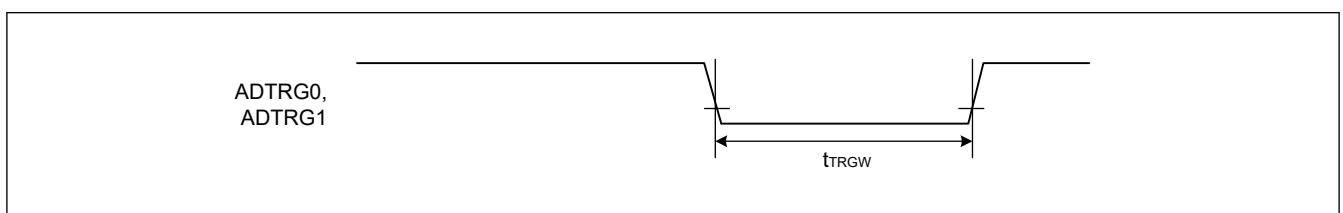


Figure 2.31 ADC trigger input timing

### 2.3.7 PDG Timing

**Table 2.21 PDG timing**

Parameter	Min	Typ	Max	Unit	Test conditions
Operation frequency	80	—	200	MHz	—
Resolution	—	156	—	ps	GPTCLK = 200 MHz
DNL*1	—	±2.0	—	LSB	—

Note 1. This value normalizes the differences between lines in 1-LSB resolution.

### 2.3.8 CAC Timing

**Table 2.22 CAC timing**

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
CAC CACREF input pulse width	$t_{CACREF}$	$t_{PBcyc} \leq t_{cac}^{*1}$	—	$4.5 \times t_{cac} + 3 \times t_{PBcyc}$	ns	—
		$t_{PBcyc} > t_{cac}^{*1}$	—	$5 \times t_{cac} + 6.5 \times t_{PBcyc}$	ns	

Note:  $t_{PBcyc}$ : PCLKB cycle.

Note 1.  $t_{cac}$ : CAC count clock source cycle.

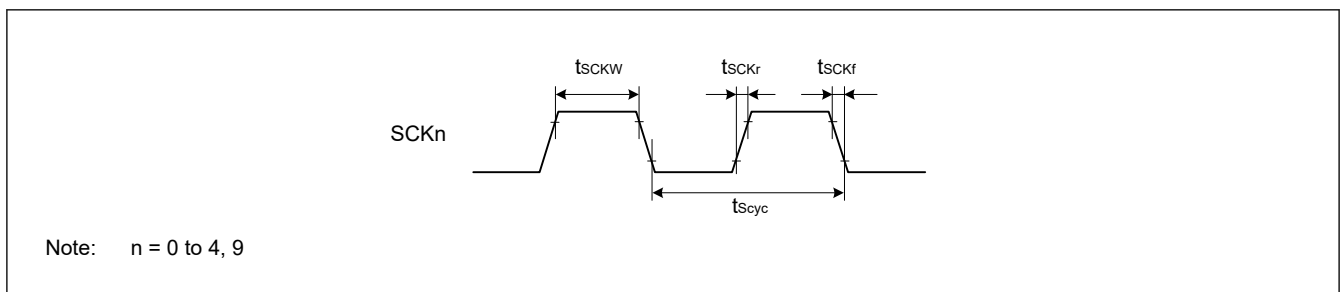
### 2.3.9 SCI Timing

**Table 2.23 SCI timing (Asynchronous mode)**

Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter	Symbol	Min	Max	Unit	Note
Input clock cycle	$t_{scyc}$	4	—	$t_{Tcyc}$	
Input clock pulse width	$t_{sckw}$	0.4	0.6	$t_{scyc}$	
Input clock rise time	$t_{sckr}$	—	5	ns	
Input clock fall time	$t_{sckf}$	—	5	ns	
Output clock cycle	$t_{scyc}$	6	—	$t_{Tcyc}$	
Output clock pulse width	$t_{sckw}$	0.4	0.6	$t_{scyc}$	
Output clock rise time	$t_{sckr}$	—	5	ns	
Output clock fall time	$t_{sckf}$	—	5	ns	

Note:  $t_{Tcyc}$ : SCITCLK cycle.



**Figure 2.32 SCK clock input/output timing**

**Table 2.24 SCI timing (Simple SPI) (1 of 2)**

Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter	High Speed/Default	Symbol	Min	Max	Unit	Note
SCK clock cycle output	Master	$t_{SPcyc}$	2	65536	$t_{Tcyc}$	
SCK clock cycle input	Slave		2	—		

**Table 2.24 SCI timing (Simple SPI) (2 of 2)**

Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter		High Speed/ Default	Symbol	Min	Max	Unit	Note
SCK clock high pulse width	Master		$t_{SPCKWH}$	0.4	0.6	$t_{SPcyc}$	
	Slave						
SCK clock low pulse width	Master		$t_{SPCKWL}$	0.4	0.6	$t_{SPcyc}$	
	Slave						
SCK clock rise and fall time	Output		$t_{SPCKr}, t_{SPCKf}$	—	5	ns	
	Input			—	1	us	
Data input setup time	Master	High Speed* <sup>1</sup>	$t_{SU}$	1.7	—	ns	
		Default* <sup>2</sup>		3	—	ns	
	Slave			3.3	—	ns	
Data input hold time	Master	High Speed* <sup>1</sup>	$t_H$	12	—	ns	
		Default* <sup>2</sup>		14	—	ns	
	Slave			3	—	ns	
Data output delay	Master	High Speed* <sup>1</sup>	$t_{OD}$	—	5	ns	
		Default* <sup>2</sup>		—	7.3	ns	
	Slave	High Speed* <sup>1</sup>		—	15	ns	
		Default* <sup>2</sup>		—	21	ns	
Data output hold time	Master		$t_{OH}$	0	—	ns	
	Slave			0	—	ns	
Data rise and fall time	Output		$t_{Dr}, t_{Df}$	—	5	ns	
	Input			—	1	ns	
Slave access time			$t_{SA}$	—	5	$t_{Tcyc}$	
Slave output release time			$t_{REL}$	—	5	$t_{Tcyc}$	

Note:  $t_{Tcyc}$ : SCITCLK cycle.

Note 1. Must use pins that have a letter appended to their name, for instance \_A, \_B, \_C, to indicate group membership. SCI0 is instance \_A, SCI2 and SCI3 are instance \_B, SCI1 and SCI9 are instance \_C, SCI4 is instance \_C and RXD is only PD14.

Note 2. All pins of group membership can be used.

**Table 2.25 SCI timing (Simple SPI mode)**

Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter	Symbol	Min	Max	Unit	Note
SS input setup time	$t_{LEAD}$	1	—	$t_{SPcyc}$	
SS input hold time	$t_{LAG}$	1	—	$t_{SPcyc}$	
SS input rise and fall time	$t_{SSLr}, t_{SSLf}$	—	1	us	

**Table 2.26 SCI timing (Clock synchronous mode) (1 of 2)**

Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter		High Speed/ Default	Symbol	Min	Max	Unit	Note
SCK clock cycle output	Master		$t_{SPcyc}$	2	—	$t_{Tcyc}$	
SCK clock cycle input	Slave			2	—		
SCK clock high pulse width	Master		$t_{SPCKWH}$	0.4	0.6	$t_{SPcyc}$	
	Slave						

**Table 2.26 SCI timing (Clock synchronous mode) (2 of 2)**

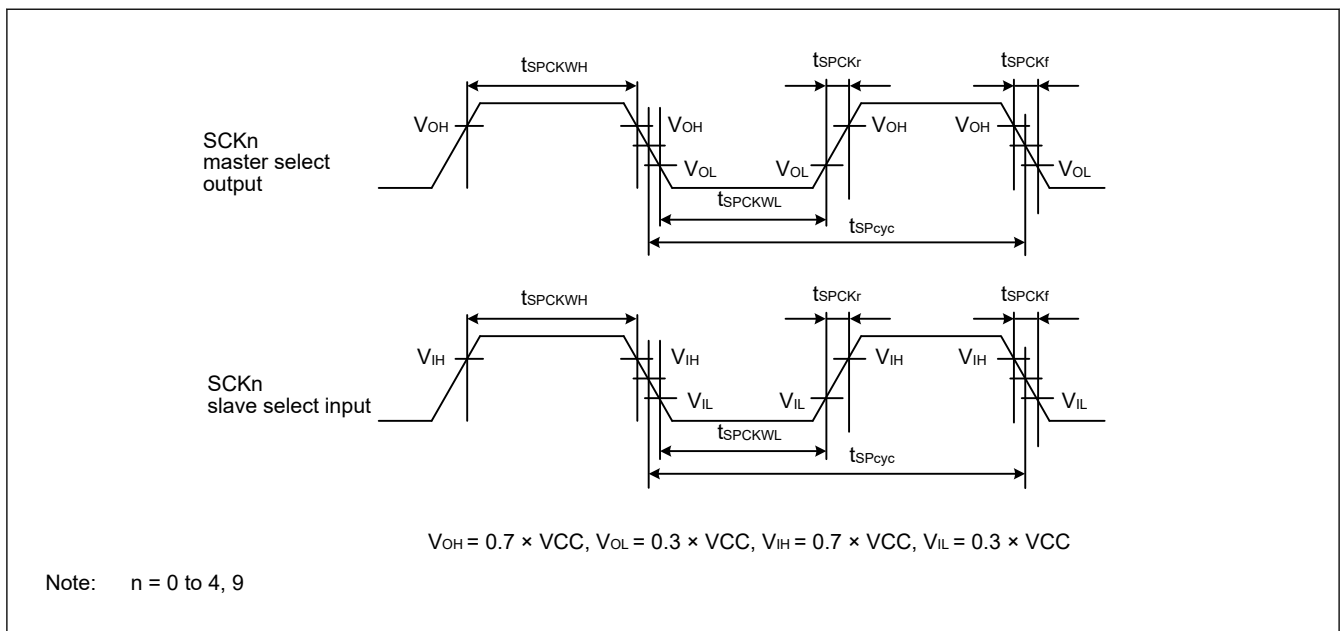
Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter		High Speed/ Default	Symbol	Min	Max	Unit	Note
SCK clock low pulse width	Master		$t_{SPCKWL}$	0.4	0.6	$t_{SPcyc}$	
	Slave						
SCK clock rise and fall time	Output		$t_{SPCKr}, t_{SPCKf}$	—	5	ns	
	Input						
Data input setup time	Master	High Speed*1	$t_{SU}$	2.6	—	ns	
		Default*2		2.8	—	ns	
	Slave			3.3		ns	
Data input hold time	Master	High Speed*1	$t_H$	12	—	ns	
		Default*2		14	—	ns	
	Slave			3		ns	
Data output delay	Master	High Speed*1	$t_{OD}$	—	5	ns	
		Default*2		—	7.3	ns	
	Slave	High Speed*1		—	15	ns	
		Default*2		—	21	ns	
Data output hold time	Master		$t_{OH}$	0	—	ns	
	Slave			0	—	ns	
Data rise and fall time	Output		$t_{Dr}, t_{Df}$	—	5	ns	
	Input			—	5	ns	

Note:  $t_{Tcyc}$ : SCITCLK cycle.

Note 1. Must use pins that have a letter appended to their name, for instance \_A, \_B, \_C, to indicate group membership. SCI0 is instance \_A, SCI2 and SCI3 are instance \_B, SCI1 and SCI9 are instance \_C, SCI4 is instance \_C and RXD is only PD14.

Note 2. All pins of group membership can be used.



**Figure 2.33 SCI simple SPI mode clock timing**

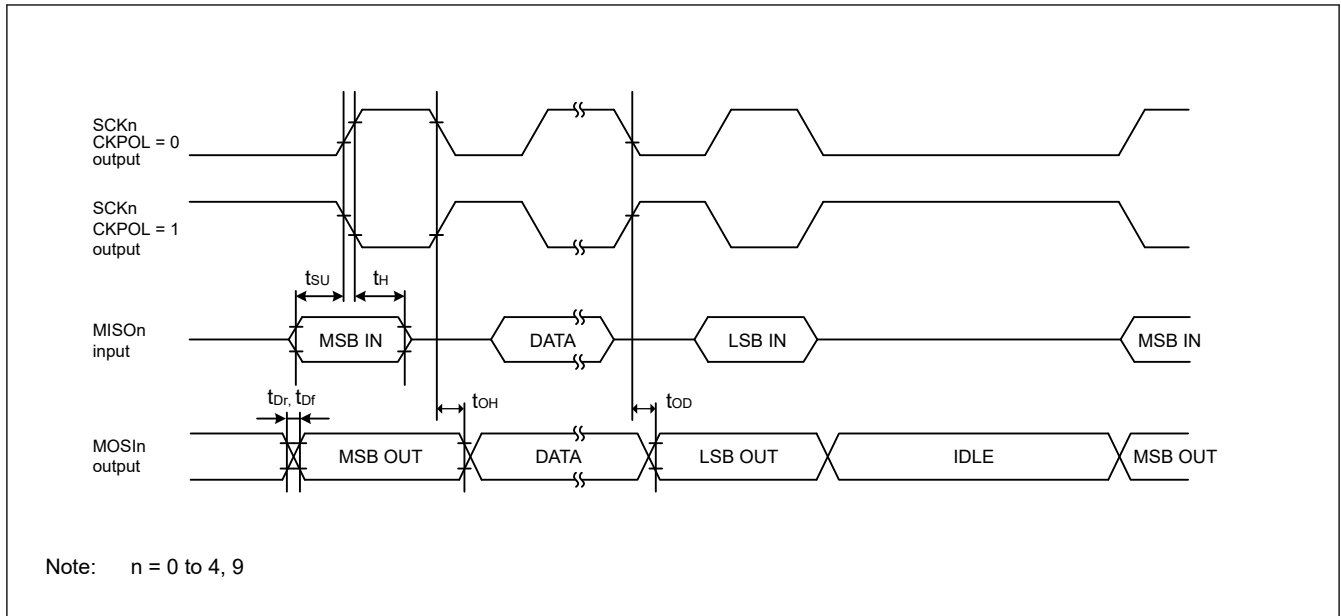


Figure 2.34 SCI simple SPI mode timing for master when CKPH = 1

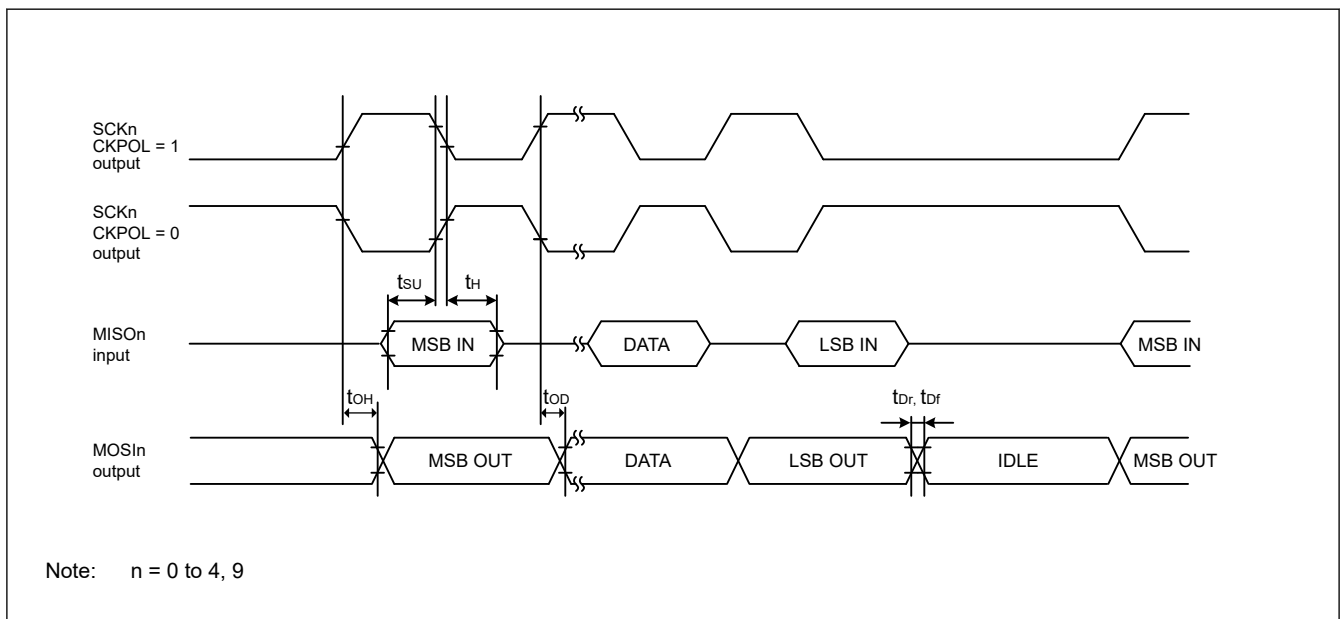


Figure 2.35 SCI simple SPI mode timing for master when CKPH = 0

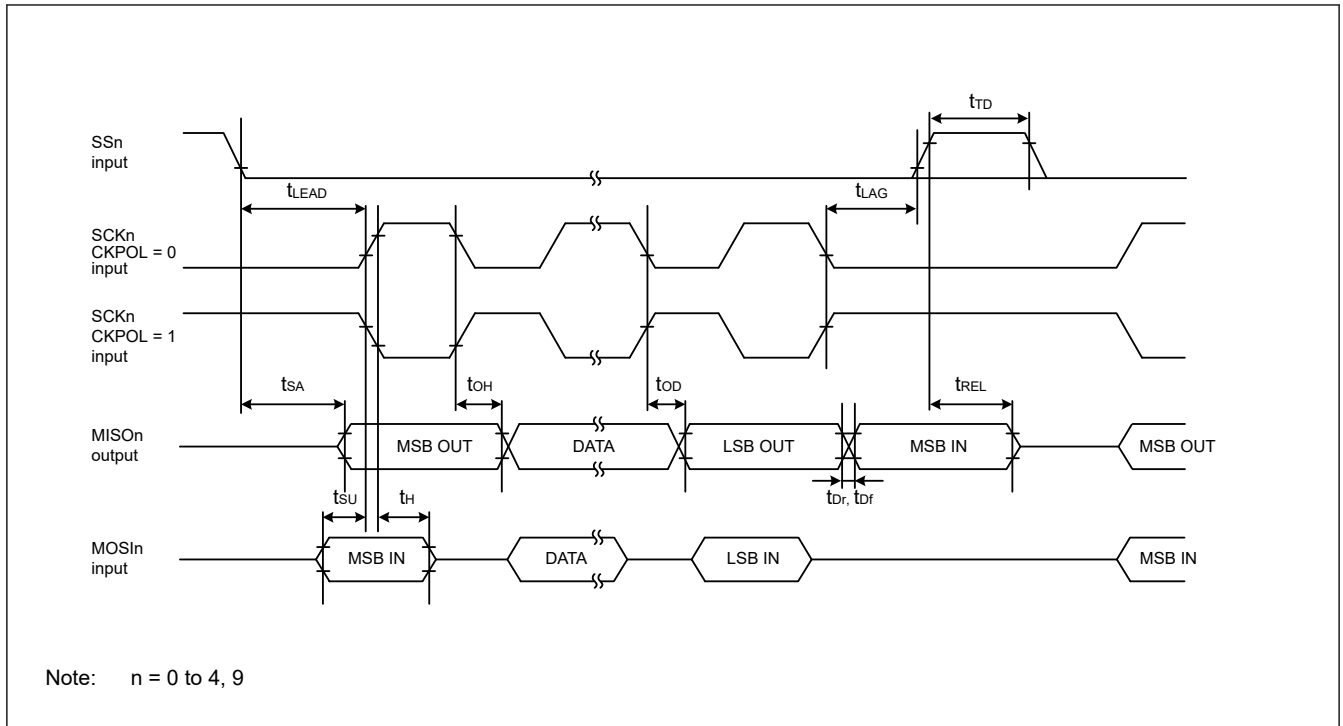


Figure 2.36 SCI simple SPI mode timing for slave when CKPH = 1

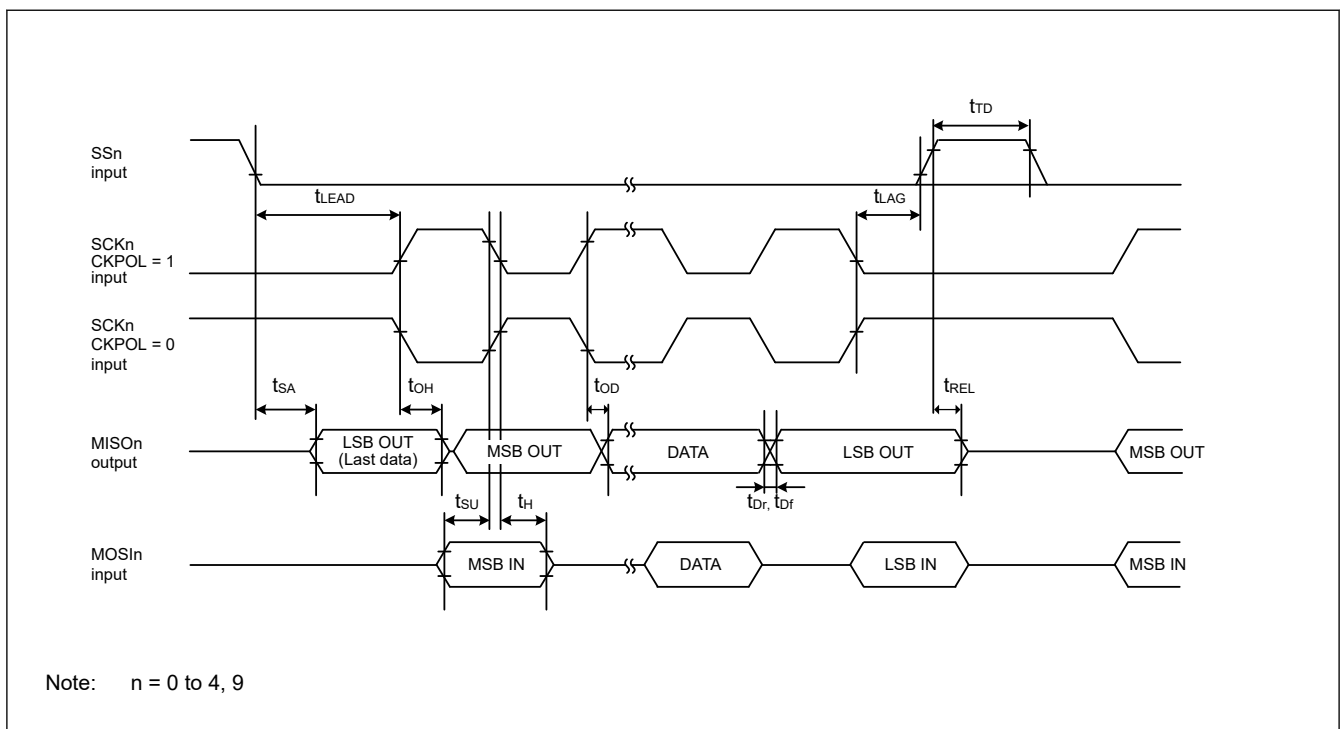


Figure 2.37 SCI simple SPI mode timing for slave when CKPH = 0



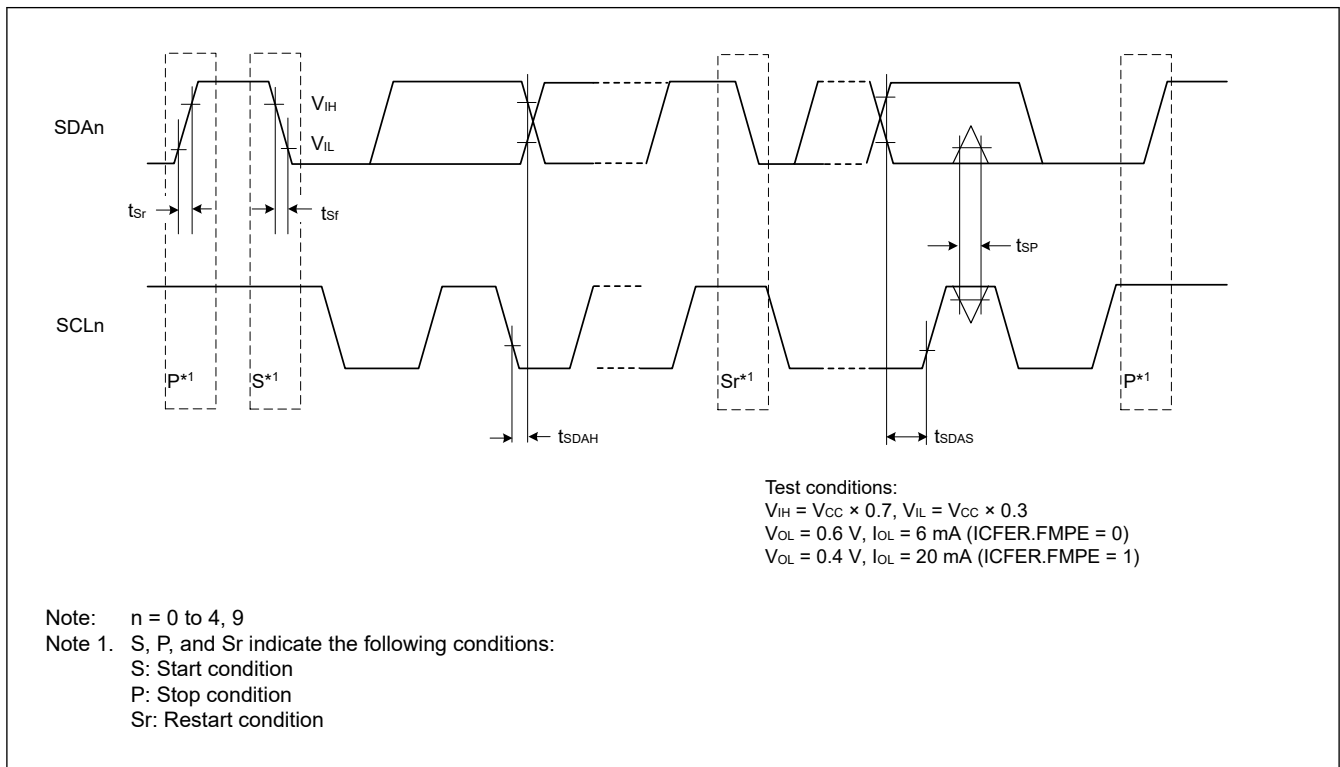
**Table 2.27 SCI timing (Simple IIC mode)**

Conditions: Middle drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter	Symbol	Min	Max	Unit	Note	
Simple IIC (Standard mode)	SCL, SDA input rise time	$t_{Sr}$	—	1000	ns	
	SCL, SDA input fall time	$t_{Sf}$	—	300	ns	
	SCL, SDA input spike pulse removal time	$t_{SP}$	0	$4 \times t_{Tcyc}$	ns	
	Data input setup time	$t_{SDAS}$	250	—	ns	
	Data input hold time	$t_{SDAH}$	0	—	ns	
	SCL, SDA capacitive load	$C_b^{*1}$	—	400	pF	
Simple IIC (Fast mode)	SCL, SDA input rise time	$t_{Sr}$	—	300	ns	
	SCL, SDA input fall time	$t_{Sf}$	—	300	ns	
	SCL, SDA input spike pulse removal time	$t_{SP}$	0	$4 \times t_{Tcyc}$	ns	
	Data input setup time	$t_{SDAS}$	100	—	ns	
	Data input hold time	$t_{SDAH}$	0	—	ns	
	SCL, SDA capacitive load	$C_b^{*1}$	—	400	pF	

Note:  $t_{Tcyc}$ : SCITCLK cycle.

Note 1.  $C_b$  indicates the total capacity of the bus line.



**Figure 2.38 SCI simple IIC mode timing**

## 2.3.10 SPI Timing

**Table 2.28 SPI timing (1 of 2)**

Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter		High Speed/ Default	Symbol	VCC = 3.0 to 3.6 V, C = 15 pF		VCC = 2.7 to 3.6 V, C = 30 pF		Unit	Note
				Min	Max	Min	Max		
RSPCK clock cycle	Master		$t_{SPCyc}$	2	4096	2	4096	$t_{Tcyc}$	
	Slave			2	—	2	—		
RSPCK clock high pulse width	Master		$t_{SPCKWH}$	$(t_{SPCyc} - t_{SPCKr} - t_{SPCKf})/2 - 3$	—	$(t_{SPCyc} - t_{SPCKr} - t_{SPCKf})/2 - 3$	—	ns	
	Slave			0.4	0.6	0.4	0.6		$t_{SPCyc}$
RSPCK clock low pulse width	Master		$t_{SPCKWL}$	$(t_{SPCyc} - t_{SPCKr} - t_{SPCKf})/2 - 3$	—	$(t_{SPCyc} - t_{SPCKr} - t_{SPCKf})/2 - 3$	—	ns	
	Slave			0.4	0.6	0.4	0.6		$t_{SPCyc}$
RSPCK clock rise and fall time	Output		$t_{SPCKr}$ , $t_{SPCKf}$	—	5	—	5	ns	
	Input			—	1	—	1		$\mu s$
Data input setup time	Master	High Speed*1	$t_{SU}$	0	—	—	—	ns	
		Default*2		—	—	1.3	—		ns
	Slave			2.5	—	2.7	—	ns	
Data input hold time	Master	High Speed*1	$t_H$	6.2	—	—	—	ns	
		Default*2		—	—	8	—		ns
	Slave			2.5	—	2.5	—	ns	
SSL setup time	Master		$t_{LEAD}$	1	8	1	8	$t_{SPCyc}$	
	Slave			6	—	6	—		$t_{Tcyc}$
SSL hold time	Master		$t_{LAG}$	1	8	1	8	$t_{SPCyc}$	
	Slave			6	—	6	—		$t_{Tcyc}$
TI SSP SS input setup time	Slave		$t_{TISS}$	2.5	—	2.8	—	ns	
TI SSP SS input hold time	Slave		$t_{TISH}$	2.5	—	2.5	—	ns	
TI SSP next-access time	Slave		$t_{TIND}$	$2 \times t_{Tcyc} + SLNDL \times t_{Tcyc}$	—	$2 \times t_{Tcyc} + SLNDL \times t_{Tcyc}$	—	ns	
TI SSP master SS output delay	Master		$t_{TISSOD}$	—	8.9	—	8.9	ns	

**Table 2.28 SPI timing (2 of 2)**

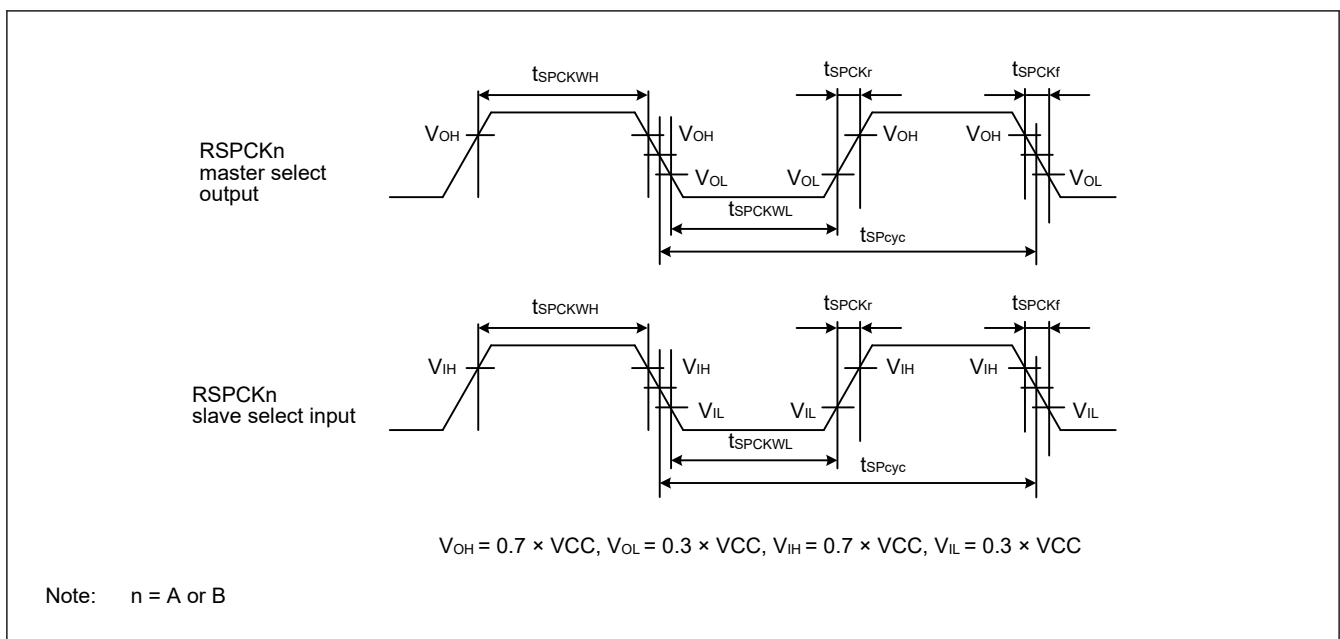
Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter	High Speed/Default	Symbol	VCC = 3.0 to 3.6 V, C = 15 pF		VCC = 2.7 to 3.6 V, C = 30 pF		Unit	Note
			Min	Max	Min	Max		
Data output delay time	Master	High Speed*1	—	4.6	—	—	ns	
		Default*2	—	—	—	7	ns	
	Slave	High Speed*1	—	14	—	—	ns	
		Default*2	—	—	—	21	ns	
Data output hold time	Master	$t_{OH}$	0	—	0	—	ns	
	Slave		0	—	0	—	ns	
Successive transmission delay time	Master	$t_{TD}$	$t_{SPcyc} + 2 \times t_{Tcyc}$	$8 \times t_{SPcyc} + 2 \times t_{Pcyc}$	$t_{SPcyc} + 2 \times t_{Tcyc}$	$8 \times t_{SPcyc} + 2 \times t_{Pcyc}$	ns	
	Slave		$t_{Tcyc}$	—	$t_{Tcyc}$	—	ns	
MOSI and MISO rise and fall time	Output	$t_{Dr}$	—	5	—	5	ns	
	Input	$t_{Df}$	—	1	—	1	$\mu s$	
SSL rise and fall time	Output	$t_{SSLr}$	—	5	—	5	ns	
	Input	$t_{SSLf}$	—	1	—	1	$\mu s$	
Slave access time	Slave	$t_{SA}$	—	20	—	20	ns	
Slave output release time	Slave	$t_{REL}$	—	20	—	20	ns	

Note:  $t_{Tcyc}$ : PCLKA or SCISPICLK cycle.

Note 1. Must use pins that have a letter appended to their name, for instance \_A, \_B, \_C, to indicate group membership. SPIA is instance \_B, SPIB is instance \_A.

Note 2. All pins of group membership can be used.



**Figure 2.39 SPI clock timing**

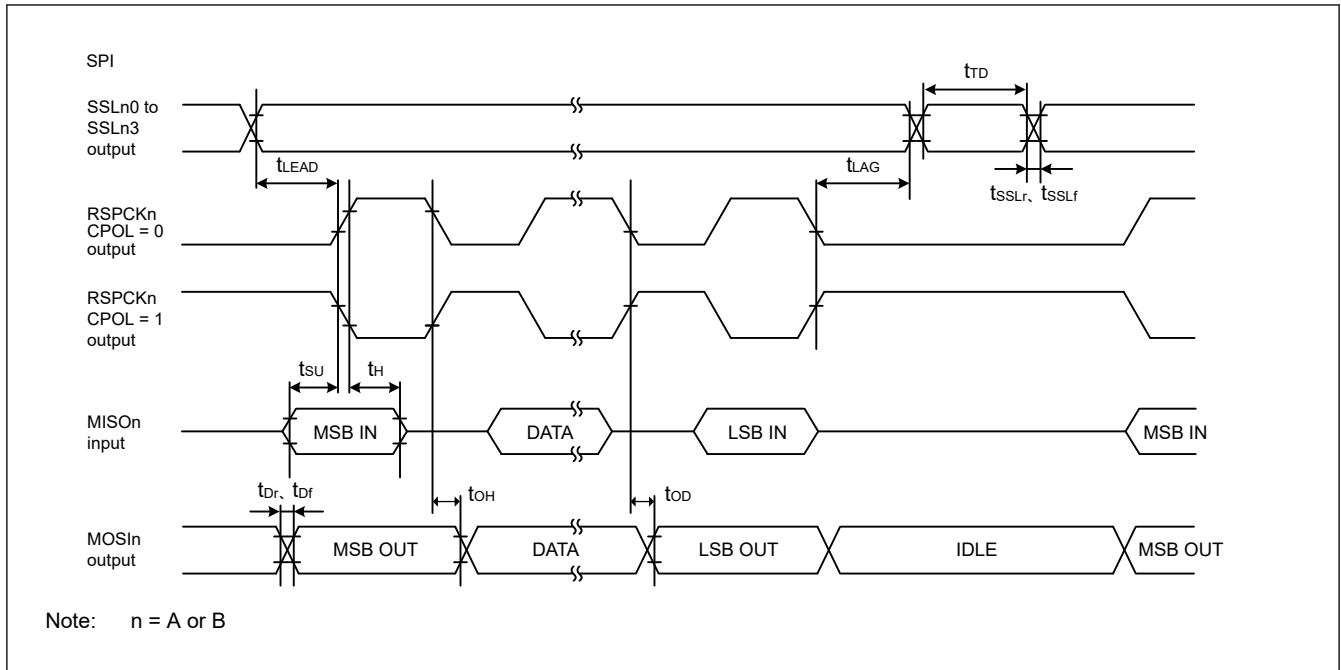


Figure 2.40 SPI timing for Motorola SPI master when CPHA = 0

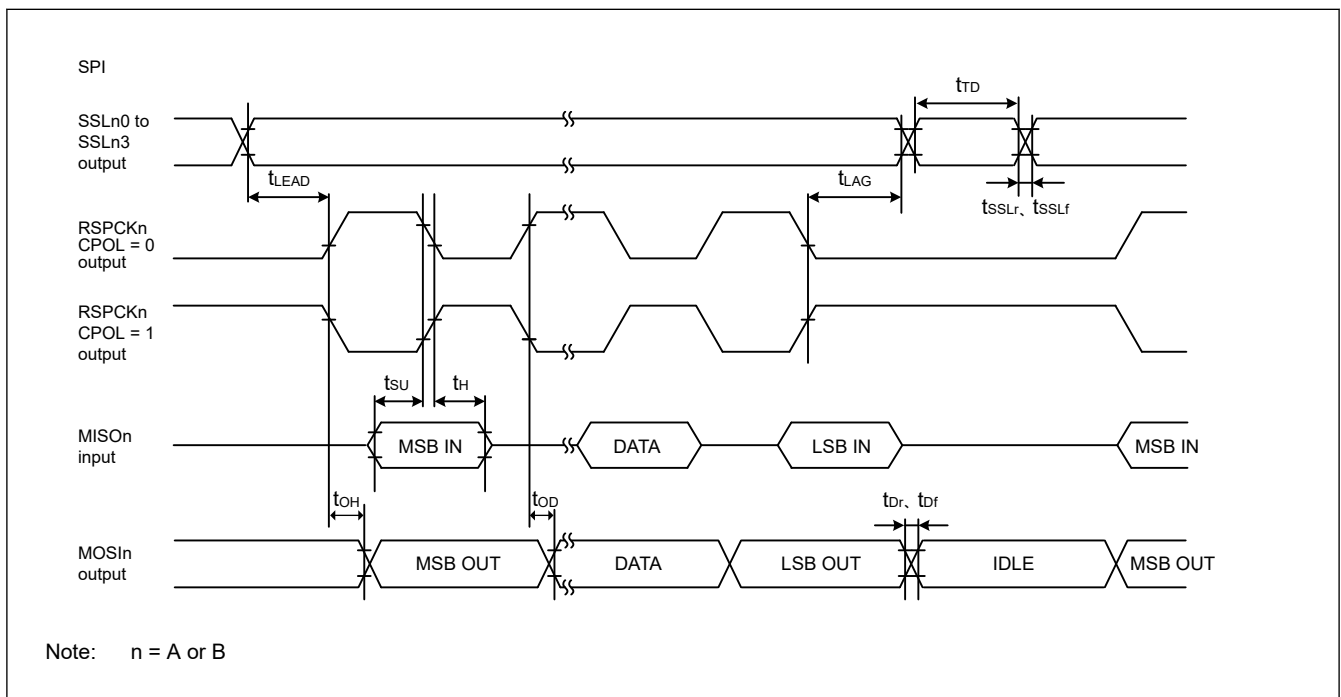


Figure 2.41 SPI timing for Motorola SPI master when CPHA = 1

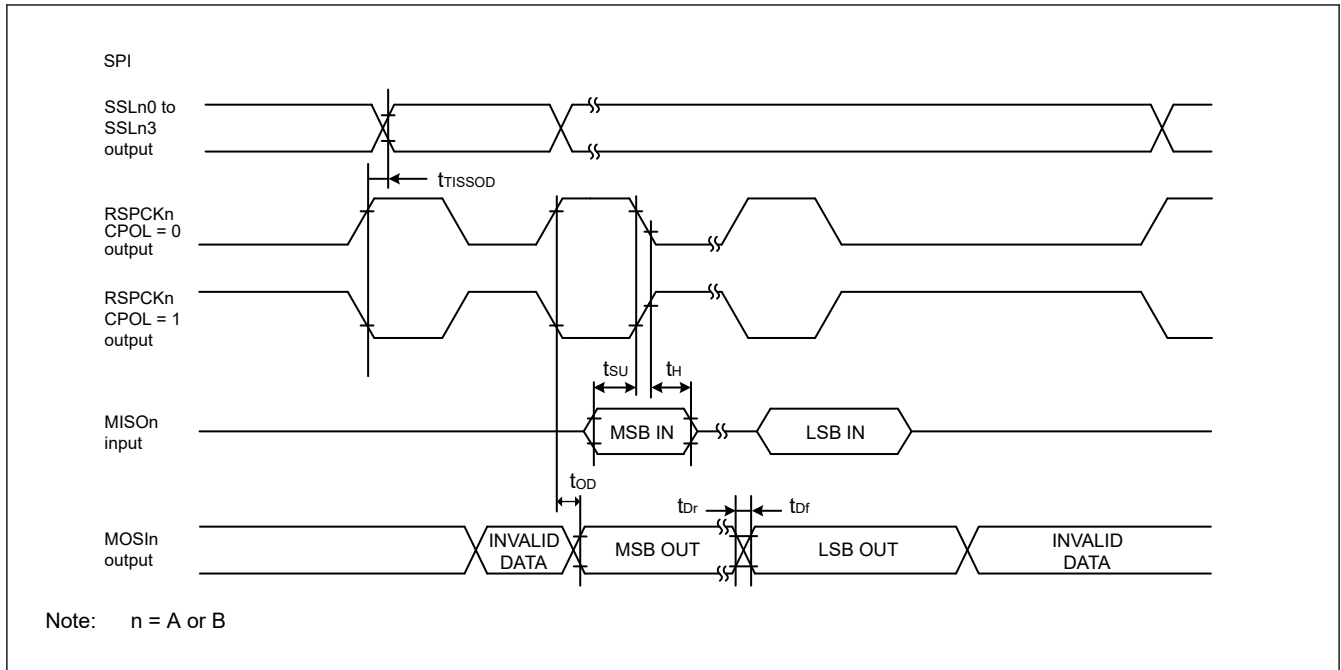


Figure 2.42 SPI timing for TI SSP master

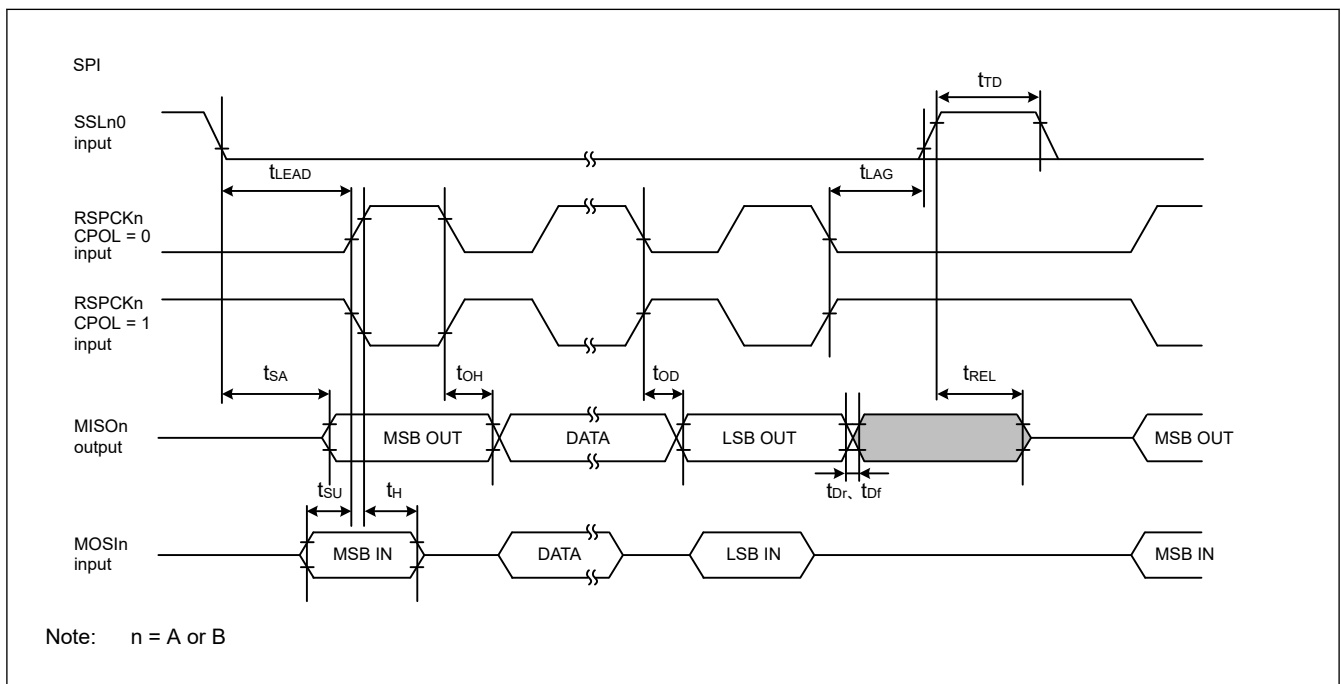


Figure 2.43 SPI timing for Motorola SPI slave when CPHA = 0

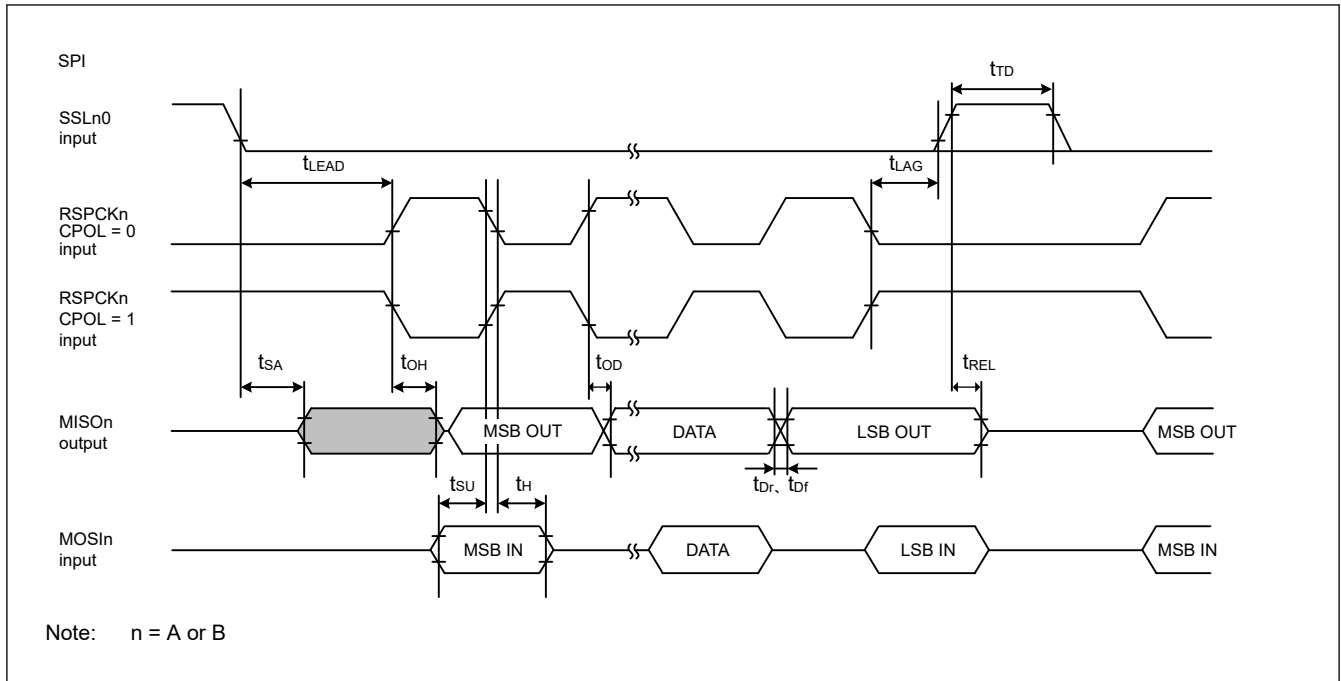


Figure 2.44 SPI timing for Motorola SPI slave when CPHA = 1

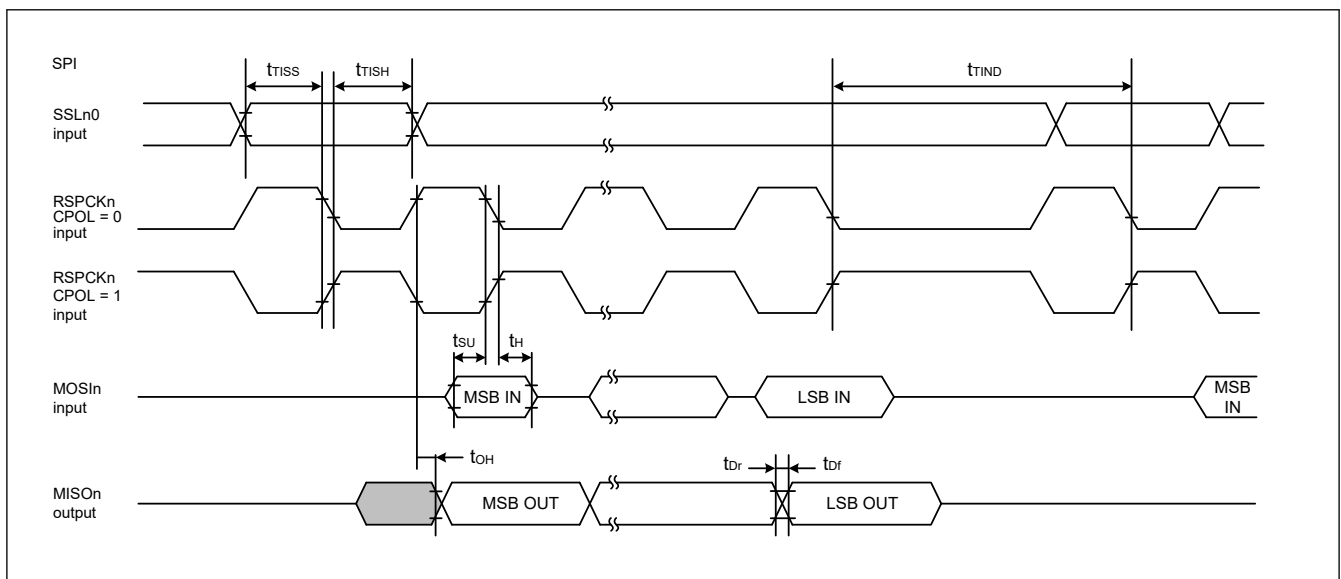


Figure 2.45 SPI timing for TI SSP slave when transmit with delay between frames

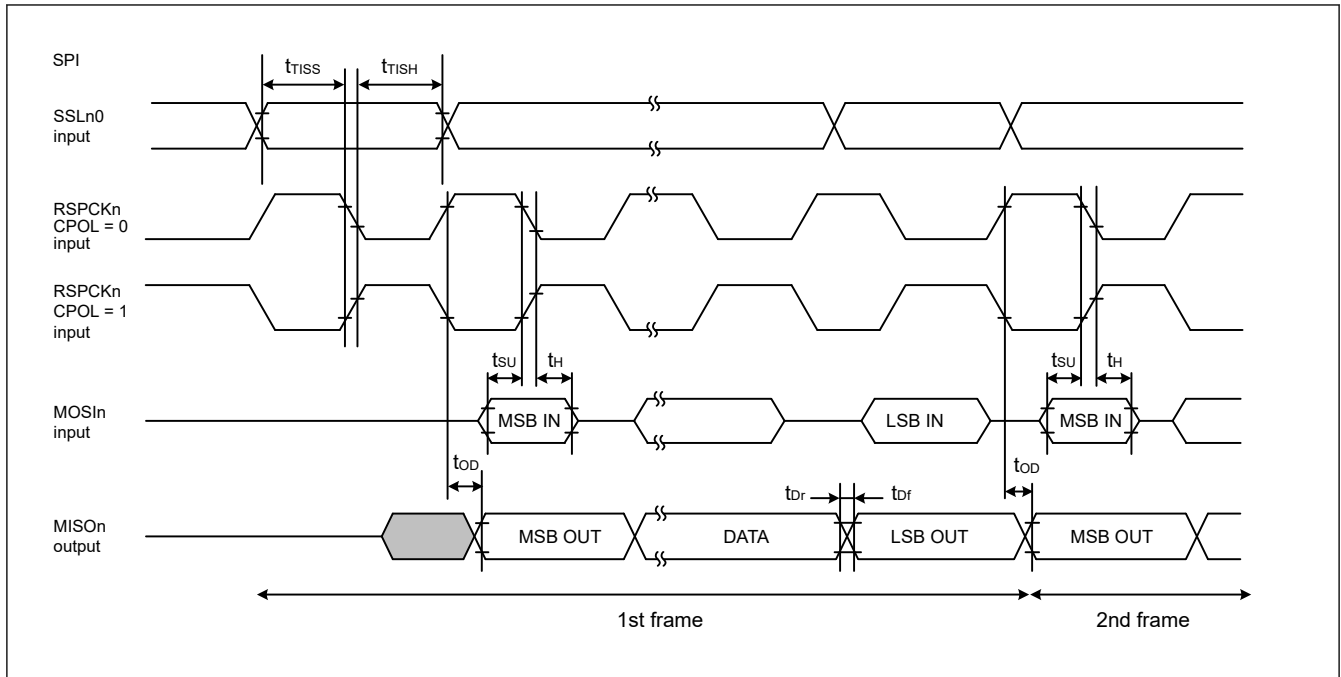


Figure 2.46 SPI timing for TI SSP slave when transmit with no delay between frames

### 2.3.11 IIC Timing

Table 2.29 IIC timing (1)-1

- (1) Conditions: Middle drive output is selected in the Port Drive Capability bit in the PmnPFS register for the following pins: SDA0\_B, SCL0\_B, SDA1\_B, SCL1\_B, SCL0\_C, SDA0\_C, SCL0\_D, SDA0\_D, SCL0\_E, SDA0\_E, SCL0\_F, SDA0\_F, SCL1\_C, SDA1\_C, SCL1\_D, SDA1\_D, SCL1\_E, SDA1\_E.
- (2) The following pins do not require setting: SCL0\_A, SDA0\_A, SCL1\_A, SDA1\_A.
- (3) Use pins that have a letter appended to their names, for instance \_A or \_B or \_C or \_D or \_E or \_F, to indicate group membership. For the IIC interface, the AC portion of the electrical characteristics is measured for each group.

Parameter	Symbol	Min	Max	Unit	Test conditions	
IIC (Standard mode, SMBus) BFCTL.FMPE = 0	SCL input cycle time	$t_{SCL}$	$10 (18) \times t_{IICcyc} + 1300$	—	ns	Figure 2.47
	SCL input high pulse width	$t_{SCLH}$	$5 (9) \times t_{IICcyc}$	—	ns	
	SCL input low pulse width	$t_{SCLL}$	$5 (9) \times t_{IICcyc}$	—	ns	
	SCL, SDA rise time	$t_{Sr}$	—	1000	ns	
	SCL, SDA fall time	$t_{Sf}$	—	300	ns	
	SCL, SDA input spike pulse removal time	$t_{SP}$	0	$1 (4) \times t_{IICcyc}$	ns	
	SDA input bus free time	$t_{BUF}$	$5 (9) \times t_{IICcyc} + 300$	—	ns	
	START condition input hold time	$t_{STAH}$	$t_{IICcyc} + 300$	—	ns	
	Repeated START condition input setup time	$t_{STAS}$	1000	—	ns	
	STOP condition input setup time	$t_{STOS}$	1000	—	ns	
	Data input setup time	$t_{SDAS}$	$t_{IICcyc} + 50$	—	ns	
	Data input hold time	$t_{SDAH}$	0	—	ns	
	SCL, SDA capacitive load	$C_b^{*1}$	—	400	pF	

Note:  $t_{IICcyc}$ : IIC internal reference clock (IICφ) cycle.

Note: Values in parentheses apply when INCTL.DNFS[3:0] is set to 0011b while the digital filter is enabled with INCTL.DNFE set to 1.

Note 1.  $C_b$  indicates the total capacity of the bus line.

**Table 2.30 IIC timing (1)-2**

(1) Conditions: Middle drive output is selected in the Port Drive Capability bit in the PmnPFS register for the following pins: SDA0\_B, SCL0\_B, SDA1\_B, SCL1\_B, SCL0\_C, SDA0\_C, SCL0\_D, SDA0\_D, SCL0\_E, SDA0\_E, SCL0\_F, SDA0\_F, SCL1\_C, SDA1\_C, SCL1\_D, SDA1\_D, SCL1\_E, SDA1\_E.

(2) The following pins do not require setting: SCL0\_A, SDA0\_A, SCL1\_A, SDA1\_A.

(3) Use pins that have a letter appended to their names, for instance \_A or \_B or \_C or \_D or \_E or \_F, to indicate group membership. For the IIC interface, the AC portion of the electrical characteristics is measured for each group.

Parameter	Symbol	Min	Max	Unit	Test conditions	
IIC (Fast-mode)	SCL input cycle time	$t_{SCL}$	$10 (18) \times t_{IICcyc} + 600$	—	ns	Figure 2.47
	SCL input high pulse width	$t_{SCLH}$	$5 (9) \times t_{IICcyc}$	—	ns	
	SCL input low pulse width	$t_{SCLL}$	$5 (9) \times t_{IICcyc}$	—	ns	
	SCL, SDA rise time	$t_{Sr}$	$20 \times (\text{external pullup voltage} / 5.5V)^{*1}$	300	ns	
	SCL, SDA fall time	$t_{Sf}$	$20 \times (\text{external pullup voltage} / 5.5V)^{*1}$	300	ns	
	SCL, SDA input spike pulse removal time	$t_{SP}$	0	$1 (4) \times t_{IICcyc}$	ns	
	SDA input bus free time	$t_{BUF}$	$5 (9) \times t_{IICcyc} + 300$	—	ns	
	START condition input hold time	$t_{STAH}$	$t_{IICcyc} + 300$	—	ns	
	Repeated START condition input setup time	$t_{STAS}$	300	—	ns	
	STOP condition input setup time	$t_{STOS}$	300	—	ns	
	Data input setup time	$t_{SDAS}$	$t_{IICcyc} + 50$	—	ns	
	Data input hold time	$t_{SDAH}$	0	—	ns	
	SCL, SDA capacitive load	$C_b^{*2}$	—	400	pF	

Note:  $t_{IICcyc}$ : IIC internal reference clock (IIC $\phi$ ) cycle.

Note: Values in parentheses apply when INCTL.DNFS[3:0] is set to 0011b while the digital filter is enabled with INCTL.DNFE set to 1.

Note: Must use pins that have a letter appended to their name, for instance \_A, \_B, to indicate group membership. For the IIC interface, the AC portion of the electrical characteristics is measured for each group.

Note 1. Only supported for SCL0\_A, SDA0\_A, SCL1\_A, and SDA1\_A. Other ports are depend on DC characteristics.

Note 2.  $C_b$  indicates the total capacity of the bus line.



**Table 2.31 IIC timing (1)-3**

Setting of the SCL0\_A, SDA0\_A pins are not required with the Port Drive Capability bit in the PmnPFS register.

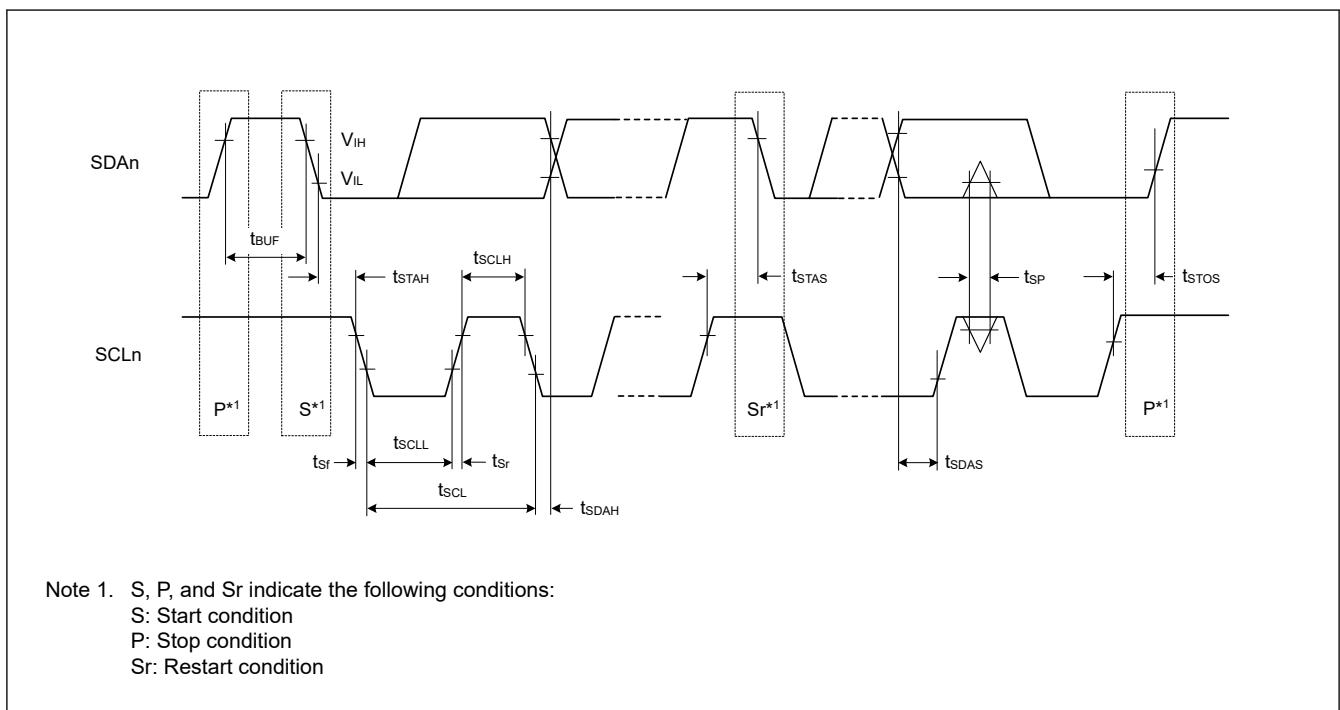
Parameter	Symbol	Min	Max	Unit	Test conditions	
IIC (Fast-mode+) BFCTL.FMPE = 1	SCL input cycle time	$t_{SCL}$	$10 (18) \times t_{IICcyc} + 240$	—	ns	Figure 2.47
	SCL input high pulse width	$t_{SCLH}$	$5 (9) \times t_{IICcyc}$	—	ns	
	SCL input low pulse width	$t_{SCLL}$	$5 (9) \times t_{IICcyc}$	—	ns	
	SCL, SDA rise time	$t_{Sr}$	—	120	ns	
	SCL, SDA fall time	$t_{Sf}$	—	120	ns	
	SCL, SDA input spike pulse removal time	$t_{SP}$	0	$1 (4) \times t_{IICcyc}$	ns	
	SDA input bus free time	$t_{BUF}$	$5 (9) \times t_{IICcyc} + 120$	—	ns	
	START condition input hold time	$t_{STAH}$	$t_{IICcyc} + 120$	—	ns	
	Repeated START condition input setup time	$t_{STAS}$	120	—	ns	
	STOP condition input setup time	$t_{STOS}$	120	—	ns	
	Data input setup time	$t_{SDAS}$	$t_{IICcyc} + 30$	—	ns	
	Data input hold time	$t_{SDAH}$	0	—	ns	
	SCL, SDA capacitive load	$C_b^{*1}$	—	550	pF	

Note:  $t_{IICcyc}$ : IIC internal reference clock (IIC $\phi$ ) cycle.

Note: Values in parentheses apply when INCTL.DNFS[3:0] is set to 0011b while the digital filter is enabled with INCTL.DNFE set to 1.

Note: Targets are SCL0\_A and SDA0\_A.

Note 1.  $C_b$  indicates the total capacity of the bus line.



**Figure 2.47 I<sup>2</sup>C bus interface input/output timing**

**Table 2.32 IIC timing (2)**

Setting of the SCL0\_A, SDA0\_A pins are not required with the Port Drive Capability bit in the PmnPFS register.

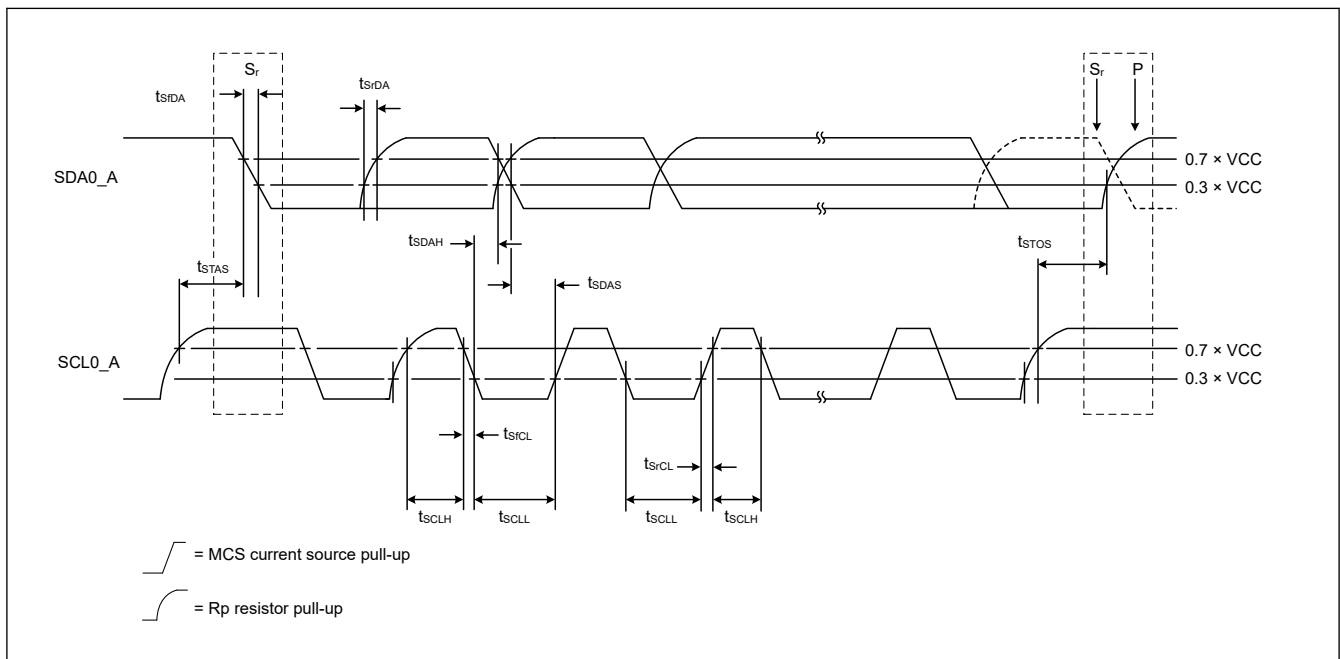
Parameter	Symbol	Min	Max	Unit	Test conditions		
IIC (Hs-mode) BFCTL.HSME = 1	SCL input cycle time	$t_{SCL}$	$10 (12) \times t_{IICcyc} + 80$	—	ns	Figure 2.48	
	SCL input high pulse width	$t_{SCLH}$	$5 (6) \times t_{IICcyc}$	—	ns		
	SCL input low pulse width	$t_{SCLL}$	$5 (6) \times t_{IICcyc}$	—	ns		
	SCL rise time	$C_b = 400pF$ $C_b = 100pF$	$t_{SrCL}$	—	80		ns
				—	40		ns
	SDA rise time	$C_b = 400pF$ $C_b = 100pF$	$t_{SrDA}$	—	160		ns
				—	80		ns
	SCL fall time	$C_b = 400pF$ $C_b = 100pF$	$t_{SfCL}$	—	80		ns
				—	40		ns
	SDA fall time	$C_b = 400pF$ $C_b = 100pF$	$t_{SfDA}$	—	160		ns
				—	80		ns
	SCL, SDA input spike pulse removal time	$t_{SP}$	0	$1 (1) \times t_{IICcyc}$	ns		
	Repeated START condition input setup time	$t_{STAS}$	40	—	ns		
	STOP condition input setup time	$t_{STOS}$	40	—	ns		
	Data input setup time	$t_{SDAS}$	10	—	ns		
Data input hold time	$C_b = 400pF$ $C_b = 100pF$	$t_{SDAH}$	0	150	ns		
			0	70	ns		
SCL, SDA capacitive load	$C_b^{*1}$	—	400	pF			

Note:  $t_{IICcyc}$ : IIC internal reference clock (IICφ) cycle.

Note: Values in parentheses apply when INCTL.DNFS[3:0] is set to 0011b while the digital filter is enabled with INCTL.DNFE set to 1.

Note: Targets are SCL0\_A and SDA0\_A.

Note 1.  $C_b$  indicates the total capacity of the bus line.



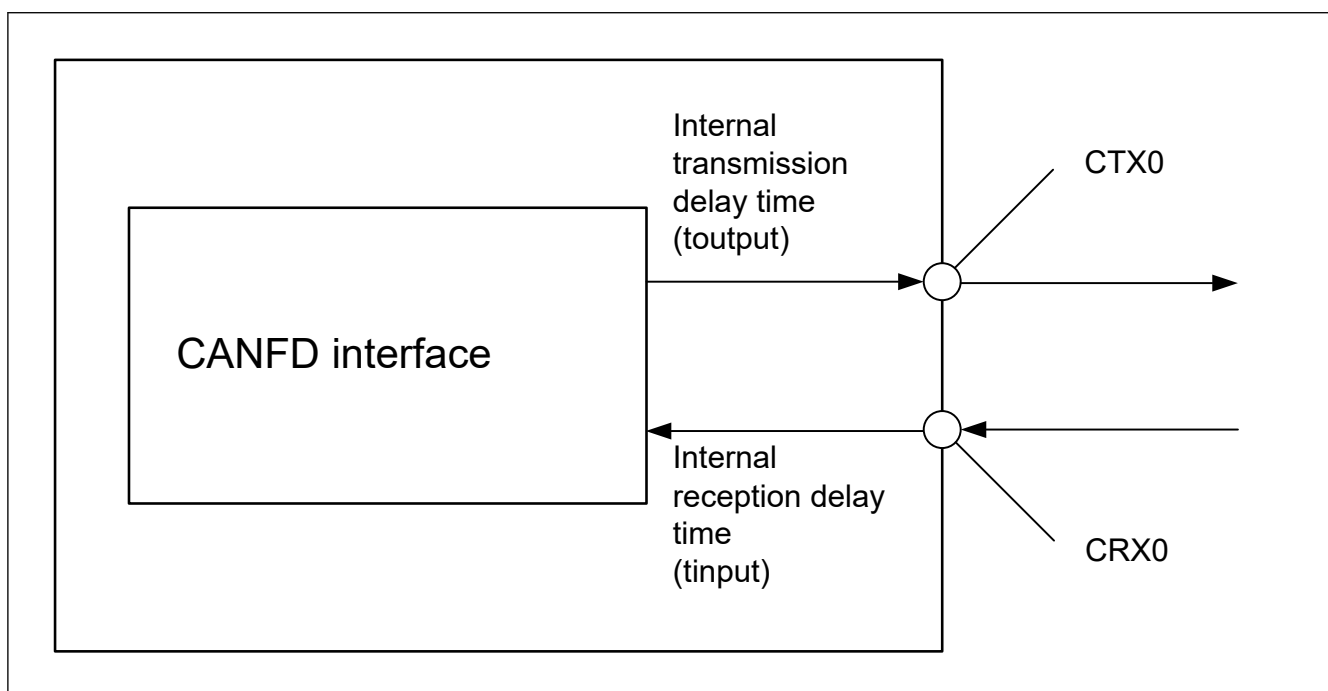
**Figure 2.48 I<sup>2</sup>C bus interface input/output timing (Hs-mode)**

### 2.3.12 CANFD Timing

**Table 2.33 CANFD interface timing**

Parameter	Symbol	CAN		CAN-FD		Unit	Test conditions
		Min	Max	Min	Max		
Internal delay time	$t_{node}$	—	100	—	75	ns	Figure 2.49
Transmission rate		—	1	—	5	Mbps	

Note:  $t_{node} = t_{output} + t_{input}$



**Figure 2.49 CANFD interface condition**

### 2.4 ADC Characteristics

**Table 2.34 A/D conversion characteristics (Common) (1 of 2)**

Parameter	Min	Typ	Max	Unit	Test conditions	
A/D conversion clock frequency(ADCLK)	25	50	60	MHz		
Quantization error	—	±0.5	—	LSB		
Successive approximation time	100	—	140	ns		
A/D sampling time	During calibration		400	—	—	ns
	In self-diagnosis mode		$1 \times t_{ADcyc} + 40$	—	—	ns
	During A/D conversion	Channel-dedicated sample-and-hold circuits in use (AN000 to AN005) (AN006 to AN011)	$1 \times t_{ADcyc} + 160$	—	—	ns
		High-speed channels (AN000 to AN005) (AN006 to AN011) (AN018 to AN019)	$1 \times t_{ADcyc} + 40$	—	—	ns
		High-precision channels (AN012 to AN017)	180	—	—	ns
Normal-precision channels (AN020 to AN028)		400	—	—	ns	

**Table 2.34 A/D conversion characteristics (Common) (2 of 2)**

Parameter		Min	Typ	Max	Unit	Test conditions
Channel-dedicated sample-and-hold circuits	Sampling time during calibration	400	—	—	ns	
	Sampling time during A/D conversion	400	—	—	ns	
	Hold mode switching time	40	—	—	ns	
	Hold time	—	—	5	μs	
Operation stabilization time	A/D start-up time	2.0	—	—	us	
	Channel-dedicated sample-and-hold circuits start-up time	2.0	—	—	us	
	A/D shut-down time	1.0	—	—	us	
Analog input voltage range		VREFL0	—	VREFH0	V	

Note:  $t_{ADcyc}$  : ADCLK cycle**Table 2.35 A/D conversion characteristics (1 of 2)**

Parameter			Min	Typ	Max	Unit	Test conditions
Resolution			—	—	12	bit	
Channel-dedicated sample-and-hold circuits in use (AN000 to AN005) (AN006 to AN011)	Conversion time* <sup>1</sup> (operation at ADCLK = 50 MHz)	Permissible signal source impedance Max. = 50Ω	0.70	—	—	μs	<ul style="list-style-type: none"> <li>Sampling time of channel-dedicated sample-and-hold circuits: 20 ADCLK</li> <li>Hold mode switching time of channel-dedicated sample-and-hold circuits: 2 ADCLK</li> <li>Sampling time: 8 ADCLK</li> <li>Successive approximation time: 5 ADCLK</li> </ul>
	Offset error		—	±0.5	±1.0	LSB	
	Full-scale error		—	±1.0	±1.5	LSB	
	Absolute accuracy		—	±5.0	±7.0	LSB	
	DNL pseudo-differential nonlinearity error		—	-1 to +1.5	-1 to +2.5	LSB	
	INL integral nonlinearity error		—	±2.0	±3.0	LSB	
High-speed channels (AN000 to AN005) (AN006 to AN011) (AN018 to AN019)* <sup>2</sup>	Conversion time* <sup>1</sup> (operation at ADCLK = 50 MHz)	Permissible signal source impedance Max. = 50Ω	0.16	—	—	μs	<ul style="list-style-type: none"> <li>Sampling time: 3 ADCLK</li> <li>Successive approximation time: 5 ADCLK</li> </ul>
	Offset error		—	±1.0	±3.0	LSB	
	Full-scale error		—	±1.5	±2.5	LSB	
	Absolute accuracy		—	±5.5	±7.0	LSB	
	DNL pseudo-differential nonlinearity error		—	-1 to +1.5	-1 to +2.5	LSB	
	INL integral nonlinearity error		—	±2.0	±3.0	LSB	
High-precision channels (AN012 to AN017)	Conversion time* <sup>1</sup> (operation at ADCLK = 50 MHz)	Permissible signal source impedance Max. = 50Ω	0.28	—	—	μs	<ul style="list-style-type: none"> <li>Sampling time: 9 ADCLK</li> <li>Successive approximation time: 5 ADCLK</li> </ul>
	Offset error		—	±1.0	±1.5	LSB	
	Full-scale error		—	±1.0	±2.5	LSB	
	Absolute accuracy		—	±4.0	±7.0	LSB	
	DNL pseudo-differential nonlinearity error		—	-1 to +1.5	-1 to +2.5	LSB	
	INL integral nonlinearity error		—	±2.0	±3.0	LSB	

**Table 2.35 A/D conversion characteristics (2 of 2)**

Parameter			Min	Typ	Max	Unit	Test conditions
Normal-precision channels (AN020 to AN028)	Conversion time*1 (operation at ADCLK = 50 MHz)	Permissible signal source impedance Max. = 50Ω	0.50	—	—	μs	<ul style="list-style-type: none"> <li>Sampling time: 20 ADCLK</li> <li>Successive approximation time: 5 ADCLK</li> </ul>
	Offset error		—	±1.0	±2.5	LSB	
	Full-scale error		—	±1.5	±2.5	LSB	
	Absolute accuracy		—	±5.5	±8.0	LSB	
	DNL pseudo-differential nonlinearity error		—	-1 to +1.5	-1 to +2.5	LSB	
	INL integral nonlinearity error		—	±2.0	±4.0	LSB	

Note 1. Channel-dedicated sample-and-hold circuits in use; The conversion time is the sum of the sampling time of channel-dedicated sample-and-hold circuits, the hold mode switching time, the sampling time and the successive approximation time. Each of the above state is indicated for the test conditions.

Channel-dedicated sample-and-hold circuits not in use; The conversion time is the sum of the sampling time and the successive approximation time. Each of the above state is indicated for the test conditions.

Note 2. These channels cannot be used with Channel-dedicated sample-and-hold circuits.

**Table 2.36 A/D internal reference voltage characteristics**

Parameter	Min	Typ	Max	Unit	Test conditions
A/D internal reference voltage	1.13	1.18	1.23	V	
Sampling time	4.15	—	—	μs	

**Table 2.37 A/D with D/A conversion characteristics**

Parameter	Min	Typ	Max	Unit	Test conditions
Sampling time	1	—	—	μs	

## 2.5 DAC12 Characteristics

**Table 2.38 D/A conversion characteristics**

Parameter	Min	Typ	Max	Unit	Test conditions
Resolution	—	—	12	Bits	—
Without output amplifier					
Absolute accuracy	—	—	±24	LSB	Resistive load 2 MΩ
INL	—	±2.0	±8.0	LSB	Resistive load 2 MΩ
DNL	—	±1.0	±2.0	LSB	—
Output impedance	—	8.5	—	kΩ	—
Conversion time	—	—	3	μs	Resistive load 2 MΩ, Capacitive load 20 pF
Output voltage range	0	—	AVCC0	V	—
With output amplifier					
INL	—	±2.0	±4.0	LSB	—
DNL	—	±1.0	±2.0	LSB	—
Conversion time	—	—	4.0	μs	—
Resistive load	5	—	—	kΩ	—
Capacitive load	—	—	50	pF	—
Output voltage range	0.2	—	AVCC0 – 0.2	V	—

## 2.6 TSN Characteristics

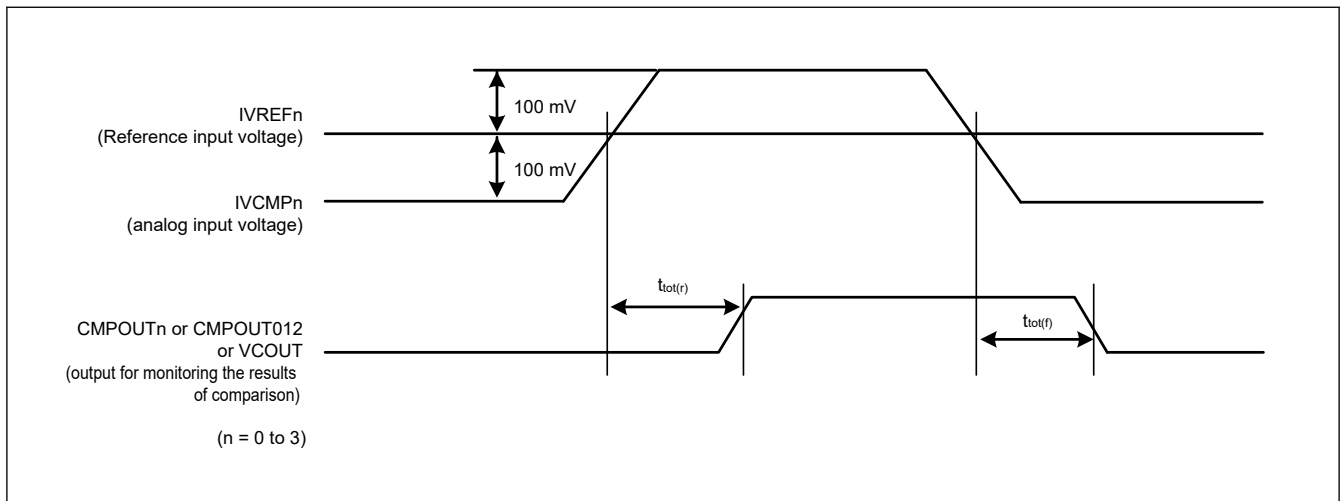
**Table 2.39 TSN characteristics**

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Relative accuracy	—	—	± 1.0	—	°C	—
Temperature slope	—	—	4.0	—	mV/°C	—
Output voltage (at 25 °C)	—	—	1.24	—	V	—
Temperature sensor start time	t <sub>START</sub>	—	—	30	μs	—
Sampling time	—	4.15	—	—	μs	—

## 2.7 ACMPHS Characteristics

**Table 2.40 ACMPHS characteristics**

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Input offset voltage	V <sub>IO</sub>	—	—	40	mV	
Reference voltage range	V <sub>REF</sub>	0	—	AVCC0	V	
Input voltage range	V <sub>I</sub>	0	—	AVCC0	V	
Output delay	t <sub>tot(r)</sub>	—	—	200	ns	VOD = 100 mV CMPCTL.CDFS = 0
	t <sub>tot(f)</sub>	—	—	200	ns	
Waiting time for stabilization following switching of the input	t <sub>cwait</sub>	300	—	—	ns	
Operation stabilization time	t <sub>cmp</sub>	—	—	1	us	



**Figure 2.50 Comparator Response Time**

## 2.8 PGA Characteristics

**Table 2.41 PGA characteristics in single mode (1 of 3)**

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Offset error	V <sub>off</sub>	-8	—	8	mV	

Table 2.41 PGA characteristics in single mode (2 of 3)

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
PGAVSS input voltage range	PGAVSS	0	—	0	V	
	AIN0 (G = 2.000)	$0.05 \times AVCC0$	—	$0.45 \times AVCC0$	V	
	AIN1 (G = 2.500)	$0.047 \times AVCC0$	—	$0.36 \times AVCC0$	V	
	AIN2 (G = 2.667)	$0.046 \times AVCC0$	—	$0.337 \times AVCC0$	V	
	AIN3 (G = 2.857)	$0.046 \times AVCC0$	—	$0.32 \times AVCC0$	V	
	AIN4 (G = 3.077)	$0.045 \times AVCC0$	—	$0.292 \times AVCC0$	V	
	AIN5 (G = 3.333)	$0.044 \times AVCC0$	—	$0.265 \times AVCC0$	V	
	AIN6 (G = 3.636)	$0.042 \times AVCC0$	—	$0.247 \times AVCC0$	V	
	AIN7 (G = 4.000)	$0.04 \times AVCC0$	—	$0.212 \times AVCC0$	V	
	AIN8 (G = 4.444)	$0.036 \times AVCC0$	—	$0.191 \times AVCC0$	V	
	AIN9 (G = 5.000)	$0.033 \times AVCC0$	—	$0.17 \times AVCC0$	V	
	AIN10 (G = 5.714)	$0.031 \times AVCC0$	—	$0.148 \times AVCC0$	V	
	AIN11 (G = 6.667)	$0.029 \times AVCC0$	—	$0.127 \times AVCC0$	V	
	AIN12 (G = 8.000)	$0.027 \times AVCC0$	—	$0.09 \times AVCC0$	V	
	AIN13 (G = 10.000)	$0.025 \times AVCC0$	—	$0.08 \times AVCC0$	V	
AIN14 (G = 13.333)	$0.023 \times AVCC0$	—	$0.06 \times AVCC0$	V		
Output voltage range <sup>*1</sup>	PGAOUT0 (G = 2.000)	$0.100 \times AVCC0$	—	$0.900 \times AVCC0$	V	
	PGAOUT1 (G = 2.500)	$0.118 \times AVCC0$	—	$0.900 \times AVCC0$	V	
	PGAOUT2 (G = 2.667)	$0.123 \times AVCC0$	—	$0.899 \times AVCC0$	V	
	PGAOUT3 (G = 2.857)	$0.131 \times AVCC0$	—	$0.914 \times AVCC0$	V	
	PGAOUT4 (G = 3.077)	$0.138 \times AVCC0$	—	$0.898 \times AVCC0$	V	
	PGAOUT5 (G = 3.333)	$0.147 \times AVCC0$	—	$0.883 \times AVCC0$	V	
	PGAOUT6 (G = 3.636)	$0.153 \times AVCC0$	—	$0.898 \times AVCC0$	V	
	PGAOUT7 (G = 4.000)	$0.160 \times AVCC0$	—	$0.848 \times AVCC0$	V	
	PGAOUT8 (G = 4.444)	$0.160 \times AVCC0$	—	$0.849 \times AVCC0$	V	
	PGAOUT9 (G = 5.000)	$0.165 \times AVCC0$	—	$0.850 \times AVCC0$	V	
	PGAOUT10 (G = 5.714)	$0.177 \times AVCC0$	—	$0.846 \times AVCC0$	V	
	PGAOUT11 (G = 6.667)	$0.193 \times AVCC0$	—	$0.847 \times AVCC0$	V	
	PGAOUT12 (G = 8.000)	$0.216 \times AVCC0$	—	$0.720 \times AVCC0$	V	
	PGAOUT13 (G = 10.000)	$0.250 \times AVCC0$	—	$0.800 \times AVCC0$	V	
	PGAOUT14 (G = 13.333)	$0.307 \times AVCC0$	—	$0.800 \times AVCC0$	V	

**Table 2.41 PGA characteristics in single mode (3 of 3)**

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Gain error	Gerr0 (G = 2.000)	-1.0	—	1.0	%	
	Gerr1 (G = 2.500)	-1.0	—	1.0	%	
	Gerr2 (G = 2.667)	-1.0	—	1.0	%	
	Gerr3 (G = 2.857)	-1.0	—	1.0	%	
	Gerr4 (G = 3.007)	-1.0	—	1.0	%	
	Gerr5 (G = 3.333)	-1.5	—	1.5	%	
	Gerr6 (G = 3.636)	-1.5	—	1.5	%	
	Gerr7 (G = 4.000)	-1.5	—	1.5	%	
	Gerr8 (G = 4.444)	-2.0	—	2.0	%	
	Gerr9 (G = 5.000)	-2.0	—	2.0	%	
	Gerr10 (G = 5.714)	-2.0	—	2.0	%	
	Gerr11 (G = 6.667)	-2.0	—	2.0	%	
	Gerr12 (G = 8.000)	-2.0	—	2.0	%	
	Gerr13 (G = 10.000)	-2.0	—	2.0	%	
Gerr14 (G = 13.333)	-2.0	—	2.0	%		
Operation stabilization time	t <sub>start</sub>	—	—	5	μs	

Note 1. Calculate with the following formula. (n = 0 to 14)

$$\text{PGAOUT}_n = \text{AIN}_n \times G$$

Actual output range includes gain error.

$$\text{PGAOUT}_n = (\text{AIN}_n \times G) \times (\text{Gerr} + 100\%)$$

**Table 2.42 PGA characteristics in differential mode**

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions	
Offset error	V <sub>off</sub>	-20	—	20	mV		
PGAVSS input voltage range	PGAVSS	-0.5	—	0.3	V		
Differential input voltage range	G = 1.500	A <sub>IN</sub> -PGAVSS	-0.5	—	0.5	V	
	G = 2.333		-0.4	—	0.4	V	
	G = 4.000		-0.2	—	0.2	V	
	G = 5.667		-0.15	—	0.15	V	
Output voltage range*1	G = 1.500	V <sub>OR</sub>	0.600	—	2.550	V	
	G = 2.333		0.417	—	2.733	V	
	G = 4.000		0.550	—	2.600	V	
	G = 5.667		0.500	—	2.650	V	
Gain error	G = 1.500	Gerr	-1.0	—	1.0	%	
	G = 2.333		-1.0	—	1.0	%	
	G = 4.000		-1.0	—	1.0	%	
	G = 5.667		-1.0	—	1.0	%	
Operation stabilization time	t <sub>start</sub>	—	—	5	μs		

Note 1. Calculate with the following formula.

$$V_{OR} = (\text{A}_{IN}\text{-PGAVSS}) \times G + (0.5 \times \text{AVCC0})$$

Actual output range includes gain error.

$$V_{OR} = (\text{A}_{IN}\text{-PGAVSS}) \times G \times (\text{Gerr} + 100\%) + (0.5 \times \text{AVCC0})$$



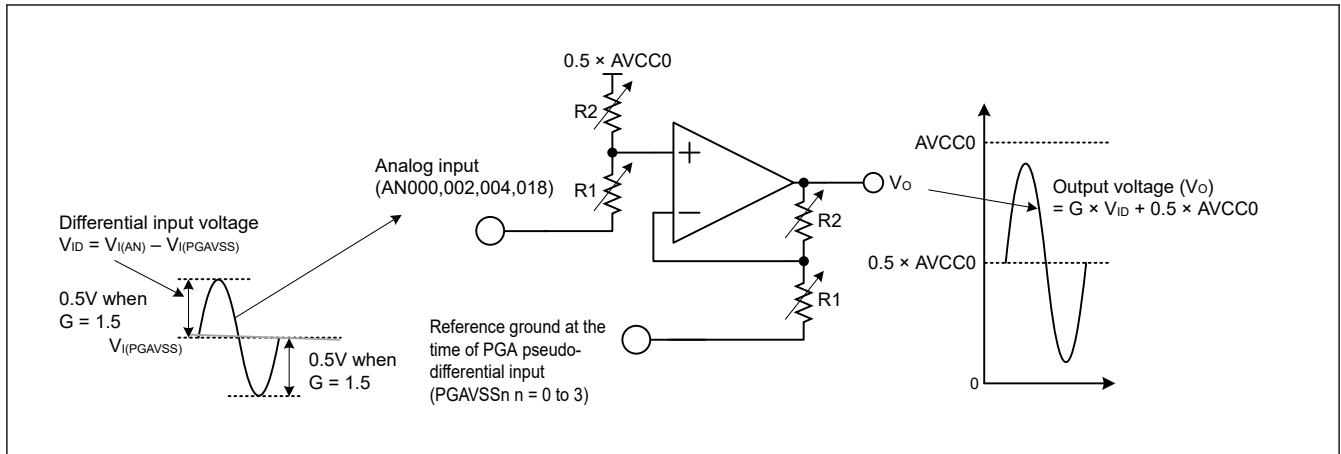


Figure 2.51 Input and Output Signal Levels with the PGA's Pseudo-Differential Setting

## 2.9 OSC Stop Detect Characteristics

Table 2.43 Oscillation stop detection circuit characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Detection time	$t_{dr}$	—	—	1	ms	Figure 2.52

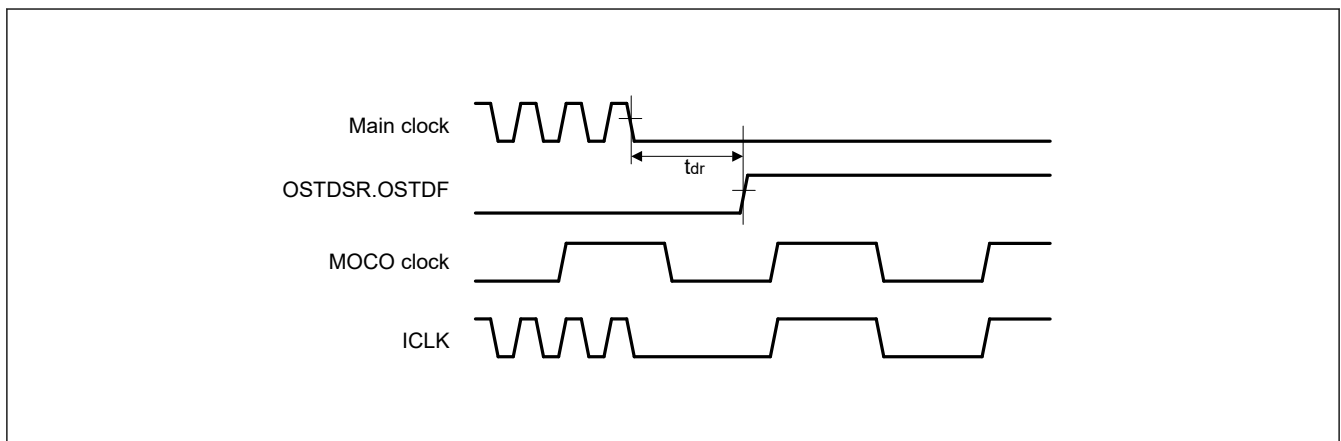


Figure 2.52 Oscillation stop detection timing

2.10 POR and LVD Characteristics

Table 2.44 Power-on reset circuit and voltage detection circuit characteristics (1)

Parameter			Symbol	Min	Typ	Max	Unit	Test conditions	
Voltage detection level	Power-on reset (POR)	DPSBYCR.DEEP_CUT[1:0] = 00b or 01b.	$V_{POR}$	2.5	2.6	2.7	V	Figure 2.53	
		DPSBYCR.DEEP_CUT[1:0] = 11b.		1.8	2.25	2.7			
	Voltage detection circuit (LVD0)		$V_{det0\_1}$	2.84	2.94	3.04		Figure 2.54	
				$V_{det0\_2}$	2.77	2.87			2.97
				$V_{det0\_3}$	2.70	2.80			2.90
	Voltage detection circuit (LVD1)		$V_{det1\_1}$	2.89	2.99	3.09		Figure 2.55	
				$V_{det1\_2}$	2.82	2.92			3.02
				$V_{det1\_3}$	2.75	2.85			2.95
	Voltage detection circuit (LVD2)		$V_{det2\_1}$	2.89	2.99	3.09		Figure 2.56	
				$V_{det2\_2}$	2.82	2.92			3.02
				$V_{det2\_3}$	2.75	2.85			2.95
	Internal reset time	Power-on reset time		$t_{POR}$	—	4.5		—	ms
LVD0 reset time		$t_{LVD0}$	—	0.51	—	Figure 2.54			
LVD1 reset time		$t_{LVD1}$	—	0.38	—	Figure 2.55			
LVD2 reset time		$t_{LVD2}$	—	0.38	—	Figure 2.56			
Minimum VCC down time <sup>*1</sup>			$t_{VOFF}$	200	—	—	$\mu$ s	Figure 2.53, Figure 2.54	
Response delay			$t_{det}$	—	—	200	$\mu$ s	Figure 2.54 to Figure 2.56	
LVD operation stabilization time (after LVD is enabled)			$t_{d(E-A)}$	—	—	10	$\mu$ s	Figure 2.55, Figure 2.56	
Hysteresis width (LVD1 and LVD2)			$V_{LVH}$	—	70	—	mV		

Note 1. The minimum VCC down time indicates the time when VCC is below the minimum value of voltage detection levels  $V_{POR}$ ,  $V_{det0}$ ,  $V_{det1}$ , and  $V_{det2}$  for POR and LVD.

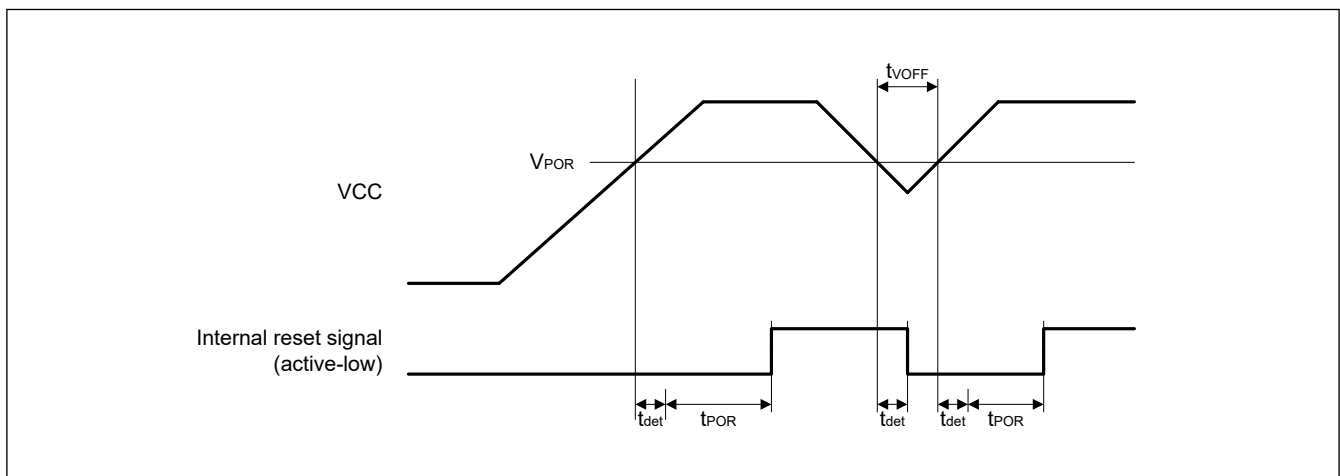


Figure 2.53 Power-on reset timing

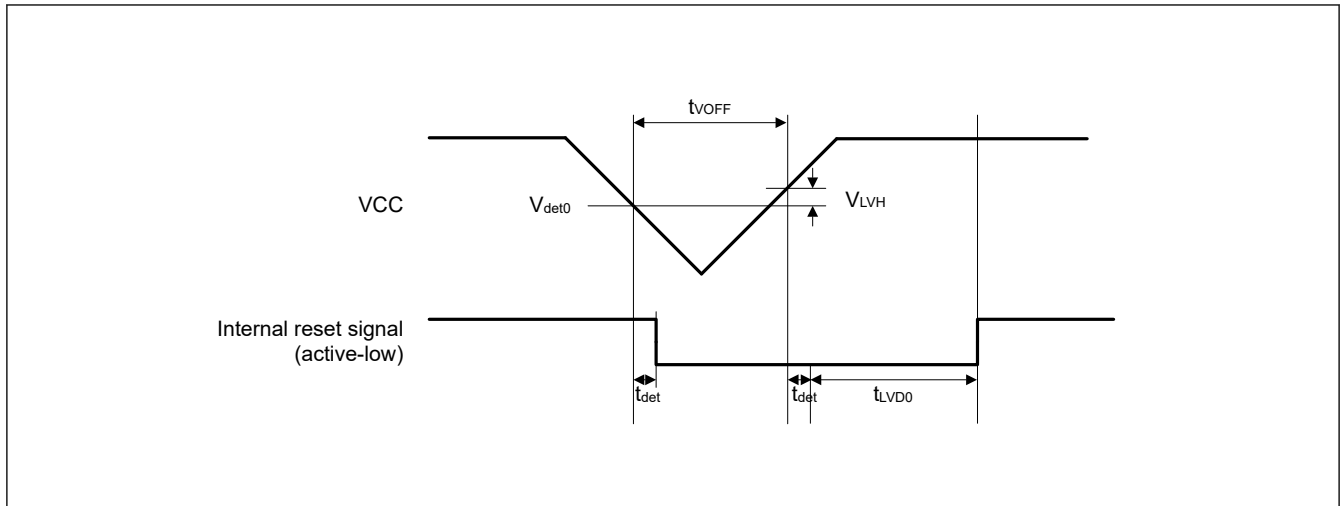


Figure 2.54 Voltage detection circuit timing ( $V_{det0}$ )

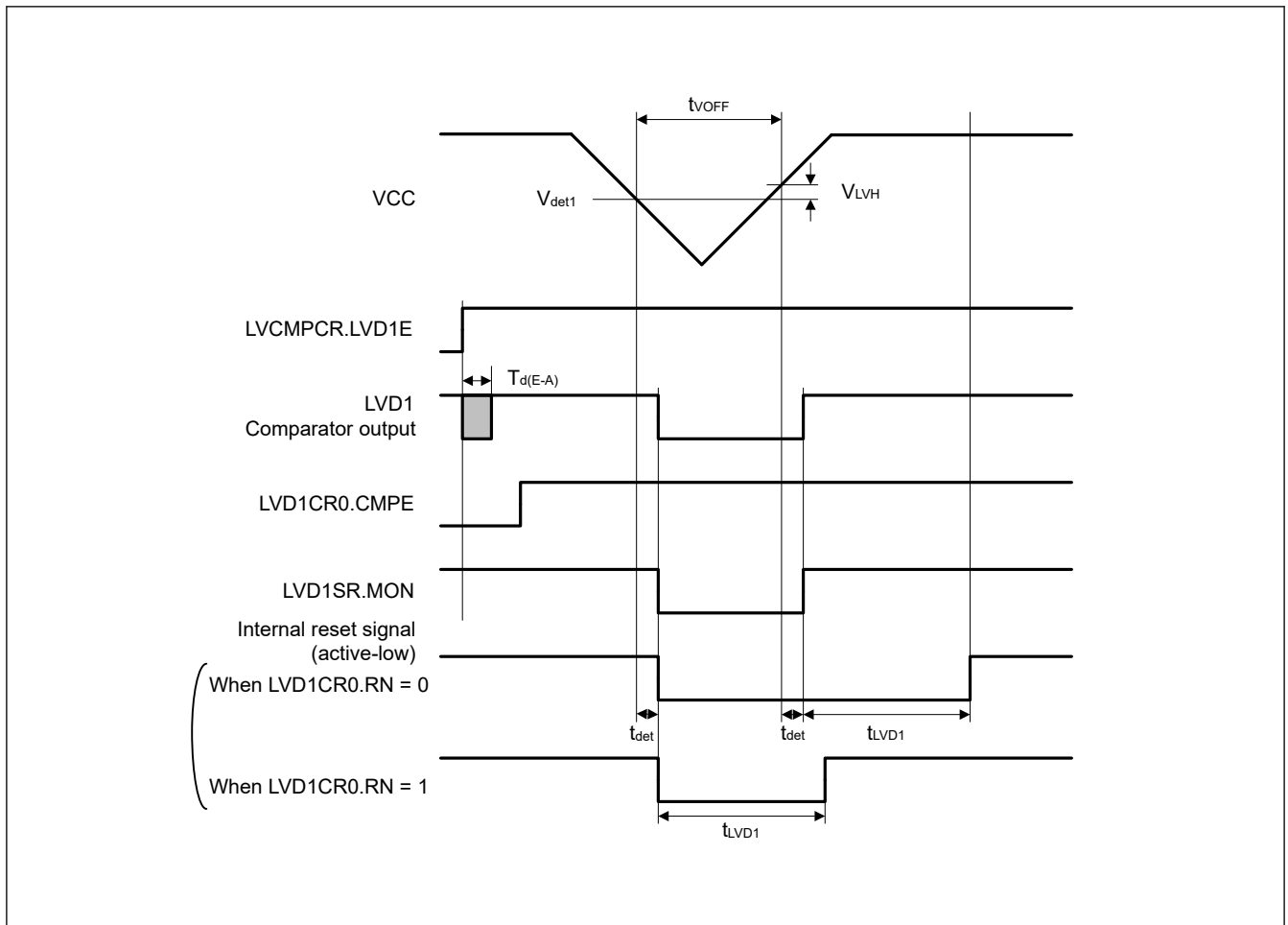


Figure 2.55 Voltage detection circuit timing ( $V_{det1}$ )

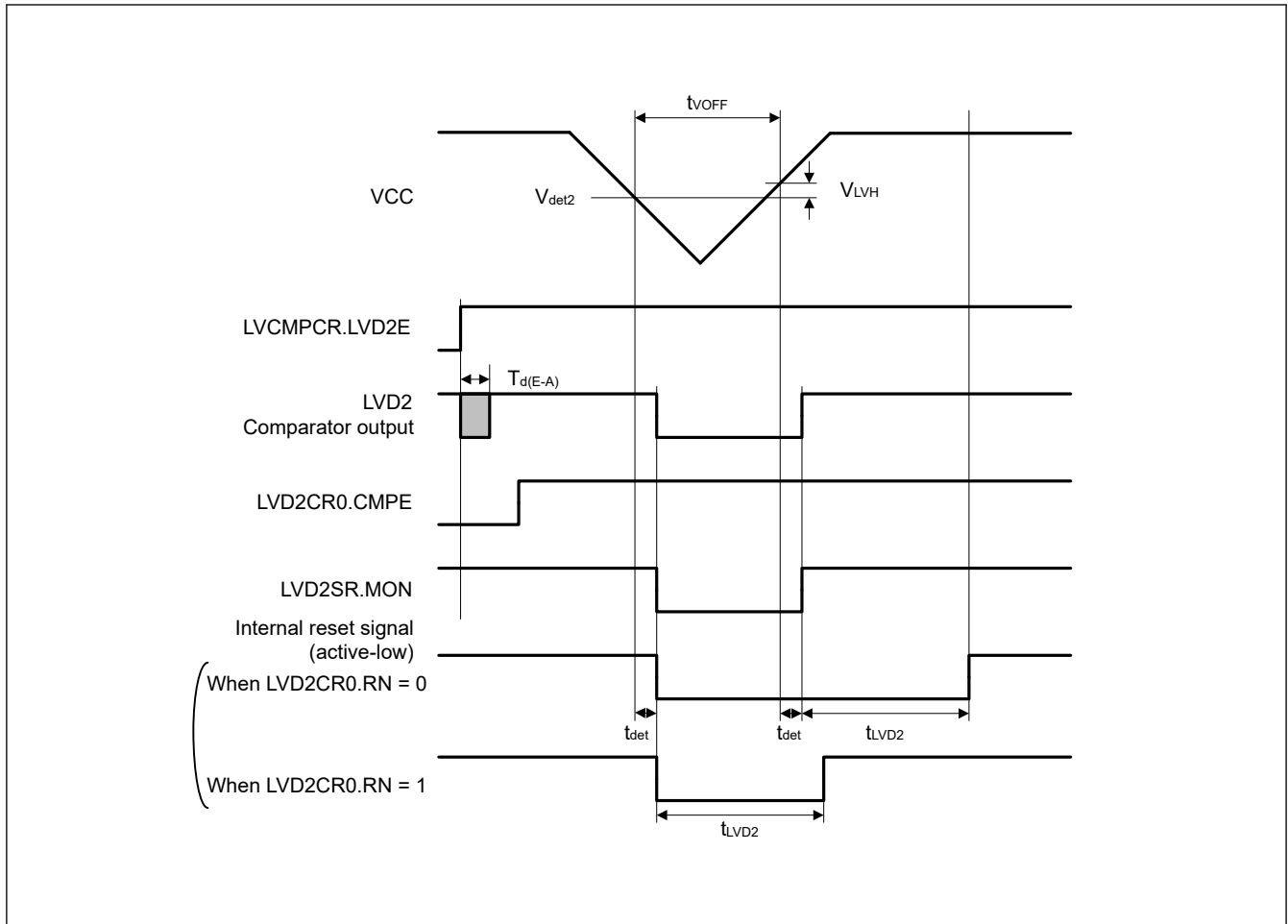


Figure 2.56 Voltage detection circuit timing ( $V_{det2}$ )

## 2.11 Flash Memory Characteristics

### 2.11.1 Code Flash Memory Characteristics

Table 2.45 Code flash memory characteristics (1 of 2)

Conditions: Program or erase: FCLK = 4 to 60 MHz  
Read: FCLK ≤ 60 MHz

Parameter	Symbol	FCLK = 4 MHz			20 MHz ≤ FCLK ≤ 60 MHz			Unit	Test conditions	
		Min	Typ*6	Max	Min	Typ*6	Max			
Programming time $N_{PEC} \leq 100$ times	128-byte	$t_{P128}$	—	0.75	13.2	—	0.34	6.0	ms	
	8-KB	$t_{P8K}$	—	49	176	—	22	80	ms	
	32-KB	$t_{P32K}$	—	194	704	—	88	320	ms	
Programming time $N_{PEC} > 100$ times	128-byte	$t_{P128}$	—	0.91	15.8	—	0.41	7.2	ms	
	8-KB	$t_{P8K}$	—	60	212	—	27	96	ms	
	32-KB	$t_{P32K}$	—	234	848	—	106	384	ms	
Erasure time $N_{PEC} \leq 100$ times	8-KB	$t_{E8K}$	—	78	216	—	43	120	ms	
	32-KB	$t_{E32K}$	—	283	864	—	157	480	ms	
Erasure time $N_{PEC} > 100$ times	8-KB	$t_{E8K}$	—	94	260	—	52	144	ms	
	32-KB	$t_{E32K}$	—	341	1040	—	189	576	ms	
Reprogramming/erasure cycle*4	$N_{PEC}$	10000*1	—	—	10000*1	—	—	—	Times	

**Table 2.45 Code flash memory characteristics (2 of 2)**

Conditions: Program or erase: FCLK = 4 to 60 MHz

Read: FCLK ≤ 60 MHz

Parameter	Symbol	FCLK = 4 MHz			20 MHz ≤ FCLK ≤ 60 MHz			Unit	Test conditions
		Min	Typ <sup>*6</sup>	Max	Min	Typ <sup>*6</sup>	Max		
Suspend delay during programming	t <sub>SPD</sub>	—	—	264	—	—	120	μs	
Programming resume time	t <sub>PRT</sub>	—	—	110	—	—	50	μs	
First suspend delay during erasure in suspend priority mode	t <sub>SESD1</sub>	—	—	216	—	—	120	μs	
Second suspend delay during erasure in suspend priority mode	t <sub>SESD2</sub>	—	—	1.7	—	—	1.7	ms	
Suspend delay during erasure in erasure priority mode	t <sub>SEED</sub>	—	—	1.7	—	—	1.7	ms	
First erasing resume time during erasure in suspend priority mode <sup>*5</sup>	t <sub>REST1</sub>	—	—	1.7	—	—	1.7	ms	
Second erasing resume time during erasure in suspend priority mode	t <sub>REST2</sub>	—	—	144	—	—	80	μs	
Erasing resume time during erasure in erasure priority mode	t <sub>REET</sub>	—	—	144	—	—	80	μs	
Forced stop command	t <sub>FD</sub>	—	—	32	—	—	20	μs	
Data hold time <sup>*2</sup>	t <sub>DRP</sub>	10 <sup>*2 *3</sup>	—	—	10 <sup>*2 *3</sup>	—	—	Years	Ta = +85°C
		30 <sup>*2 *3</sup>	—	—	30 <sup>*2 *3</sup>	—	—		

Note 1. This is the minimum number of times to guarantee all the characteristics after reprogramming. The guaranteed range is from 1 to the minimum value.

Note 2. This indicates the minimum value of the characteristic when reprogramming is performed within the specified range.

Note 3. This result is obtained from reliability testing.

Note 4. The reprogram/erase cycle is the number of erasures for each block. When the reprogram/erase cycle is n times (n = 10,000), erasing can be performed n times for each block. For example, when 128-byte programming is performed 64 times for different addresses in 8-KB blocks, and then the entire block is erased, the reprogram/erase cycle is counted as one. However, programming the same address several times as one erasure is not enabled. Overwriting is prohibited.

Note 5. Time for resumption includes time for reapplying the erasing pulse (up to one full pulse) that was cut off at the time of suspension.

Note 6. The reference value at VCC = 3.3V and room temperature.

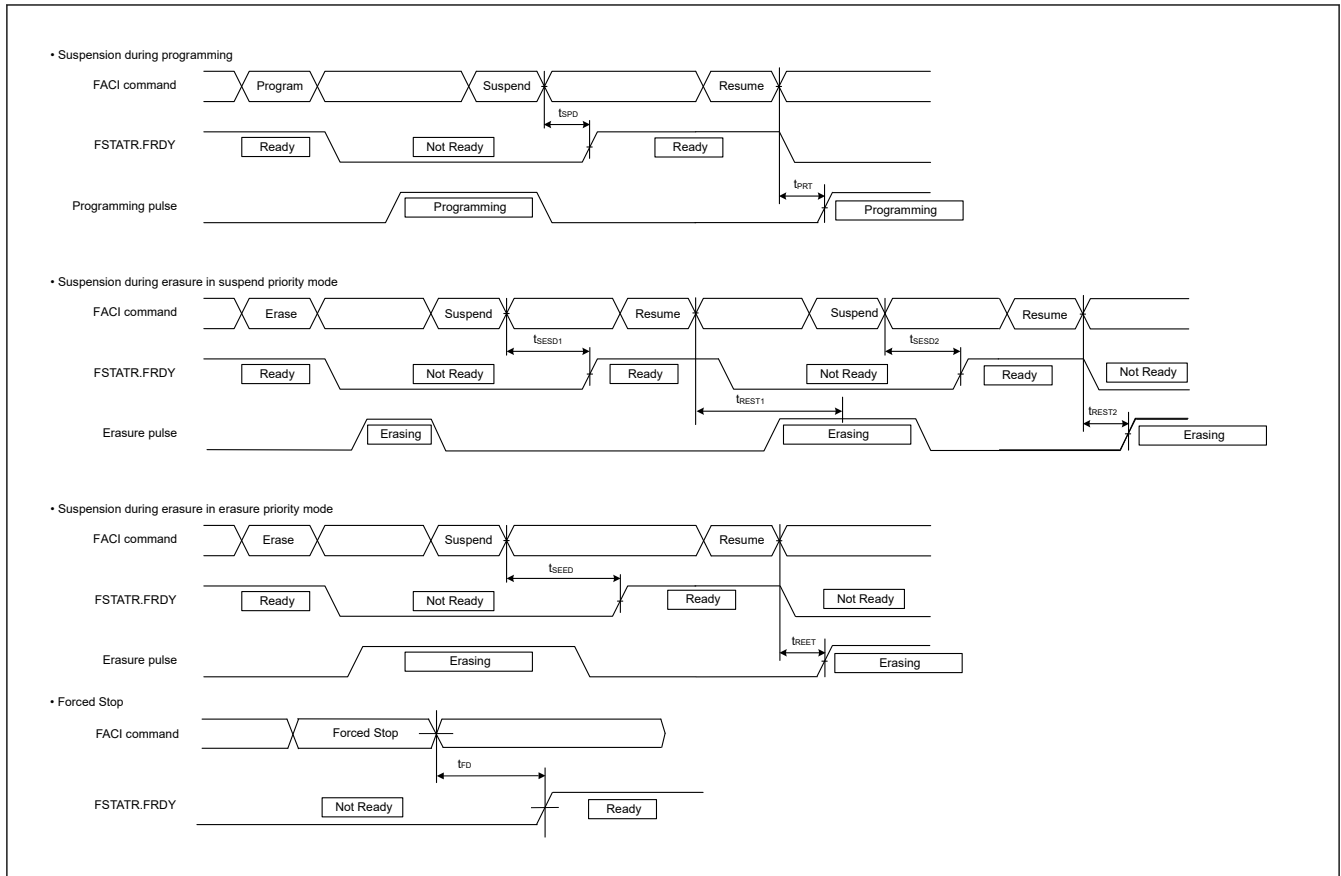


Figure 2.57 Suspension and forced stop timing for flash memory programming and erasure

2.11.2 Data Flash Memory Characteristics

Table 2.46 Data flash memory characteristics (1 of 2)

Conditions: Program or erase: FCLK = 4 to 60 MHz  
Read: FCLK ≤ 60 MHz

Parameter	Symbol	FCLK = 4 MHz			20 MHz ≤ FCLK ≤ 60 MHz			Unit	Test conditions
		Min	Typ*6	Max	Min	Typ*6	Max		
Programming time	4-byte	t <sub>DP4</sub>	—	0.36	3.8	—	0.16	1.7	ms
	8-byte	t <sub>DP8</sub>	—	0.38	4.0	—	0.17	1.8	
	16-byte	t <sub>DP16</sub>	—	0.42	4.5	—	0.19	2.0	
Erasure time	64-byte	t <sub>DE64</sub>	—	3.1	18	—	1.7	10	ms
	128-byte	t <sub>DE128</sub>	—	4.7	27	—	2.6	15	
	256-byte	t <sub>DE256</sub>	—	8.9	50	—	4.9	28	
Blank check time	4-byte	t <sub>DBC4</sub>	—	—	84	—	—	30	μs
Reprogramming/erasure cycle*1		N <sub>DPEC</sub>	125000*2	—	—	125000*2	—	—	—
Suspend delay during programming	4-byte	t <sub>DSPD</sub>	—	—	264	—	—	120	μs
	8-byte		—	—	264	—	—	120	
	16-byte		—	—	264	—	—	120	
Programming resume time		t <sub>DPRT</sub>	—	—	110	—	—	50	μs
First suspend delay during erasure in suspend priority mode	64-byte	t <sub>DSESD1</sub>	—	—	216	—	—	120	μs
	128-byte		—	—	216	—	—	120	
	256-byte		—	—	216	—	—	120	

**Table 2.46 Data flash memory characteristics (2 of 2)**

Conditions: Program or erase: FCLK = 4 to 60 MHz  
Read: FCLK ≤ 60 MHz

Parameter	Symbol	FCLK = 4 MHz			20 MHz ≤ FCLK ≤ 60 MHz			Unit	Test conditions	
		Min	Typ <sup>*6</sup>	Max	Min	Typ <sup>*6</sup>	Max			
Second suspend delay during erasure in suspend priority mode	64-byte	t <sub>DSESD2</sub>	—	—	300	—	—	300	μs	
	128-byte		—	—	390	—	—	390		
	256-byte		—	—	570	—	—	570		
Suspend delay during erasing in erasure priority mode	64-byte	t <sub>DSEED</sub>	—	—	300	—	—	300	μs	
	128-byte		—	—	390	—	—	390		
	256-byte		—	—	570	—	—	570		
First erasing resume time during erasure in suspend priority mode <sup>*5</sup>	t <sub>DREST1</sub>	—	—	300	—	—	300	μs		
Second erasing resume time during erasure in suspend priority mode First erasing resume time during erasure in suspend priority mode	t <sub>DREST2</sub>	—	—	126	—	—	70	μs		
Erasing resume time during erasure in erasure priority mode	t <sub>DREET</sub>	—	—	126	—	—	70	μs		
Forced stop command	t <sub>FD</sub>	—	—	32	—	—	20	μs		
Data hold time <sup>*3</sup>	t <sub>DRP</sub>	10 <sup>*3</sup> *4	—	—	10 <sup>*3</sup> *4	—	—	Year	Ta = +85°C	
		30 <sup>*3</sup> *4	—	—	30 <sup>*3</sup> *4	—	—			

Note 1. The reprogram/erase cycle is the number of erasures for each block. When the reprogram/erase cycle is n times (n = 125,000), erasing can be performed n times for each block. For example, when 4-byte programming is performed 16 times for different addresses in 64-byte blocks, and then the entire block is erased, the reprogram/erase cycle is counted as one. However, programming the same address several times as one erasure is not enabled. Overwriting is prohibited.

Note 2. This is the minimum number of times to guarantee all the characteristics after reprogramming. The guaranteed range is from 1 to the minimum value.

Note 3. This indicates the minimum value of the characteristic when reprogramming is performed within the specified range.

Note 4. This result is obtained from reliability testing.

Note 5. Time for resumption includes time for reapplying the erasing pulse (up to one full pulse) that was cut off at the time of suspension.

Note 6. The reference value at VCC = 3.3 V and room temperature.

### 2.11.3 Option Setting Memory Characteristics

**Table 2.47 Option setting memory characteristics**

Conditions: Program: FCLK = 4 to 60 MHz  
Read: FCLK ≤ 60 MHz

Parameter	Symbol	FCLK = 4 MHz			20 MHz ≤ FCLK ≤ 60 MHz			Unit	Test conditions
		Min	Typ <sup>*4</sup>	Max	Min	Typ <sup>*4</sup>	Max		
Programming time N <sub>OPC</sub> ≤ 100 times	t <sub>OP</sub>	—	83	309	—	45	162	ms	
Programming time N <sub>OPC</sub> > 100 times	t <sub>OP</sub>	—	100	371	—	55	195	ms	
Reprogramming cycle	N <sub>OPC</sub>	20000 <sup>*1</sup>	—	—	20000 <sup>*1</sup>	—	—	Times	
Data hold time <sup>*2</sup>	t <sub>DRP</sub>	10 <sup>*2</sup> *3	—	—	10 <sup>*2</sup> *3	—	—	Years	Ta = +85°C
		30 <sup>*2</sup> *3	—	—	30 <sup>*2</sup> *3	—	—		

Note 1. This is the minimum number of times to guarantee all the characteristics after reprogramming. The guaranteed range is from 1 to the minimum value.

Note 2. This indicates the minimum value of the characteristic when reprogramming is performed within the specified range.

Note 3. This result is obtained from reliability testing.

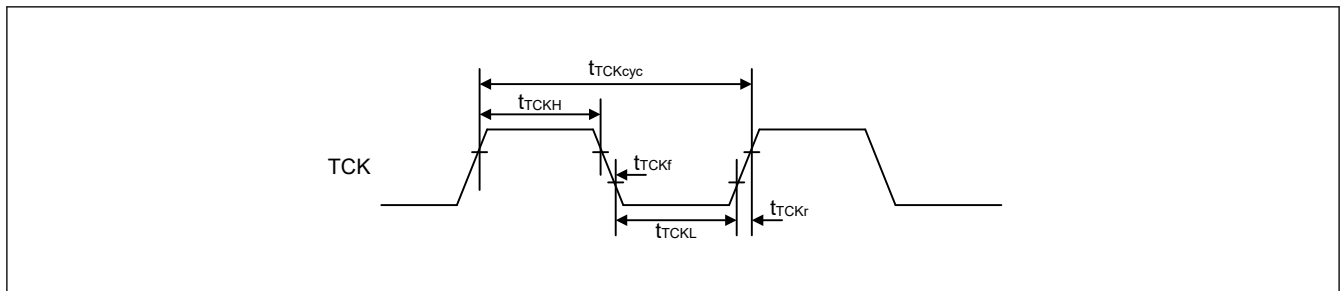
Note 4. The reference value at VCC = 3.3 V and room temperature.

## 2.12 Boundary Scan

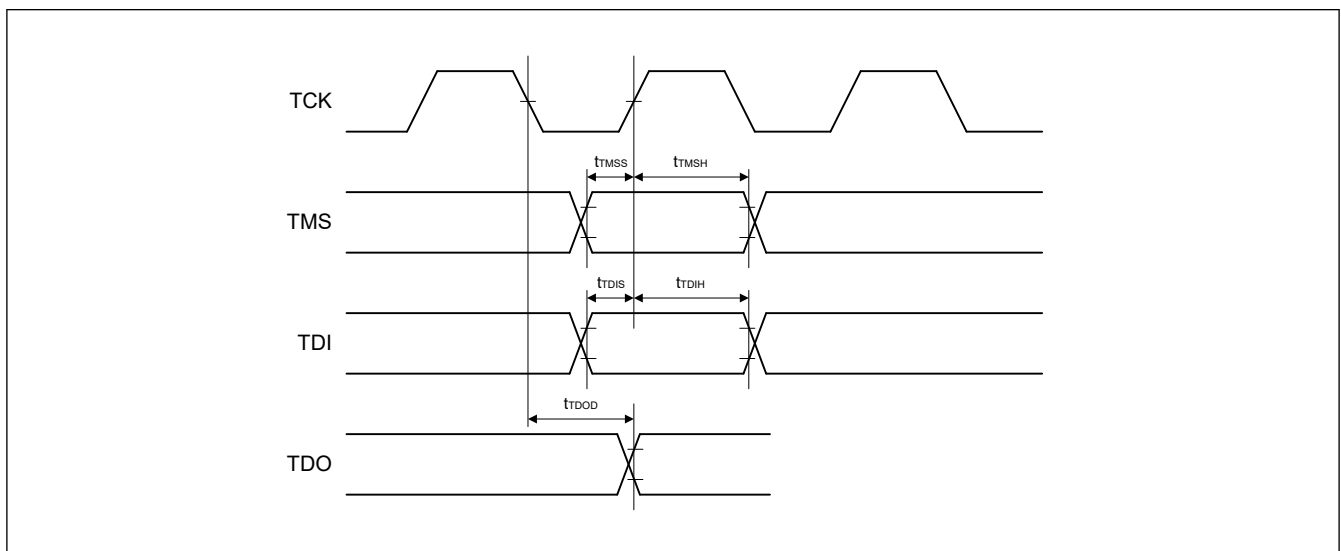
**Table 2.48 Boundary scan characteristics**

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
TCK clock cycle time	$t_{TCKcyc}$	100	—	—	ns	Figure 2.58
TCK clock high pulse width	$t_{TCKH}$	45	—	—	ns	
TCK clock low pulse width	$t_{TCKL}$	45	—	—	ns	
TCK clock rise time	$t_{TCKr}$	—	—	5	ns	
TCK clock fall time	$t_{TCKf}$	—	—	5	ns	
TMS setup time	$t_{TMSS}$	20	—	—	ns	Figure 2.59
TMS hold time	$t_{TMSH}$	20	—	—	ns	
TDI setup time	$t_{TDIS}$	20	—	—	ns	
TDI hold time	$t_{TDIH}$	20	—	—	ns	
TDO data delay	$t_{TDOD}$	—	—	40	ns	Figure 2.60
Boundary scan circuit startup time*1	$T_{BSSTUP}$	$t_{RESWP}$	—	—	—	

Note 1. Boundary scan does not function until the power-on reset becomes negative.



**Figure 2.58 Boundary scan TCK timing**



**Figure 2.59 Boundary scan input/output timing**



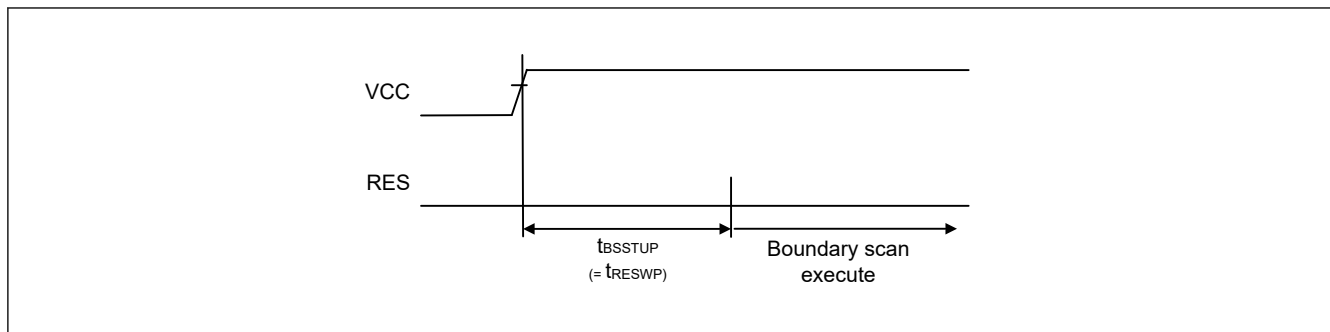


Figure 2.60 Boundary scan circuit startup timing

### 2.13 Joint Test Action Group (JTAG)

Table 2.49 JTAG

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
TCK clock cycle time	$t_{TCKcyc}$	40	—	—	ns	Figure 2.61
TCK clock high pulse width	$t_{TCKH}$	15	—	—	ns	
TCK clock low pulse width	$t_{TCKL}$	15	—	—	ns	
TCK clock rise time	$t_{TCKr}$	—	—	5	ns	
TCK clock fall time	$t_{TCKf}$	—	—	5	ns	
TMS setup time	$t_{TMSS}$	8	—	—	ns	Figure 2.62
TMS hold time	$t_{TMSH}$	8	—	—	ns	
TDI setup time	$t_{TDIS}$	8	—	—	ns	
TDI hold time	$t_{TDIH}$	8	—	—	ns	
TDO data delay time	$t_{TDOD}$	—	—	20	ns	

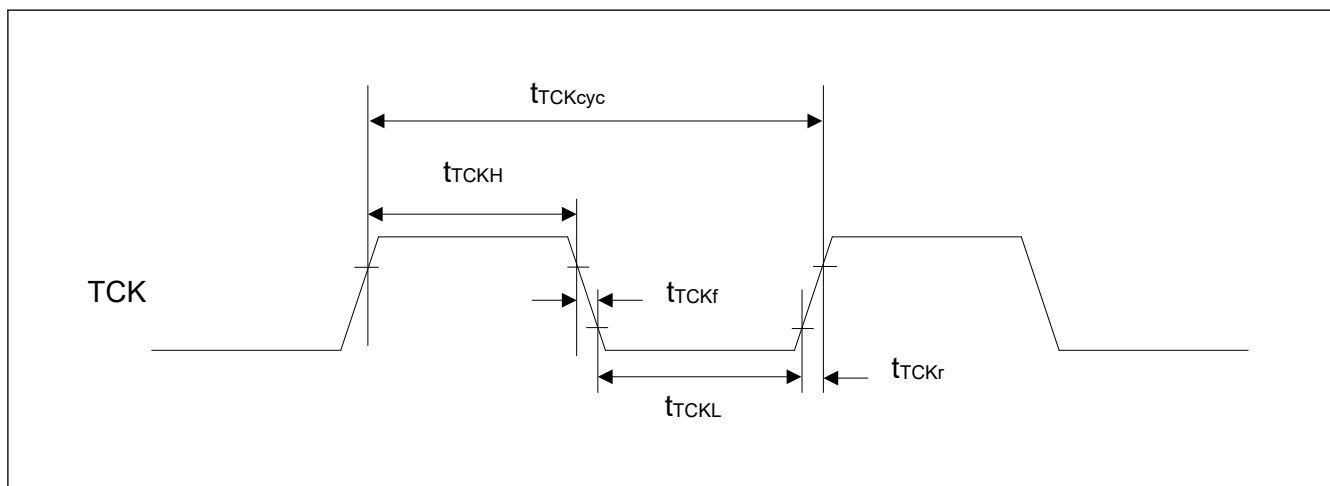


Figure 2.61 JTAG TCK timing

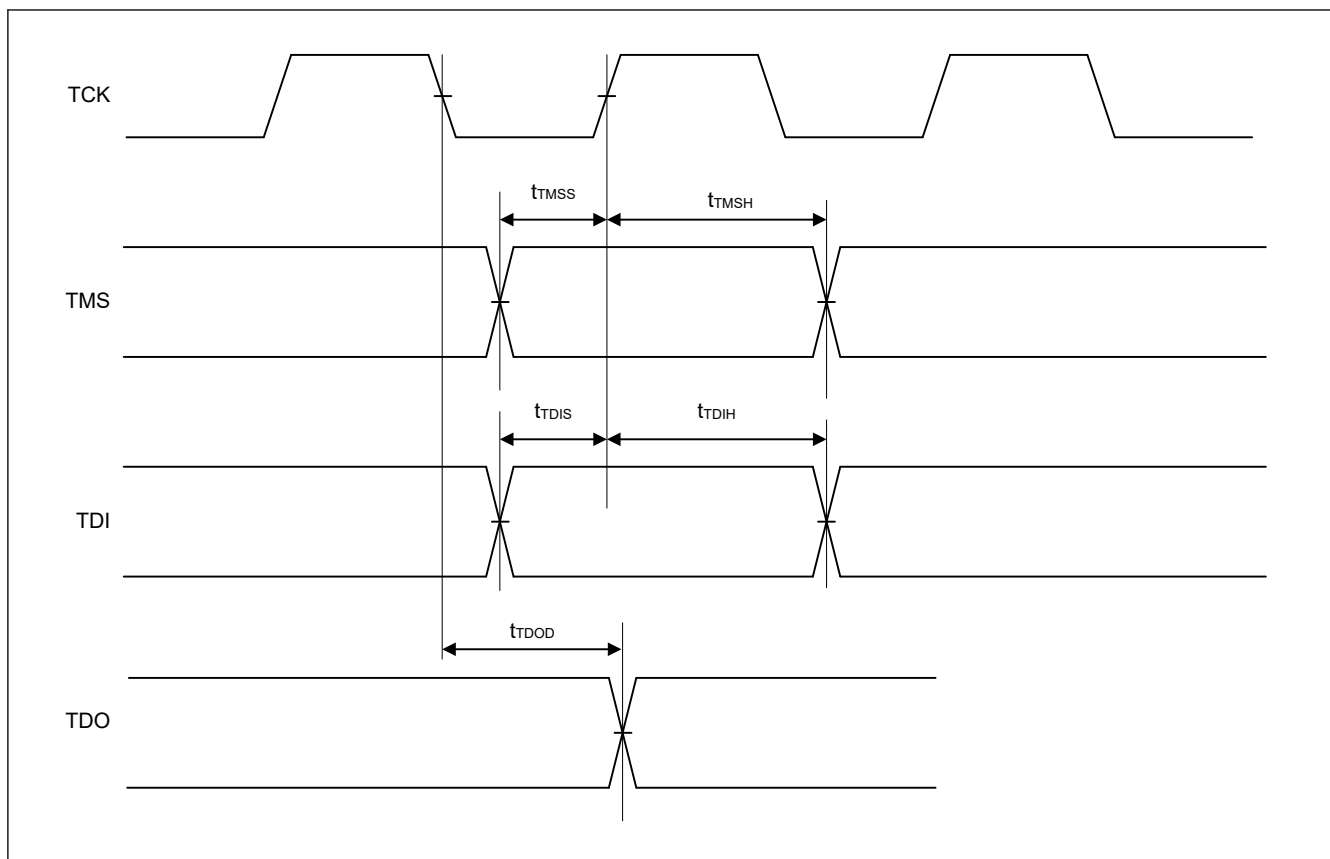


Figure 2.62 JTAG input/output timing

## 2.14 Serial Wire Debug (SWD)

Table 2.50 SWD

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
SWCLK clock cycle time	$t_{SWCKcyc}$	40	—	—	ns	Figure 2.63
SWCLK clock high pulse width	$t_{SWCKH}$	15	—	—	ns	
SWCLK clock low pulse width	$t_{SWCKL}$	15	—	—	ns	
SWCLK clock rise time	$t_{SWCKr}$	—	—	5	ns	
SWCLK clock fall time	$t_{SWCKf}$	—	—	5	ns	
SWDIO setup time	$t_{SWDS}$	8	—	—	ns	Figure 2.64
SWDIO hold time	$t_{SWDH}$	8	—	—	ns	
SWDIO data delay time	$t_{SWDD}$	2	—	28	ns	

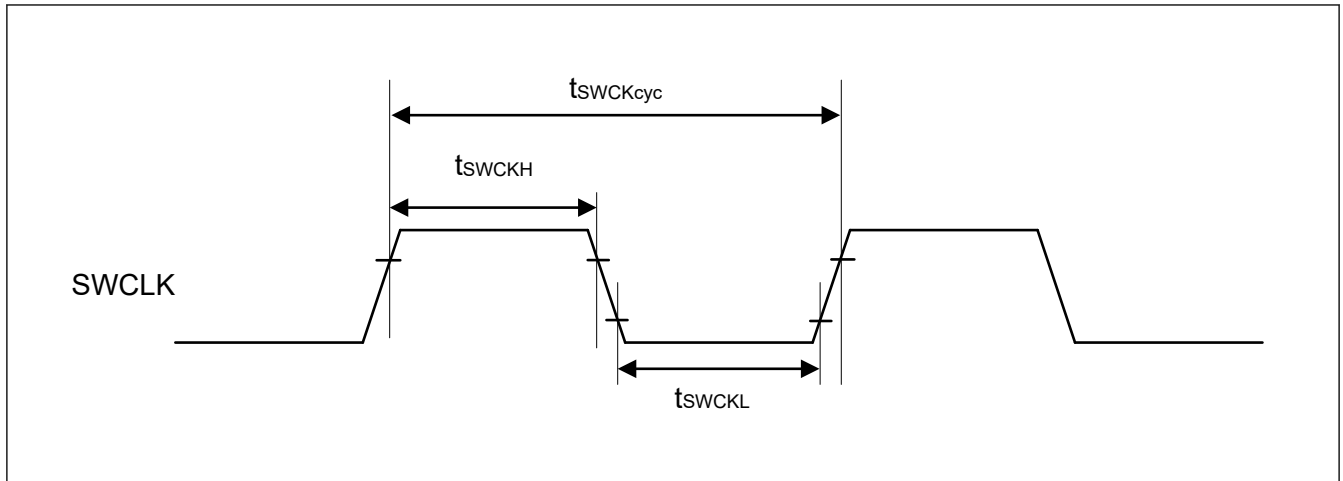


Figure 2.63 SWD SWCLK timing

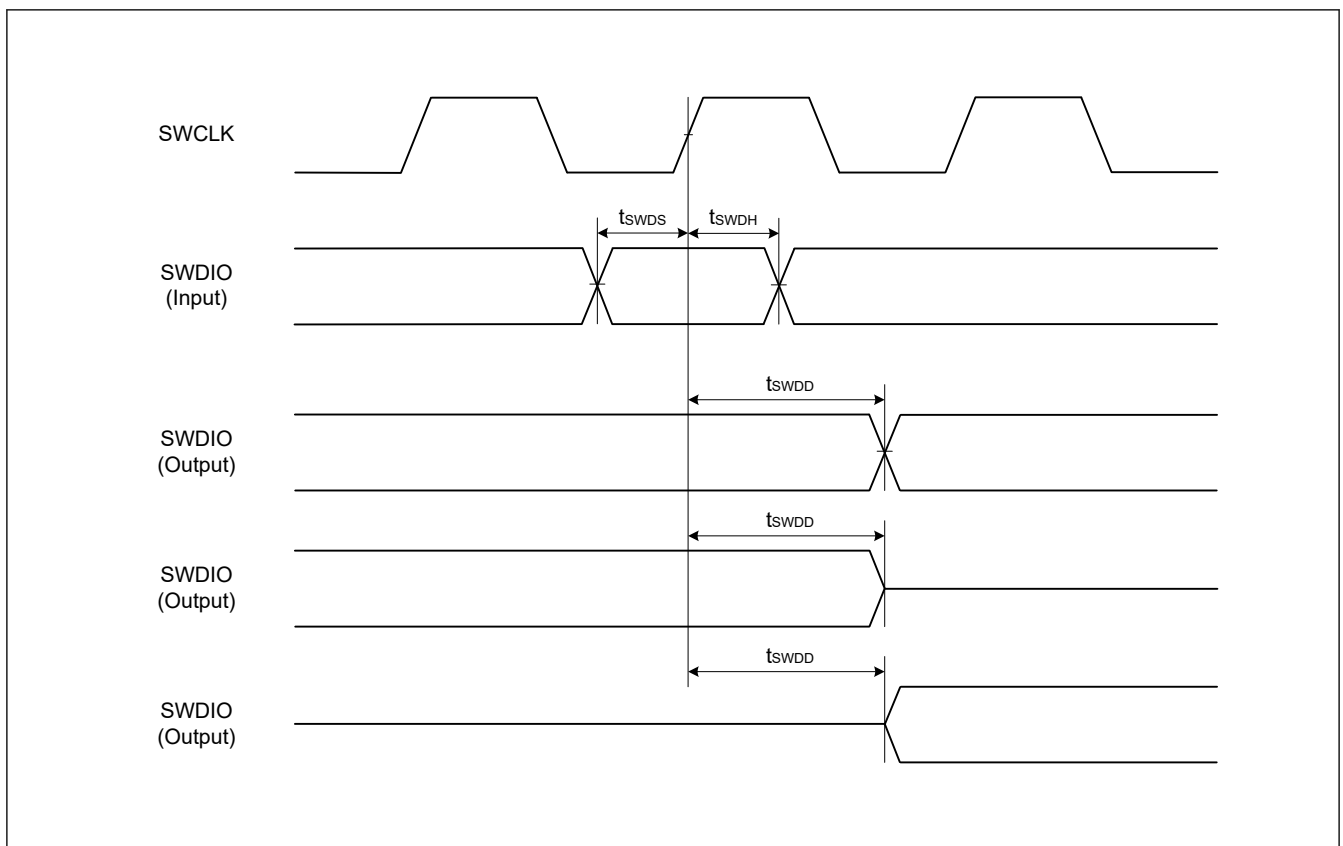


Figure 2.64 SWD input/output timing

### 2.15 Embedded Trace Macro Interface (ETM)

**Table 2.51 ETM**

Conditions: High speed high drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
TCLK clock cycle time	$t_{TCLKcyc}$	16.7	—	—	ns	Figure 2.65
TCLK clock high pulse width	$t_{TCLKH}$	7.35	—	—	ns	
TCLK clock low pulse width	$t_{TCLKL}$	7.35	—	—	ns	
TCLK clock rise time	$t_{TCLKr}$	—	—	1	ns	
TCLK clock fall time	$t_{TCLKf}$	—	—	1	ns	
TDATA[3:0] output setup time	$t_{TRDS}$	2.5	—	—	ns	Figure 2.66
TDATA[3:0] output hold time	$t_{TRDH}$	1.5	—	—	ns	

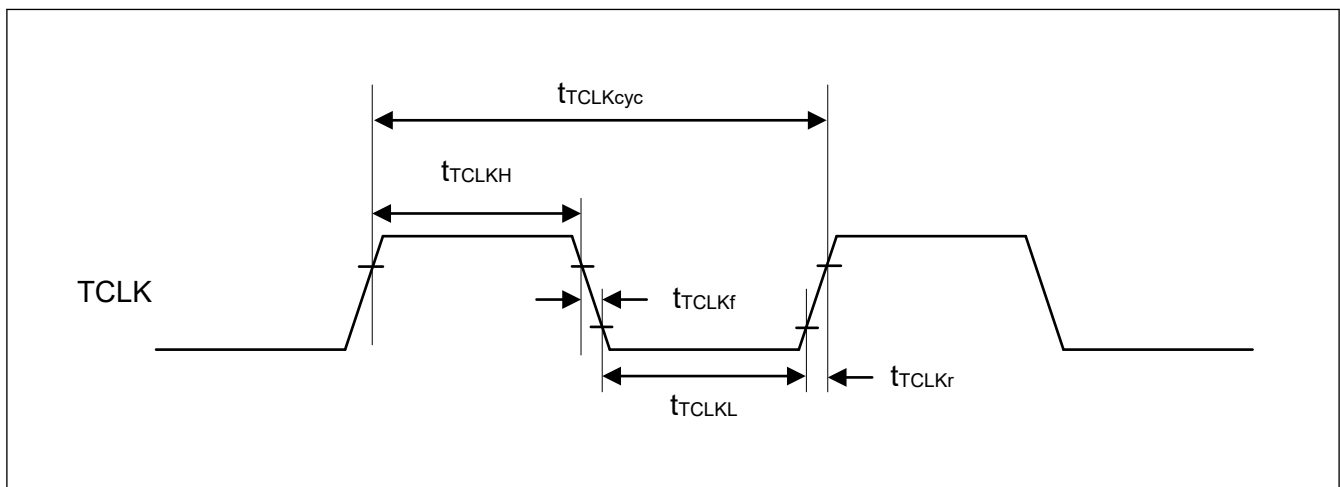


Figure 2.65 ETM TCLK timing

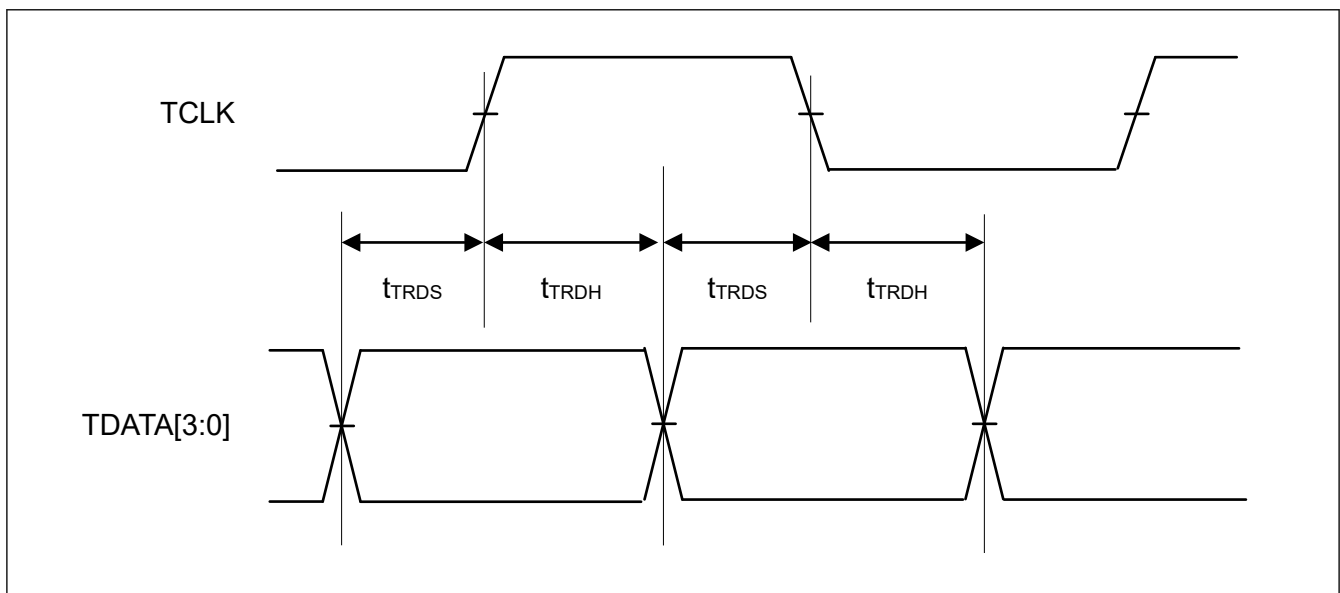


Figure 2.66 ETM output timing

## Appendix 1. Port States in Each Processing Mode

Function	Pin function	Reset	Software Standby mode	Deep Software Standby mode	After Deep Software Standby mode is canceled (return to startup mode)	
					IOKEEP = 0	IOKEEP = 1 <sup>*1</sup>
Mode	MD	Pull-up	Keep-O	Keep	Hi-Z	Keep
JTAG	TCK/TMS/TDI	Pull-up	Keep-O	Keep	Hi-Z	Keep
	TDO	TDO output	Keep-O	Keep	TDO output	Keep
Trace	TCLK/TDATAx	Hi-Z	Keep-O	Keep	Hi-Z	Keep
IRQ	IRQx	Hi-Z	Keep-O <sup>*2</sup>	Keep	Hi-Z	Keep
	IRQx-DS	Hi-Z	Keep-O <sup>*2</sup>	Keep <sup>*3</sup>	Hi-Z	Keep
KINT	KRxx	Hi-Z	Keep-O <sup>*2</sup>	Keep	Hi-Z	Keep
AGT	AGTIO <sub>n</sub>	Hi-Z	Keep-O <sup>*2</sup>	Keep	Hi-Z	Keep
IIC	SCL <sub>n</sub> /SDA <sub>n</sub>	Hi-Z	Keep-O <sup>*2</sup>	Keep	Hi-Z	Keep
CLKOUT	CLKOUT	Hi-Z	[CLKOUT selected] CLKOUT output	Keep	Hi-Z	Keep
ACMPHS	VCO <sub>UT</sub> , CMPO <sub>UT</sub> <sub>m</sub> , CMPO <sub>UT</sub> 012	Hi-Z	Hi-Z (Keep-O)	Hi-Z (Keep-O)	Hi-Z	Keep
	IVREF <sub>n</sub>	Hi-Z	Hi-Z (Keep-O)	Hi-Z (Keep-O)	Hi-Z	Hi-Z
	IVCMP <sub>m</sub>	Hi-Z	Hi-Z (Keep-O)	Hi-Z (Keep-O)	Hi-Z	Hi-Z
DAC12	DA <sub>n</sub>	Hi-Z	[DA <sub>n</sub> output (DAOE = 1)] D/A output retained	Keep	Hi-Z	Keep
ADC	AN <sub>xxx</sub>	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z
	PGA <sub>IN</sub> <sub>n</sub>	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z
	PGA <sub>VSS</sub> <sub>n</sub>	Pull-up <sup>*4</sup>	Pull-up <sup>*5</sup> / Keep	Pull-up <sup>*5</sup> / Keep	Pull-up <sup>*5</sup> / Keep	Pull-up <sup>*5</sup> / Keep
	PGA <sub>OUT</sub> <sub>n</sub>	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z
Others	—	Hi-Z	Keep-O	Keep	Hi-Z	Keep

Note: H: High-level

L: Low-level

Hi-Z: High-impedance

Keep-O: Output pins retain their previous values. Input pins go to high-impedance.

Keep: Pin states are retained during periods in Software Standby mode.

Note 1. Retains the I/O port state until the DPSBYCR.IOKEEP bit is cleared to 0.

Note 2. Input is enabled if the pin is specified as the Software Standby canceling source while it is used as an external interrupt pin.

Note 3. Input is enabled if the pin is specified as the Deep Software Standby canceling source.

Note 4. The built-in pull-up is turned on to protect the circuit from negative potential inputs.

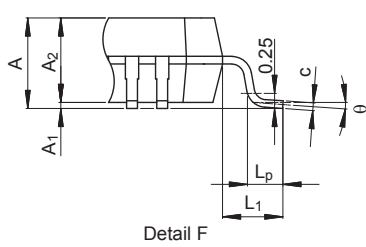
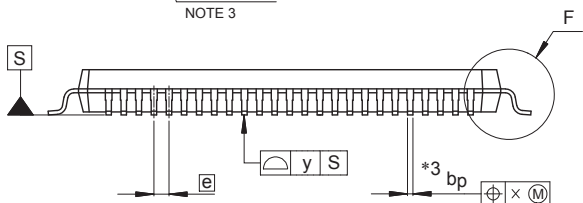
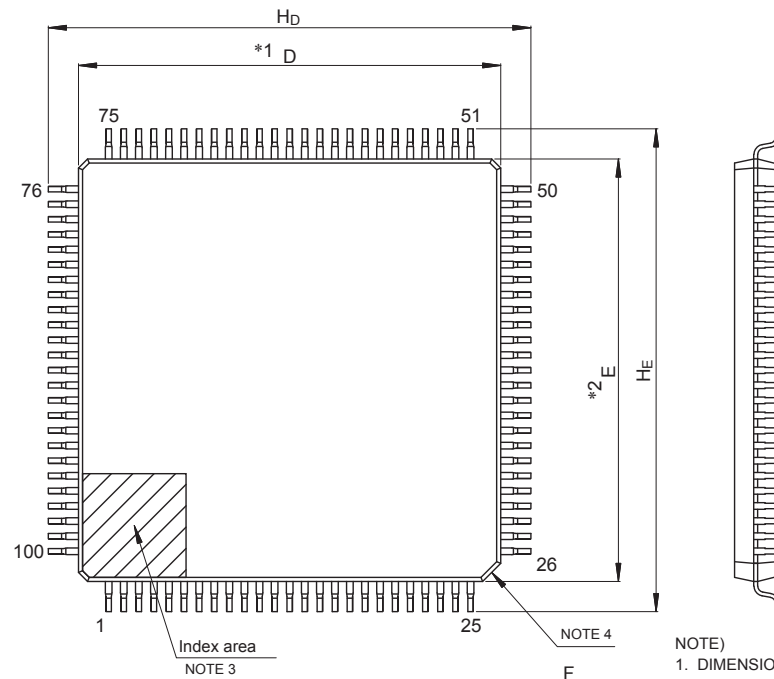
Note 5. Regardless of whether the PGA is enabled or disabled, when the PGA is set to pseudo-differential mode, the built in pull-up is turned on to protect the circuit from negative potential inputs. To turn off the built-in pull-up, turn off the PGA's pseudo-differential mode and set it to single mode.

## Appendix 2. Package Dimensions

Information on the latest version of the package dimensions or mountings is displayed in Packages on the Renesas Electronics Corporation website.

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
P-LFQFP100-14x14-0.50	PLQP0100KB-B	—	0.6

Unit: mm



- NOTE)
1. DIMENSIONS "\*\*1" AND "\*\*2" DO NOT INCLUDE MOLD FLASH.
  2. DIMENSION "\*\*3" DOES NOT INCLUDE TRIM OFFSET.
  3. PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE LOCATED WITHIN THE HATCHED AREA.
  4. CHAMFERS AT CORNERS ARE OPTIONAL, SIZE MAY VARY.

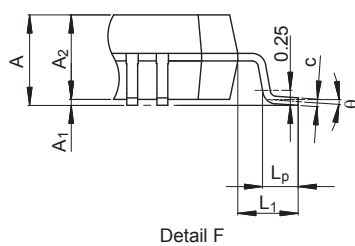
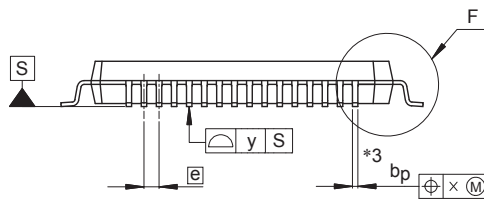
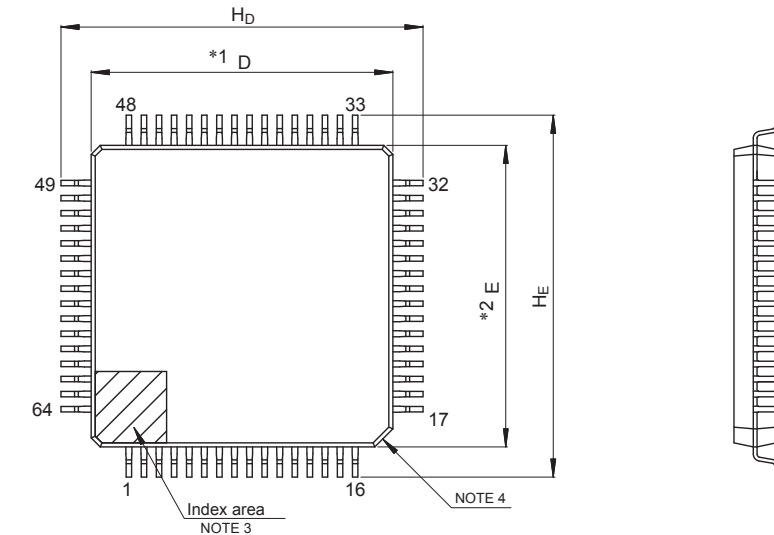
Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
D	13.9	14.0	14.1
E	13.9	14.0	14.1
A <sub>2</sub>	—	1.4	—
H <sub>D</sub>	15.8	16.0	16.2
H <sub>E</sub>	15.8	16.0	16.2
A	—	—	1.7
A <sub>1</sub>	0.05	—	0.15
b <sub>p</sub>	0.15	0.20	0.27
c	0.09	—	0.20
θ	0°	3.5°	8°
e	—	0.5	—
x	—	—	0.08
y	—	—	0.08
L <sub>p</sub>	0.45	0.6	0.75
L <sub>1</sub>	—	1.0	—

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Figure 2.1 LQFP 100-pin

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
P-LFQFP64-10x10-0.50	PLQP0064KB-C	—	0.3

Unit: mm



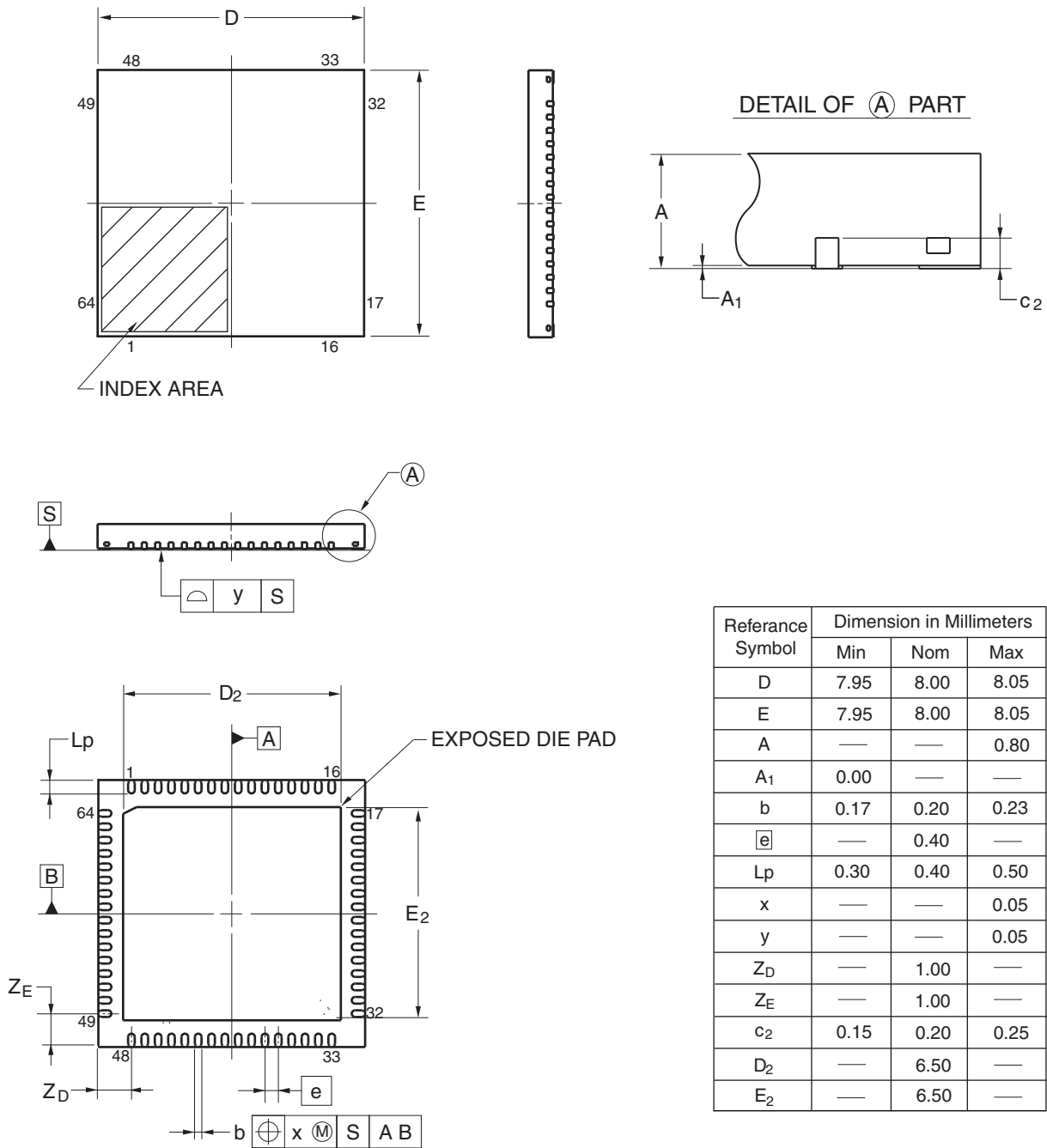
- NOTE)
1. DIMENSIONS \*\*1" AND \*\*2" DO NOT INCLUDE MOLD FLASH.
  2. DIMENSION \*\*3" DOES NOT INCLUDE TRIM OFFSET.
  3. PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE LOCATED WITHIN THE HATCHED AREA.
  4. CHAMFERS AT CORNERS ARE OPTIONAL, SIZE MAY VARY.

Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
D	9.9	10.0	10.1
E	9.9	10.0	10.1
A <sub>2</sub>	—	1.4	—
H <sub>D</sub>	11.8	12.0	12.2
H <sub>E</sub>	11.8	12.0	12.2
A	—	—	1.7
A <sub>1</sub>	0.05	—	0.15
b <sub>p</sub>	0.15	0.20	0.27
c	0.09	—	0.20
θ	0°	3.5°	8°
[e]	—	0.5	—
x	—	—	0.08
y	—	—	0.08
L <sub>p</sub>	0.45	0.6	0.75
L <sub>1</sub>	—	1.0	—

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Figure 2.2 LQFP 64-pin

JEITA Package code	RENESAS code	Previous code	MASS(TYP.)[g]
P-HWQFN64-8x8-0.40	PWQN0064LA-A	P64K8-40-9B5-3	0.16

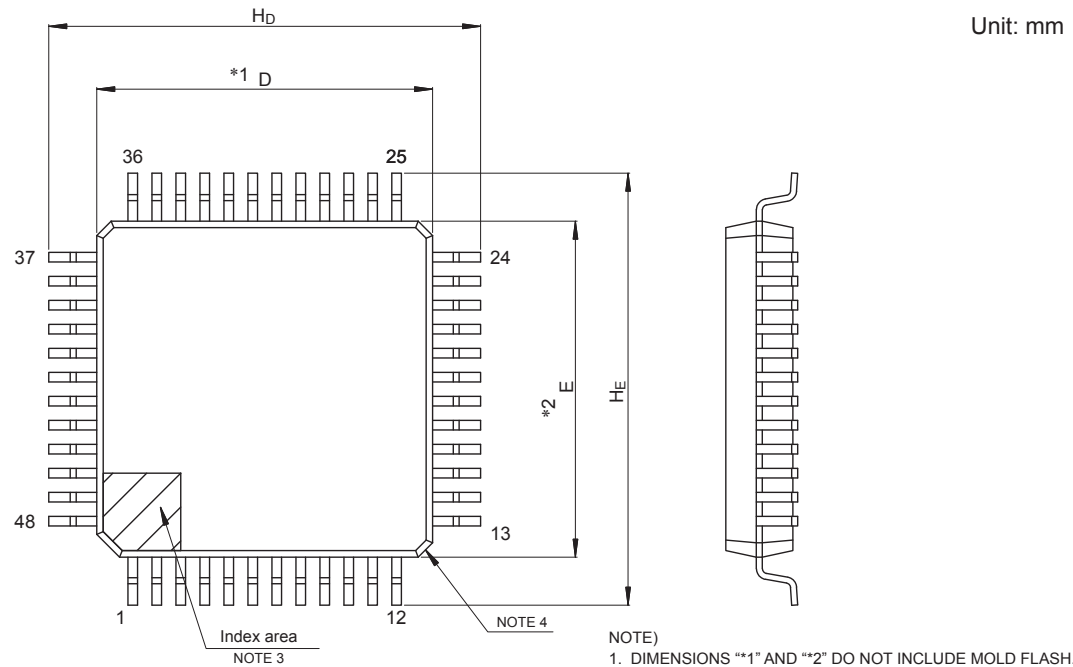


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Figure 2.3 QFN 64-pin

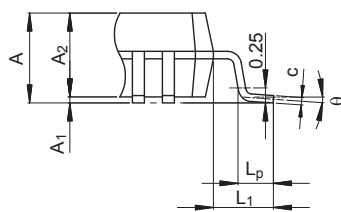
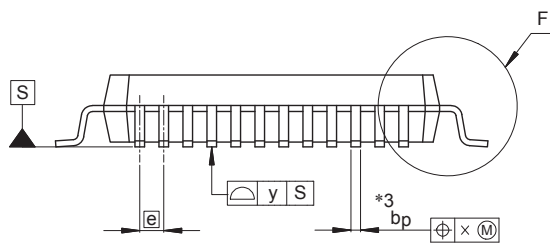


JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
P-LFQFP48-7x7-0.50	PLQP0048KB-B	—	0.2



Unit: mm

- NOTE)
1. DIMENSIONS “\*1” AND “\*2” DO NOT INCLUDE MOLD FLASH.
  2. DIMENSION “\*3” DOES NOT INCLUDE TRIM OFFSET.
  3. PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE LOCATED WITHIN THE HATCHED AREA.
  4. CHAMFERS AT CORNERS ARE OPTIONAL, SIZE MAY VARY.

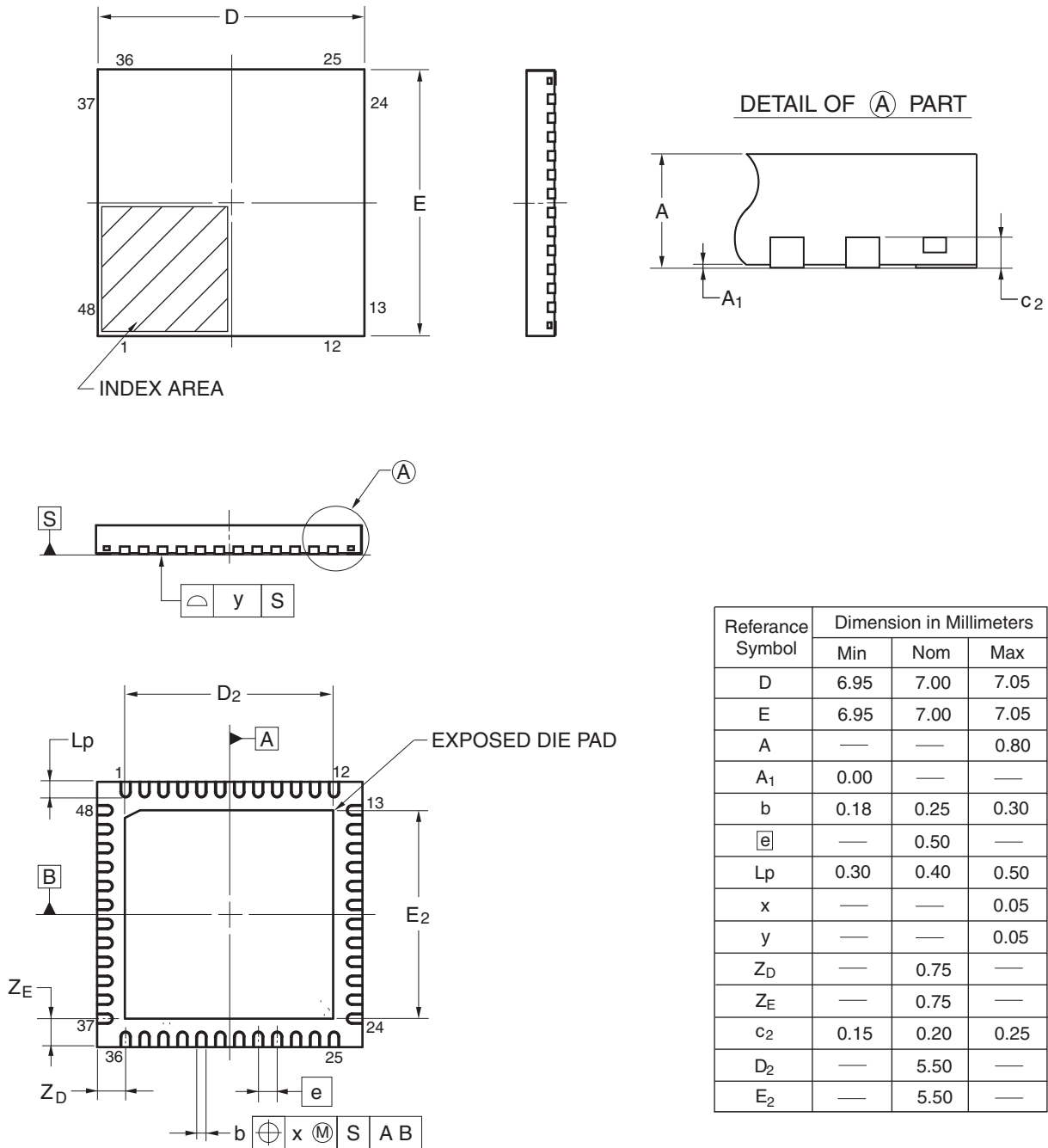


Detail F

Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
D	6.9	7.0	7.1
E	6.9	7.0	7.1
A <sub>2</sub>	—	1.4	—
H <sub>D</sub>	8.8	9.0	9.2
H <sub>E</sub>	8.8	9.0	9.2
A	—	—	1.7
A <sub>1</sub>	0.05	—	0.15
b <sub>p</sub>	0.17	0.20	0.27
c	0.09	—	0.20
θ	0°	3.5°	8°
e	—	0.5	—
x	—	—	0.08
y	—	—	0.08
L <sub>p</sub>	0.45	0.6	0.75
L <sub>1</sub>	—	1.0	—

Figure 2.4 LQFP 48-pin

JEITA Package code	RENESAS code	Previous code	MASS(TYP.)[g]
P-HWQFN48-7x7-0.50	PWQN0048KB-A	48PJN-A P48K8-50-5B4-6	0.13



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Figure 2.5 QFN 48-pin

## Appendix 3. I/O Registers

This appendix describes I/O register address and access cycles by function.

### 3.1 Peripheral Base Addresses

This section provides the base addresses for peripherals described in this manual. [Table 3.1](#) shows the name, description, and the base address of each peripheral.

**Table 3.1 Peripheral base address (1 of 3)**

Name	Description	Base address
RMPU	Renesas Memory Protection Unit	0x4000_0000
TZF	TrustZone Filter	0x4000_0E00
SRAM	SRAM Control	0x4000_2000
BUS	BUS Control	0x4000_3000
DMAC0	Direct memory access controller 0	0x4000_5000
DMAC1	Direct memory access controller 1	0x4000_5040
DMAC2	Direct memory access controller 2	0x4000_5080
DMAC3	Direct memory access controller 3	0x4000_50C0
DMAC4	Direct memory access controller 4	0x4000_5100
DMAC5	Direct memory access controller 5	0x4000_5140
DMAC6	Direct memory access controller 6	0x4000_5180
DMAC7	Direct memory access controller 7	0x4000_51C0
DMA	DMAC Module Activation	0x4000_5200
DTC	Data Transfer Controller	0x4000_5400
ICU	Interrupt Controller	0x4000_6000
CACHE	CACHE	0x4000_7000
CPSCU	CPU System Security Control Unit	0x4000_8000
DBG	Debug Function	0x4001_B000
FCACHE	Flash Cache	0x4001_C100
SYSC	System Control	0x4001_E000
PORT0	Port 0 Control Registers	0x4001_F000
PORT2	Port 2 Control Registers	0x4001_F040
PORTA	Port A Control Registers	0x4001_F140
PORTB	Port B Control Registers	0x4001_F160
PORTC	Port C Control Registers	0x4001_F180
PORTD	Port D Control Registers	0x4001_F1A0
PORTE	Port E Control Registers	0x4001_F1C0
PFS_B	Pmn Pin Function Control Register	0x4001_F800
IIRFA	IIR Filter Accelerator	0x4002_0000
TFU	Trigonometric Function Unit	0x4002_1000
ELC_B	Event Link Controller	0x4008_2000
IWDT	Independent Watchdog Timer	0x4008_3200
WDT	Watchdog Timer	0x4008_3400
CAC	Clock Frequency Accuracy Measurement Circuit	0x4008_3600
MSTP	Module Stop Control A, B, C, D, E	0x4008_4000

**Table 3.1 Peripheral base address (2 of 3)**

Name	Description	Base address
KINT	Key Interrupt Function	0x4008_5000
POEG	Port Output Enable for GPT	0x4008_A000
IIC0WU_B	Inter-Integrated Circuit 0 Wake-up Unit	0x4009_F098
CANFD_B	CANFD Module Control	0x400B_0000
PSCU	Peripheral Security Control Unit	0x400E_0000
AGTW_B0	Low Power Asynchronous General purpose Timer 0	0x400E_8000
AGTW_B1	Low Power Asynchronous General purpose Timer 1	0x400E_8100
TSN	Temperature Sensor	0x400F_3000
ACMPHS0	High-Speed Analog Comparator	0x400F_4000
ACMPHS1	High-Speed Analog Comparator	0x400F_4100
ACMPHS2	High-Speed Analog Comparator	0x400F_4200
ACMPHS3	High-Speed Analog Comparator	0x400F_4300
CRC	Cyclic Redundancy Check	0x4010_8000
DOC_B	Data Operation Circuit	0x4010_9000
SCI_B0	Serial Communication Interface 0	0x4011_8000
SCI_B1	Serial Communication Interface 1	0x4011_8100
SCI_B2	Serial Communication Interface 2	0x4011_8200
SCI_B3	Serial Communication Interface 3	0x4011_8300
SCI_B4	Serial Communication Interface 4	0x4011_8400
SCI_B9	Serial Communication Interface 9	0x4011_8900
SPI_B0	Serial Peripheral Interface 0	0x4011_A000
SPI_B1	Serial Peripheral Interface 1	0x4011_A100
IIC_B0	Inter-Integrated Circuit 0	0x4011_F000
IIC_B1	Inter-Integrated Circuit 1	0x4011_F400
ECCMB	CANFD ECC Module	0x4012_F200
SCE5_B	Secure Cryptographic Engine	0x4016_1000
GPT0	General PWM Timer 0	0x4016_9000
GPT1	General PWM Timer 1	0x4016_9100
GPT2	General PWM Timer 2	0x4016_9200
GPT3	General PWM Timer 3	0x4016_9300
GPT4	General PWM Timer 4	0x4016_9400
GPT5	General PWM Timer 5	0x4016_9500
GPT6	General PWM Timer 6	0x4016_9600
GPT7	General PWM Timer 7	0x4016_9700
GPT8	General PWM Timer 8	0x4016_9800
GPT9	General PWM Timer 9	0x4016_9900
GPT_OPS	Output Phase Switching Controller	0x4016_9A00
GPT_GTCLK	General PWM Timer	0x4016_9B00
PDG	PWM Delay Generation	0x4016_A000
ADC_B	12-Bit A/D Converter	0x4017_0000
DAC120	12-bit D/A converter	0x4017_2000
DAC121	12-bit D/A converter	0x4017_2100

**Table 3.1 Peripheral base address (3 of 3)**

Name	Description	Base address
FLAD	Data Flash	0x407F_C000
FACI	Flash Application Command Interface	0x407F_E000

Note: Name = Peripheral name  
Description = Peripheral functionality  
Base address = Lowest reserved address or address used by the peripheral

### 3.2 Access Cycles

This section provides access cycle information for the I/O registers described in this manual.

- Registers are grouped by associated module.
- The number of access cycles indicates the number of cycles based on the specified reference clock.
- In the internal I/O area, reserved addresses that are not allocated to registers must not be accessed, otherwise operations cannot be guaranteed.
- The number of I/O access cycles depends on bus cycles of the internal peripheral bus, divided clock synchronization cycles, and wait cycles of each module. Divided clock synchronization cycles differ depending on the frequency ratio between ICLK and PCLK.
- When the frequency of ICLK is equal to that of PCLK, the number of divided clock synchronization cycles is always constant.
- When the frequency of ICLK is greater than that of PCLK, at least 1 PCLK cycle is added to the number of divided clock synchronization cycles.
- The number of write access cycles indicates the number of cycles obtained by non-bufferable write access.

Note: This applies to the number of cycles when access from the CPU does not conflict with bus access from other bus masters such as DTC or DMAC.

**Table 3.2 Access cycles (1 of 3)**

Peripherals	Address		Number of access cycles				Cycle Unit	Related function
			ICLK = PCLK		ICLK > PCLK*1			
	From	To	Read	Write	Read	Write		
RMPU, TZF, SRAM, BUS, DMACn, DMA, DTC, ICU	0x4000_0000	0x4000_6FFF	4	3	4	3	ICLK	Renesas Memory Protection Unit, TrustZone Filter, SRAM Control, BUS Control, Direct memory access controller n, DMAC Module Activation, DTC Control Register, Interrupt Controller
CACHE	0x4000_7000	0x4000_7FFF	4	5	4	5	ICLK	CACHE
CPSCU, DBG, FCACHE	0x4000_8000	0x4001_CFFF	4	3	4	3	ICLK	CPU System Security Control Unit, Debug Function, Flash Cache
SYSC	0x4001_E000	0x4001_E3FF	5	4	5	4	ICLK	System Control
SYSC	0x4001_E400	0x4001_E5FF	9	8	5 to 8	5 to 8	PCLKB	System Control
PORTn	0x4001_F000	0x4001_F7FF	5	3	5	3	ICLK	PORTn Control Register 1/3/4
PORTn (PCNTR2)	0x4001_F000	0x4001_F7FF	8	3	8	3	ICLK	PORTn Control Register 2
PFS	0x4001_F800	0x4001_FFFF	8	3	8	3	ICLK	Pmn Pin Function Control Register
IIRFA	0x4002_0000	0x4002_03FF	4	3	4	3	ICLK	IIR Filter Accelerator
IIRFA	0x4002_0400	0x4002_0FFF	6	3	6	3	ICLK	IIR Filter Accelerator

Table 3.2 Access cycles (2 of 3)

Peripherals	Address		Number of access cycles				Cycle Unit	Related function
			ICLK = PCLK		ICLK > PCLK*1			
	From	To	Read	Write	Read	Write		
TFU	0x4002_1000	0x4002_1FFF	4	3	4	3	ICLK	Trigonometric Function Unit
ELC	0x4008_2000	0x4008_2FFF	5	4	3 to 5	2 to 4	PCLKB	Event Link Controller
IWDT, WDT, CAC	0x4008_3000	0x4008_3FFF	5	4	3 to 5	2 to 4	PCLKB	Independent Watchdog Timer, Watchdog Timer, Clock Frequency Accuracy Measurement Circuit
MSTP	0x4008_4000	0x4008_4FFF	5	4	2 to 4	2 to 4	PCLKB	Module Stop Control
KINT	0x4008_5000	0x4008_5FFF	4	3	1 to 4	1 to 3	PCLKB	Key Interrupt Function
POEG	0x4008_A000	0x4008_AFFF	5	4	3 to 5	2 to 4	PCLKB	Port Output Enable for GPT
CANFD	0x400B_0000	0x400C_1FFF	5	4	2 to 5	2 to 4	PCLKB	CANFD Module
PSCU	0x400E_0000	0x400E_0FFF	5	4	2 to 5	2 to 4	PCLKB	Peripheral Security Control Unit
AGTn	0x400E_8000	0x400E_8FFF	7	4	4 to 7	2 to 4	PCLKB	Low Power Asynchronous General Purpose Timer n
TSN	0x400F_3000	0x400F_3FFF	5	4	2 to 5	2 to 4	PCLKB	Temperature Sensor
ACMPHSn	0x400F_4000	0x400F_4FFF	4	3	1 to 3	1 to 3	PCLKB	High-Speed Analog Comparator
CRC, DOC	0x4010_8000	0x4010_9FFF	5	4	2 to 5	2 to 4	PCLKA	Cyclic Redundancy Check, Data Operation Circuit
SCIn	0x4011_8000	0x4011_8FFF	5	4	2 to 4	2 to 4	PCLKA	Serial Communication Interface n
SPIIn	0x4011_A000	0x4011_AFFF	5	4	2 to 5	2 to 4	PCLKA	Serial Peripheral Interface n
IICn	0x4011_F000	0x4011_FFFF	5	4	2 to 4	2 to 4	PCLKA	Inter-Integrated Circuit n
CANFD ECC	0x4012_F200	0x4012_FFFF	5	4	2 to 5	2 to 4	PCLKA	CANFD ECC Module
SCE5	0x4016_1000	0x4016_1FFF	6	4	3 to 6	2 to 4	PCLKA	Secure Cryptographic Engine
GPTn, GPT_OPS (core clock = PCLKD)	0x4016_9000	0x4016_9FFF	8	5	5 to 8	3 to 5	PCLKA	General PWM Timer n, Output Phase Switching Controller
GPTn, GPT_OPS (core clock = GPTCLK)	0x4016_9000	0x4016_9FFF	10	7	7 to 10	5 to 7	PCLKA	General PWM Timer n, Output Phase Switching Controller
GPT (GTCKCR)	0x4016_9B00	0x4016_9B00	5	4	2 to 4	2 to 4	PCLKA	GPT Clock Control Register
PDG	0x4016_A000	0x4016_AFFF	4	3	1 to 3	1 to 3	PCLKA	PWM Delay Generation
ADC	0x4017_0000	0x4017_0FFF	5	4	2 to 5	2 to 4	PCLKA	12-bit A/D Converter
ADC	0x4017_1000	0x4017_1FFF	4	3	1 to 3	1 to 3	PCLKA	12-bit A/D Converter
DAC12n	0x4017_2000	0x4017_2FFF	5	4	2 to 4	2 to 4	PCLKA	12-bit D/A Converter

**Table 3.2 Access cycles (3 of 3)**

Peripherals	Address		Number of access cycles				Cycle Unit	Related function
			ICLK = FCLK		ICLK > FCLK*1			
	From	To	Read	Write	Read	Write		
FLAD, FACL	0x407F_C000	0x407F_EFFF	5	4	2 to 5	2 to 4	FCLK	Data Flash, Flash Application Command Interface

Note 1. If the number of PCLK or FCLK cycles is non-integer (for example 1.5), the minimum value is without the decimal point, and the maximum value is rounded up to the decimal point. For example, 1.5 to 2.5 is 1 to 3.

## Appendix 4. Peripheral Variant

Table 4.1 shows the correspondence between the module name used in this manual and the Peripheral Variant.

**Table 4.1 Module name vs Peripheral Variant**

Module name	Peripheral Variant
ELC	ELC_B
AGTW	AGTW_B
SCI	SCI_B
IIC	IIC_B
CANFD	CANFD_B
SPI	SPI_B
SCE5	SCE5_B
ADC	ADC_B
DOC	DOC_B



## Appendix 5. Related Documents

Component	Document Type	Description
Microcontrollers	Data sheet	Features, overview, and electrical characteristics of the MCU
	User's Manual: Hardware	MCU specifications such as pin assignments, memory maps, peripheral functions, electrical characteristics, timing diagrams, and operation descriptions
	Application Notes	Technical notes, board design guidelines, and software migration information
	Technical Update (TU)	Preliminary reports on product specifications such as restriction and errata
Software	User's Manual: Software	Command set, API reference and programming information
	Application Notes	Project files, guidelines for software programming, and application examples to develop embedded software applications
Tools & Kits, Solutions	User's Manual: Development Tools	User's manuals and quick start guides for developing embedded software applications with Software Packages, Development Kits, Starter Kits, Promotion Kits, Product Examples, and Application Examples
	Quick Start Guide	
	Application Notes	Project files, guidelines for software programming, and application examples to develop embedded software applications

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## Revision History

### Revision 1.10 — Dec 9, 2021

First edition, issued

# General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

## 1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity.

Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

## 2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

## 3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

## 4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

## 5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

## 6. Voltage application waveform at input pin

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.).

## 7. Prohibition of access to reserved addresses

Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

## 8. Differences between products

Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

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